

Revealing surface charge transport in thin films of topological Weyl metal SrRuO₃

Dr. Wei-Li Lee

Institute of Physics, Academia Sinica, Nankang, 11529, Taipei, Taiwan

Outline

□ Review of the topological Weyl semimetal and ferromagnetic Weyl metal SrRuO₃ (SRO) system:

- Brief review of magnetic Weyl semimetal and **Bulk-surface correspondences** in topological Weyl metal SRO.
- Adsorption control growth of SRO thin films using oxide MBE facility at IoPAS.

□ Weyl-orbit quantum oscillation effect (WQE):

- Structural charac. of **low defect level** and **untwinned** SRO thin films.
- **“Thickness”** dependent quantum oscillations and comp. to simulated Weyl-orbit QO.

□ Nonreciprocal and nonlinear charge transports (NRTE) in SRO thin film:

- Fabrication of **sunbeam** devices from an untwinned SRO thin film for anisotropy measurements.
- Observation of **NRTE** and **nonlinear Hall effect** in SRO thin film at low temperatures.

□ Conclude and future outlooks

Kar et al. Sci. Rep. 11, 16070 (2021).

Kar et al. npj Quantum Materials 8, 8 (2023).

Kar et al. arXiv:2307.04482, submitted.

Acknowledgements for outside collaborators

Weyl-orbit QO. in Weyl metal SrRuO₃



NSRRC Director Chia-Hung Hsu



Prof. Steffen Wiedmann



Prof. Wei-Cheng Lee



NCTS Director/Chair Prof. Dr. Peram S.V. Reddy



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High precision X-ray charac.



Dr. Yu-Te Hsu



M. Berben

Radbound univ. and
HMFL-Nijmegen
(Magnetotransport up to 35 T
SRO $t = 9, 13.7, 18.7$ nm)

NRTE and nonlinear Hall

Binghamton Univ.
-SUNY
(theoretical band Cal.)

NTU
(theoretical band Cal.)

EE, NTU
(Device Fabrication)

Caltech
(optical SHG)

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IoP, Academia Sinica, Taipei

1. Magnetotransport measurements up to 14 T
2. SRO thin film growths and device fabrication
3. Operation and maintenance of oxide MBE facility IoPAS
4. X-ray, LEED and RHEED structural charac.



Special thanks to **Dr. H. Nair** and **Prof. D. Schlom** for sharing experience on adsorption controlled growth using an oxide MBE

Brief review of Weyl semimetal (WSM)

Selected for a **Viewpoint** in *Physics*

PHYSICAL REVIEW B **83**, 205101 (2011)

Topological semimetal and Fermi-arc surface states in the electronic structure of pyrochlore iridates

Xiangang Wan,¹ Ari M. Turner,² Ashvin Vishwanath,^{2,3} and Sergey Y. Savrasov^{1,4}

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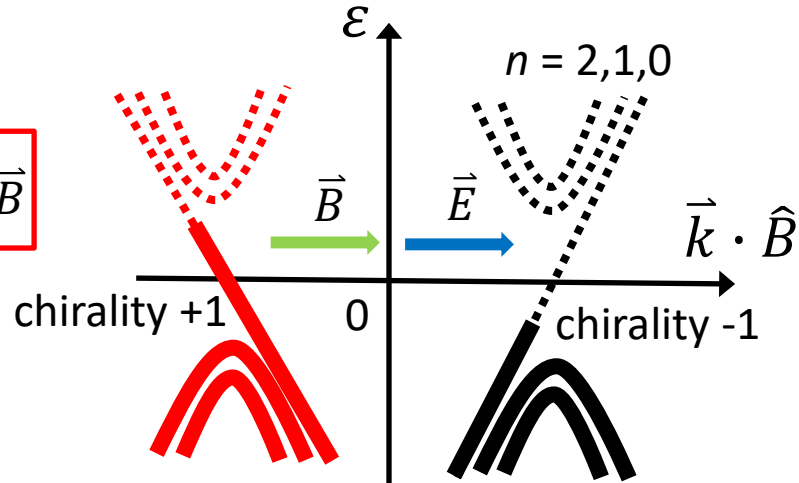
(Received 23 February 2011; published 2 May 2011)

Minimum model of a WSM with one pair of non-overlapped **Weyl nodes**:
Unusual $n = 0$ **chiral Landau levels** under applied magnetic field

$$\varepsilon_{n=0} = \pm \hbar v_F \vec{k} \cdot \hat{B}$$

$$\partial_\mu j_5^\mu = \frac{e^2}{4\pi^2 \hbar^2} \vec{E} \cdot \vec{B}$$

$$j_5^\mu = j_+^\mu - j_-^\mu$$



Chiral anomaly: non-conserved axial current
(neutral pion decay: $\pi^0 \rightarrow 2 \gamma$: Adler-Bell-Jackiw anomaly in 1968)
Axion fields and chiral magnetic effect in cosmology/astrophysics.

For $\tau_{inter} \gg \tau_{intra}$ and $\vec{E} \parallel \vec{B}$, additional conductivity

$$\sigma_{chiral} \propto \frac{B^2 \tau_{inter}}{\varepsilon_F^2}$$

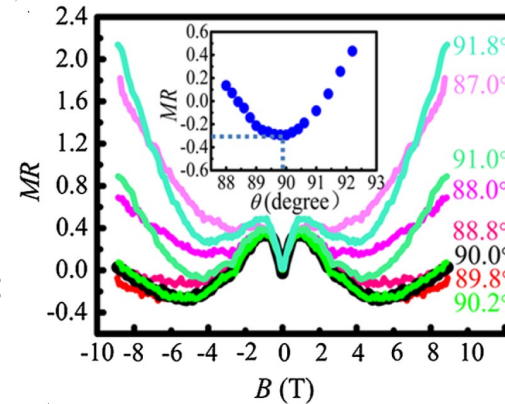
Son & Spivak PRB **88**, 104412 (2013)

Ong & Liang Nat. Rev. Phys **3**, 394 (2021)

Yip, arXiv:1508.01010

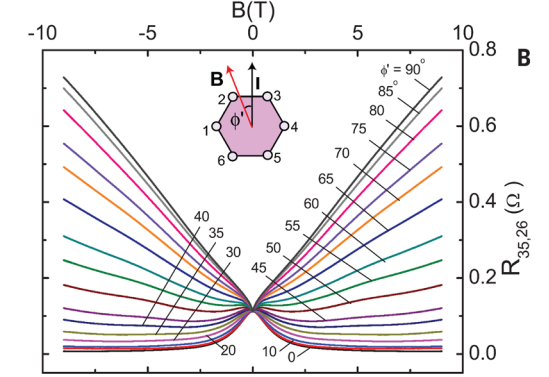
Negative longitudinal MR for $\vec{E} \parallel \vec{B}$

Huang *et al.* PRX **5**, 031023 (2015)



Inversion asymm. Weyl TaAs

Xiong *et al.* Science **350**, 413 (2015)

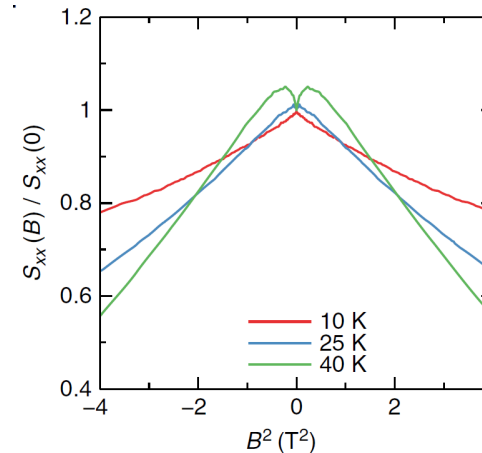


Field breaking of chiral symm. in Dirac **Na3Bi**

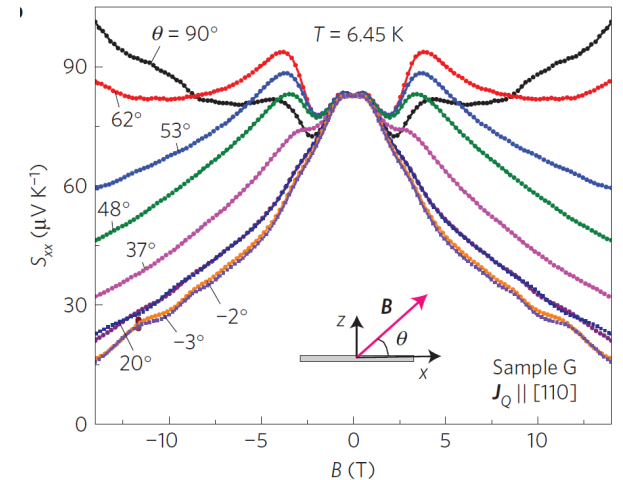
Suppressed TEP for $\vec{E} \parallel \vec{B}$: 1D $n = 0$ chiral LL (D.O.S. indep. of energy.)

Jia *et al.* Nat. commun. **8**, 13741(2016)

Hirschberger *et al.* Nat. Mat. **15**, 1161 (2016)



Broken chiral symm. by **field** in Dirac **Cd3As2**



Field induced Weyl in magnetic **GdPtBi**

Fermi arc surface states in a topological Weyl semimetal

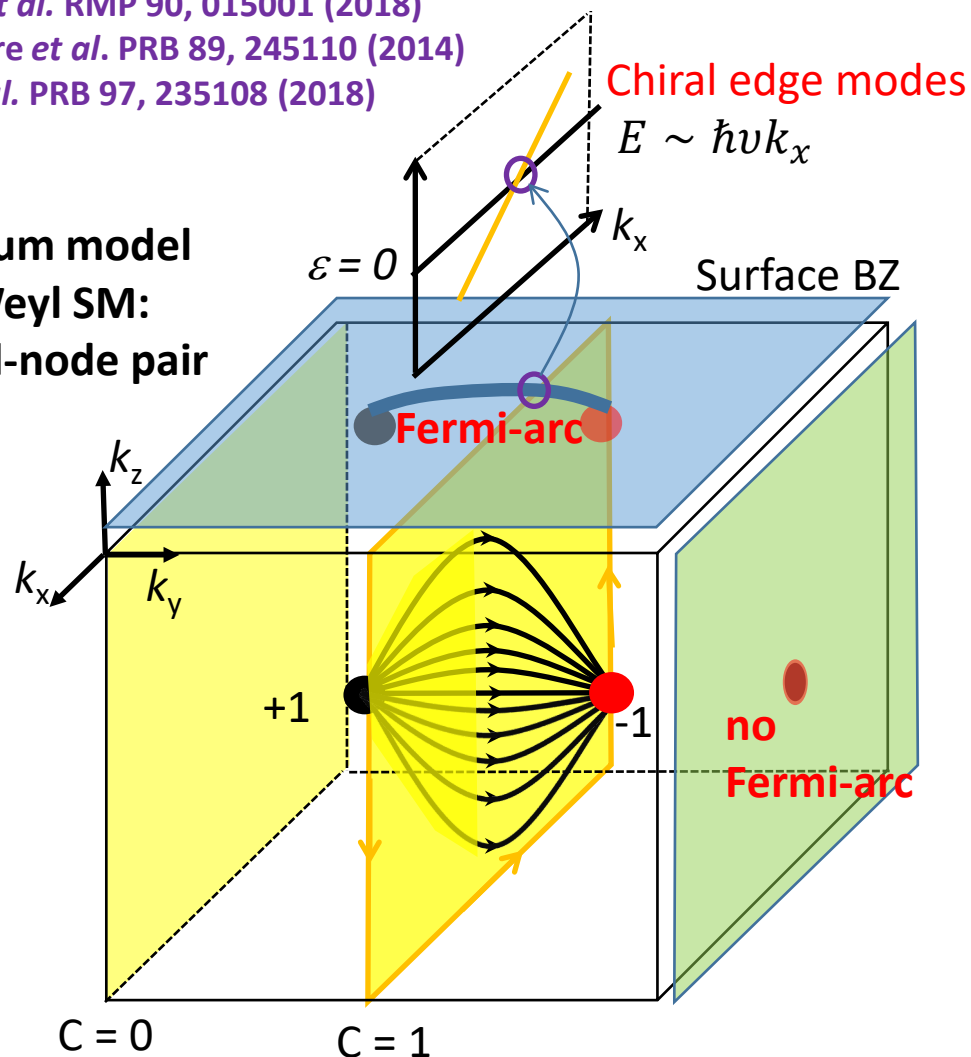
Wan *et al.* PRB 83, 205101 (2011)

Armitage *et al.* RMP 90, 015001 (2018)

Nandkishore *et al.* PRB 89, 245110 (2014)

Wilson *et al.* PRB 97, 235108 (2018)

A minimum model
of a Weyl SM:
one Weyl-node pair



- Any sliced 2D plane between a Weyl-node pair has a total Berry flux of 2π ($C = 1$): Chiral edge modes at the boundary

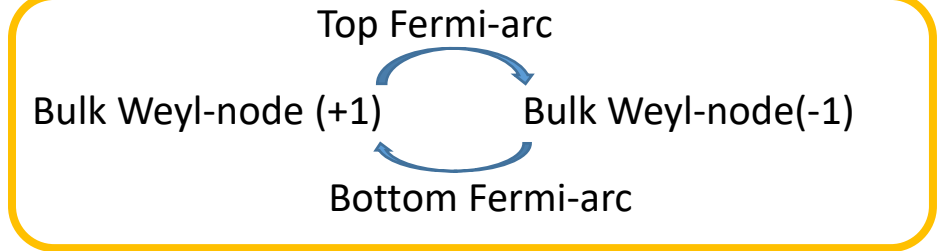
$$\text{Chern number } C = \frac{1}{2\pi} \oint \underbrace{\vec{\Omega}(\vec{k}) \cdot dS_{\vec{k}}}_{\text{Berry flux}}$$

- Fermi-arc surface states are unusual “one-way” chiral zero modes ($\varepsilon = 0$) but may not be robust against disorder: bulk-surface hybridization + rare region effect in disordered Dirac/Weyl.
(high quality crystals and thin films are needed !)
- Fermi-arc surface states: connecting projected non-overlapping Weyl-node pairs.
- Unique bulk-surface correspondence between Weyl-node bulk states and Fermi-arc surface states.

Unique thickness dep. Weyl-orbit quantum oscillations in Weyl semimetal

Potter *et al.* Nat. Commun. 5, 5161 (2014)

- Distinct **nonlocal** cyclotron orbit driven by B_z



- **Quantized** energy of nonlocal **Weyl-orbit**

$$\varepsilon_n \cdot 2 \left(\frac{\hbar k_0}{evB} + \frac{L_z}{v} \right) = 2\pi n \hbar.$$
 n is LL index, and k_0 is the length of **Fermi-arc**.

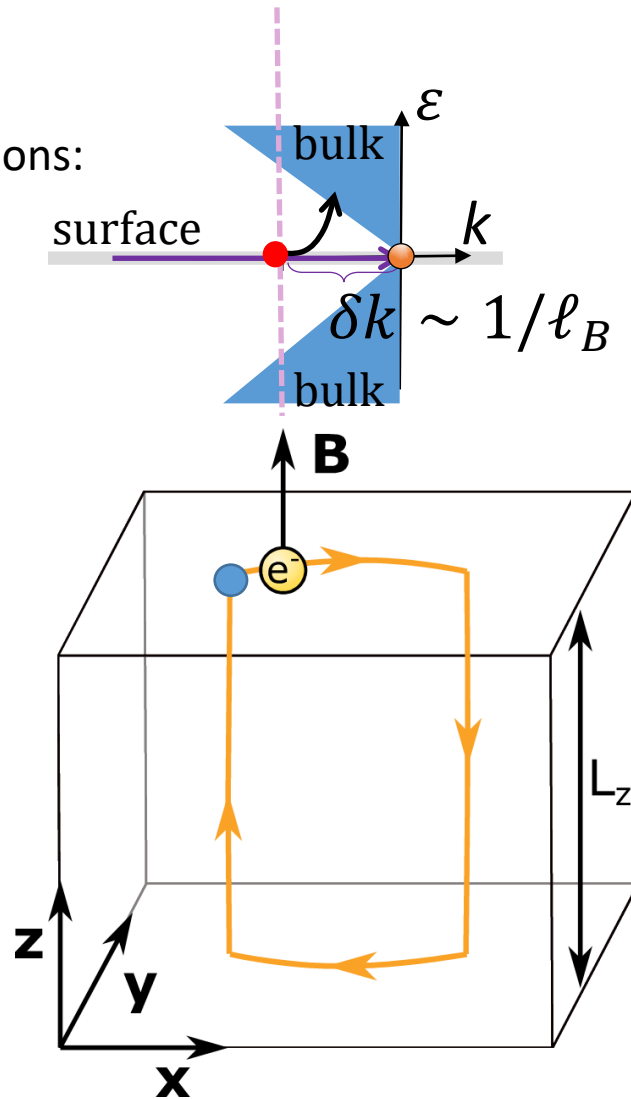
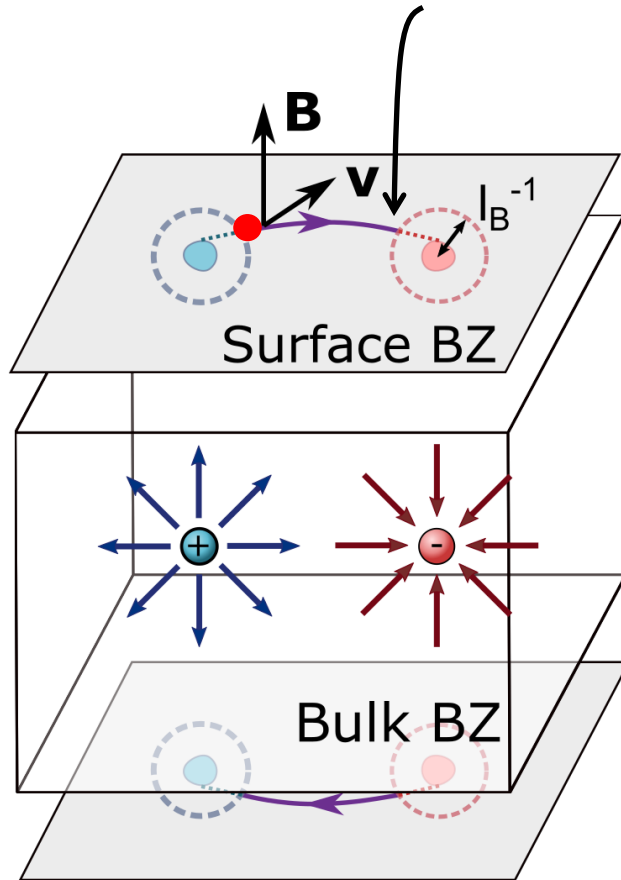
- **Unique thickness** dep. QO ($\varepsilon_n = \mu$)

$$\frac{1}{B_n} = \frac{e}{\hbar k'_0} \left[\frac{\pi \hbar v n}{\mu} - L_z \right].$$

- $k'_0 \equiv k_0 (1 - 4\alpha/k_0 \ell_B)$, and α is **non-adiabatic correction** param.
- $\ell_B \equiv \sqrt{\hbar/eB_n}$ is the magnetic length

- Reduced effective Weyl-orbit area due to α .
- Only sensitive to B_z : a 2D-like Fermi-pocket.

Non-adiabatic corrections:
"Sinking" into bulk

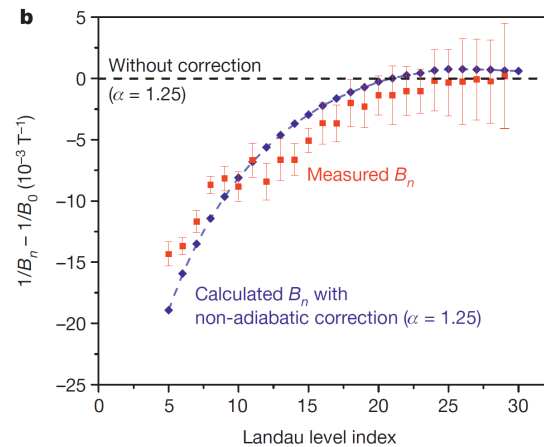
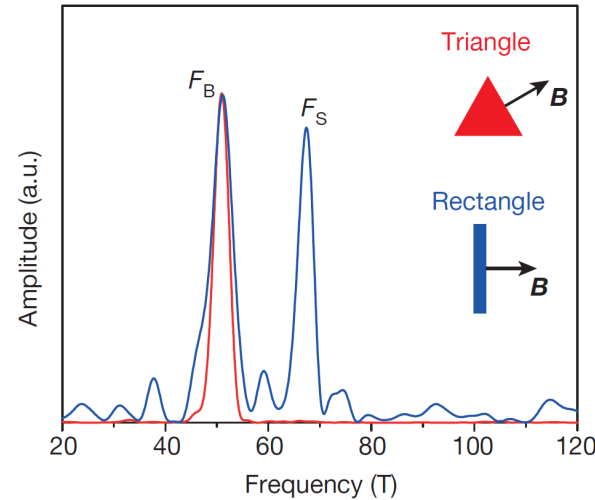
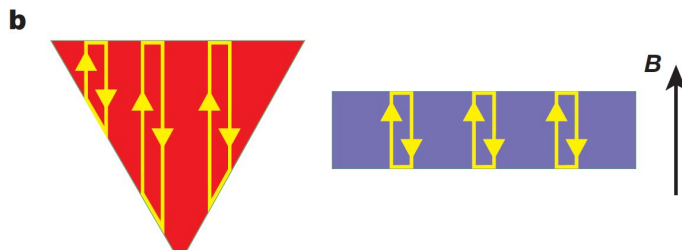
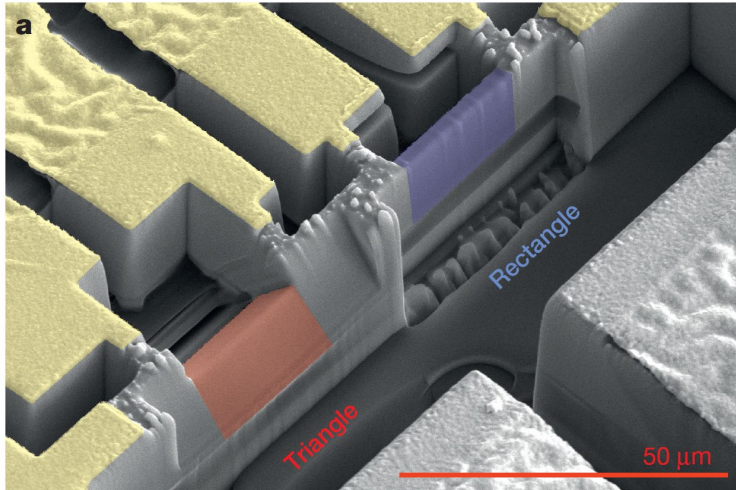


First demonstration of Weyl-orbit quantum oscillations in Dirac semimetal Cd₃As₂

Transport evidence for Fermi-arc-mediated chirality transfer in the Dirac semimetal Cd₃As₂

Philip J. W. Moll^{1,2}, Nityan L. Nair¹, Toni Helm^{1,2}, Andrew C. Potter¹, Itamar Kimchi¹, Ashvin Vishwanath¹ & James G. Analytis^{1,3}

Moll *et al.* Nature 535, 266 (2016)

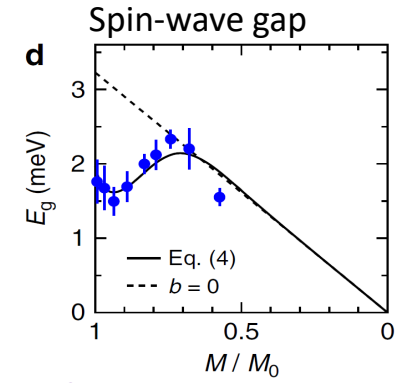
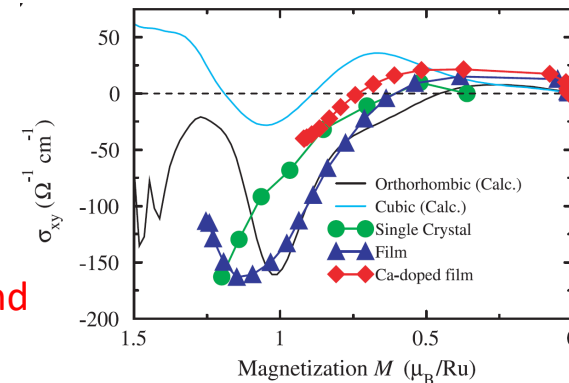
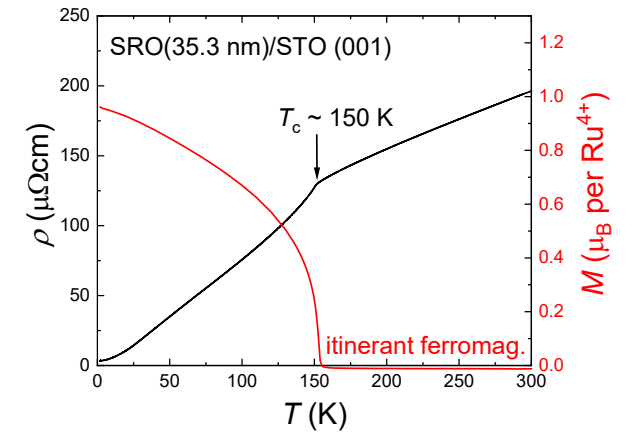
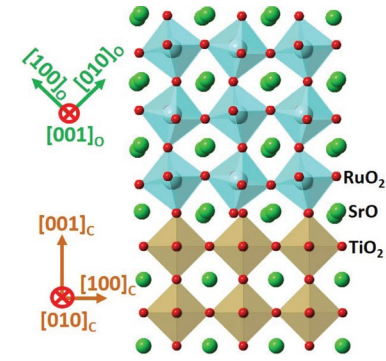


- FIB-machined thin flakes of Cd₃As₂, thickness > 150 nm (<< bulk mean free path ~ 1000 nm)
- Field-splitting of the Weyl-node pair
- The absence of Weyl-orbit QO in wedge shaped Cd₃As₂
- The presence of the **non-adiabatic correction**.
- A number of more recent reports in Cd₃As₂ thin films and other microcrystal devices:
 - Zhang *et al.* Nat. Commun. 8, 13741 (2017) & Nature 565, 331 (2019)
 - Schumann *et al.* PRL 120, 016801 (2018),
 - Nishihaya *et al.* Nat. Commun. 2, 2572 (2021)
 - ...
- Extrinsic (surface) defect from ion-implantation ? Density variation effect ? Surface Fermi-loop or Fermi-arcs ?
 - Galletti *et al.* PRB 99, 201401 (2019)
 - Lin *et al.* PRL 122, 036602 (2019) ...

Quest for further tests in other Dirac/Weyl semimetal systems, particularly in **high quality thin-film form !**

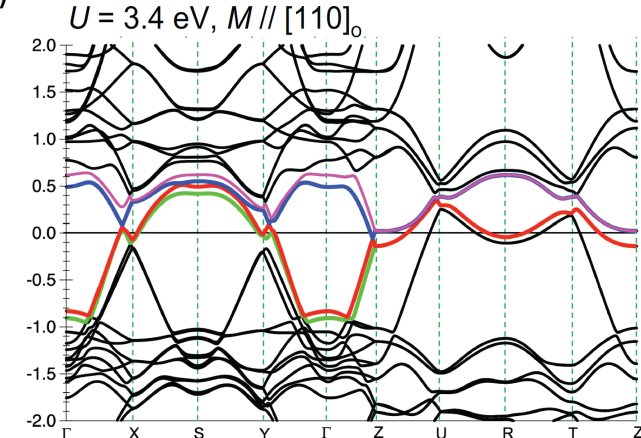
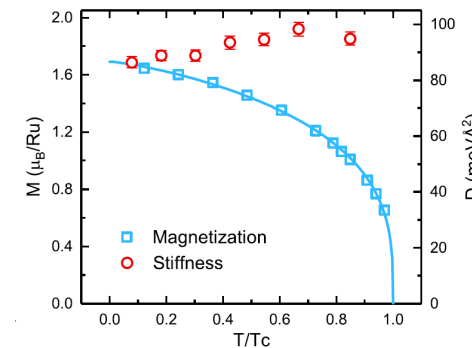
Emergent property of SRO as a magnetic Weyl

- **Orthorhombic** SRO is a metallic and ferromagnetic oxide with a Curie temp ~ 165 K.
- **Moderate correlated** material : **Fermi-liquid** at low temp and asym. tunneling spectrum
- **Slightly distorted orthorhombic** SRO films on SrTiO3 (001) compressive strain of -0.4% with magnetic easy axis along $[110]_o$.
Koster et al. Rev. Mod. Phys. 84, 253 (2012)
- The presence of the Weyl nodes near Fermi surface:
 - ✓ $\sigma_{xy} \approx -180 \Omega^{-1} \text{cm}^{-1}$ (close to $\frac{e^2}{ha} \sim 500 \Omega^{-1} \text{cm}^{-1}$)
 - ✓ **Non-monotonic** anomalous Hall conductivity with magnetization
 - ✓ Spin wave gap and **softening** of the magnon mode at low temp.
- **DFT + U ($J = 0.2U$)** calculations show ***d-p* hybridization** and complex **band crossings** around the Fermi surface (> 100 crossings), inferring a **Weyl** phase.
Chen et al. PRB 88, 125110 (2013)
- The growth of high crystalline SRO film is difficulty due to the **high volatility** of RuOx and thus the presence of **Ru vacancies**.
- High sensitivity of disorder on charge transport in ruthenates.
Capogna et al. PRL 88, 076602 (2002)
- **Achieving growth of SRO films by oxide MBE with low level of Ru vacancies.**
Adsorption controlled technique: *Nair et al. APL mater. 6, 046101 (2018)*
Machine learning assisted: *Takiguchi et al. Nat. commun. 11, 4969 (2020)*



Fang et al. Science 302, 92 (2003)

Itoh et al. Nat. commun. 7, 11788 (2016)

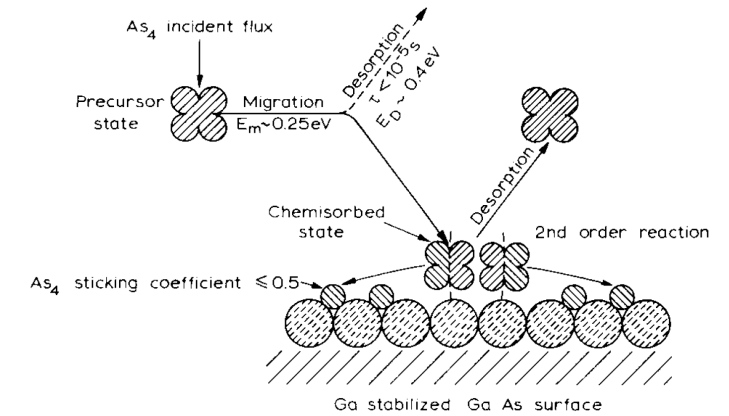
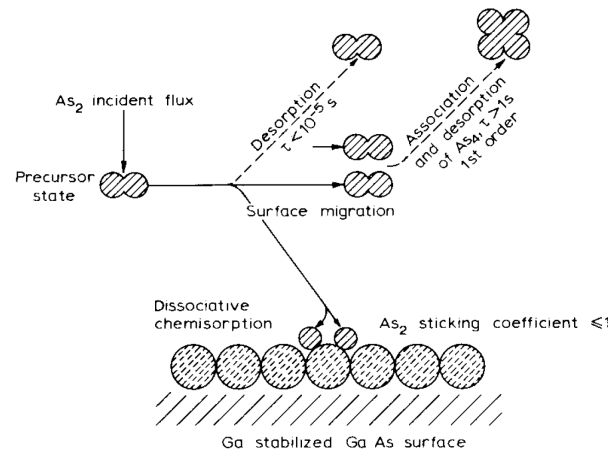
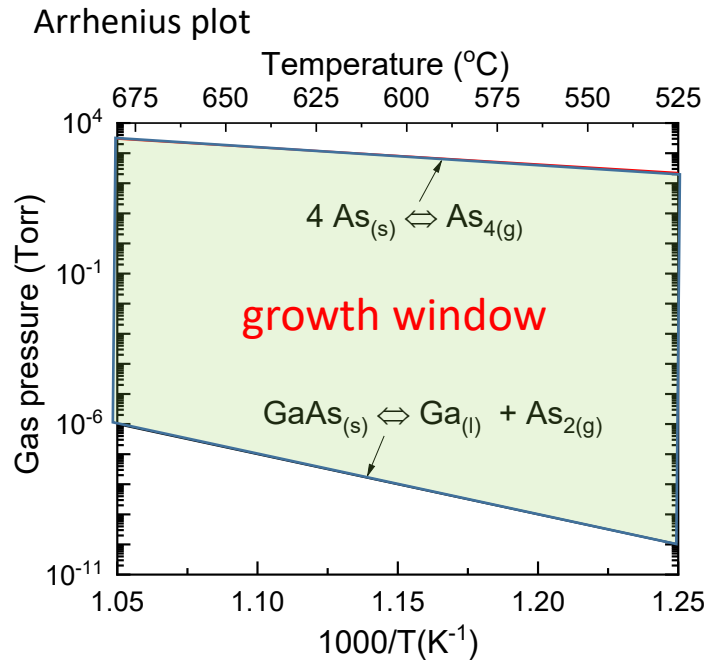


Jenni et al. PRL 123, 017202 (2019)

Adsorption control growth of films using MBE with volatile elements

- The growth of GaAs : excess As_2/As_4 flux and growth rate determined by Ga flux.

Foxon J. Vac. Sci. Technol. B 1983.



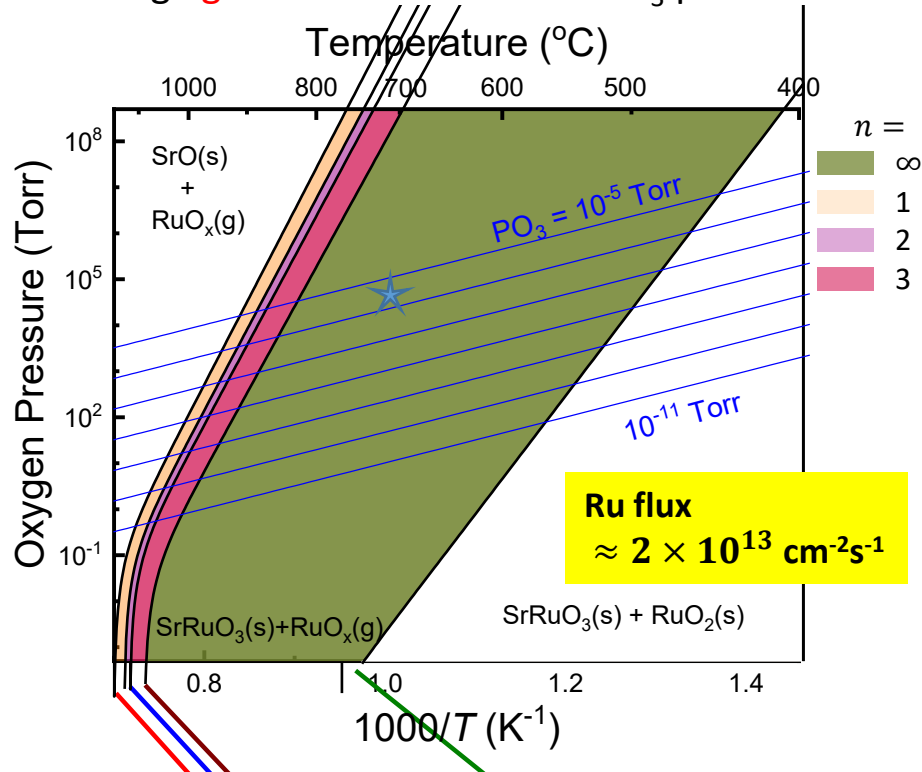
- Three temperatures approach for Bi₂Se₃: excess Se flux and $T_{Bi\ cell} > T_{substrate} > T_{Se\ cell}$.

Chen *et al.* Adv. Mater. 2011.

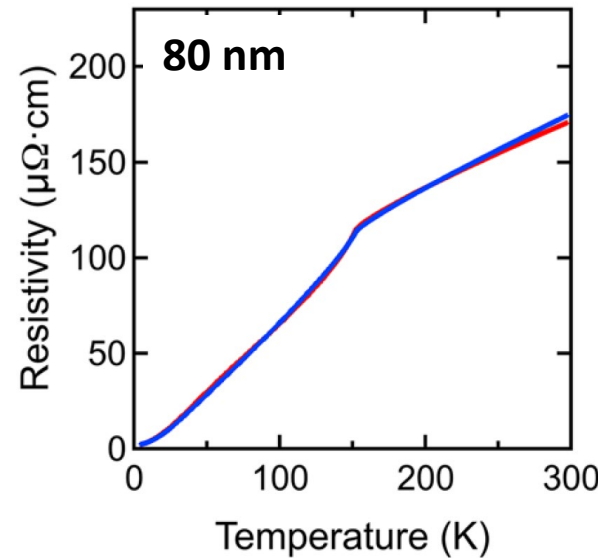
- The advantage of **thermodynamically self-adjusted** stoichiometry in the resulting films: resemble bulk single crystal growth process !

Adsorption control growth of oxide epitaxial thin films

- Growth of several oxides films: PbTiO_3 , LuFe_2O_4 , SrRuO_3 , Sr_2RuO_4 ...etc.
Theis et al. Thin Solid films 325, 107 (1998), Brooks et al. APL 101, 132907 (2012), Nair et al. APL mater. 6, 046101 (2018)
- Thermodynamics of MBE (TOMBE phase diagram) for Ruthenates $\text{Sr}_{n+1}\text{Ru}_n\text{O}_{3n+1}$: open system with excess Ru flux in ozone environment ideal for the growth of ruthenates thin films to minimize the Ru vacancies.
- Large growth window for SrRuO_3 phase and tunable by Ru flux: thermodynamically-adjusted Stoichiometry of the oxide films.



Films by MBE adsorption-controlled growth



$\rho(4\text{K}) \sim 2 \mu\Omega\text{cm}$
 RRR ~ 80 .

Cf.
 Single-crystal by F.Z.

$\rho(4\text{K}) \sim 1.05 \mu\Omega\text{cm}$
 RRR ~ 192 .

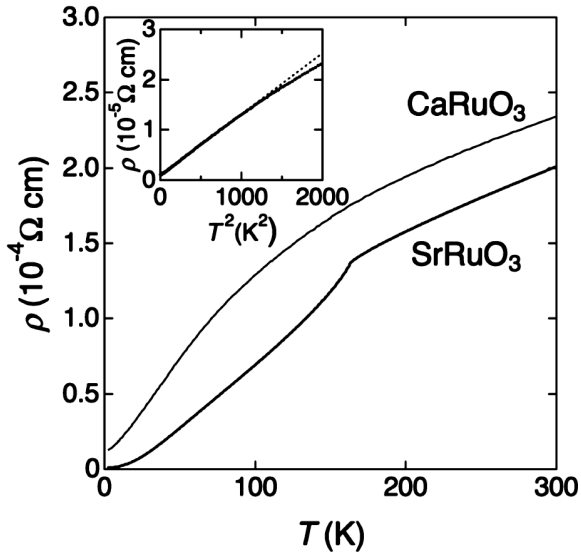
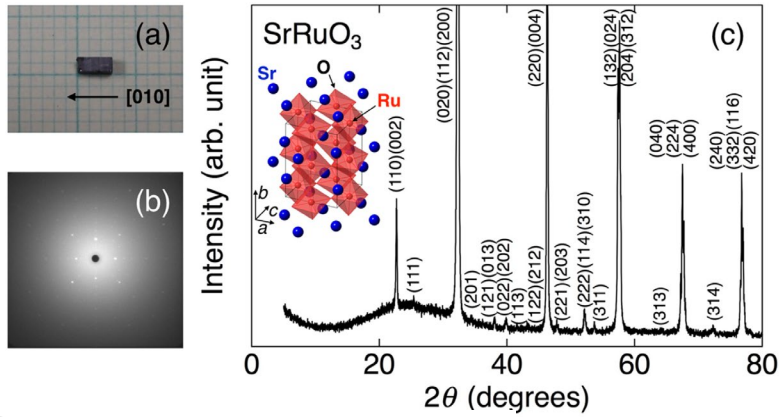
Films By PLD

$\rho(4\text{K}) > 120 \mu\Omega\text{cm}$
 RRR $\ll 10$

- In principle, it can further apply to other oxide growth with proper metal-organic source.
 Ex: the growth of SrTiO_3 using the metal-organic source of Titanium tetra-isopropoxide [$\text{Ti}(\text{OC}_3\text{H}_7)_4$ or TTIP] *Jalan et al. APL 95, 032906 (2009)*

Single crystal SRO by floating zone

Kikugawa *et al.* *Crys. Growth De.* 2015.

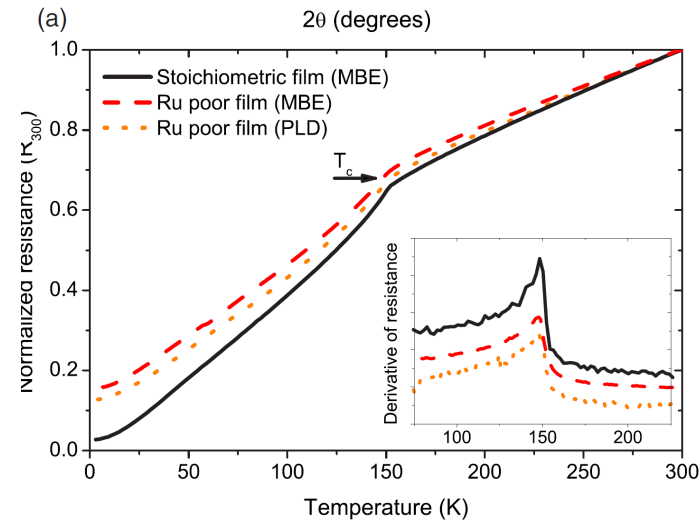
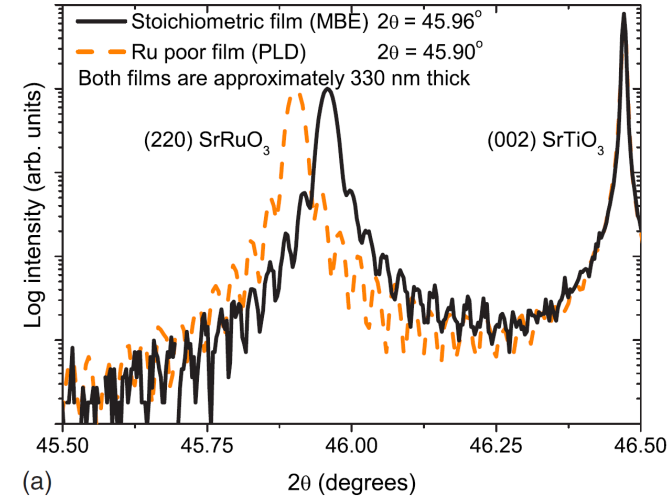


$$\rho(4K) \sim 1.05 \mu\Omega\text{cm}$$

$$RRR \equiv \rho(300K)/\rho(4K) \sim 192.$$

SRO films grown by pulsed laser deposition (PLD)

Siemons *et al.* *PRB* 2007.



PLD SRO films

$$\rho(4K) > 120 \mu\Omega\text{cm}$$

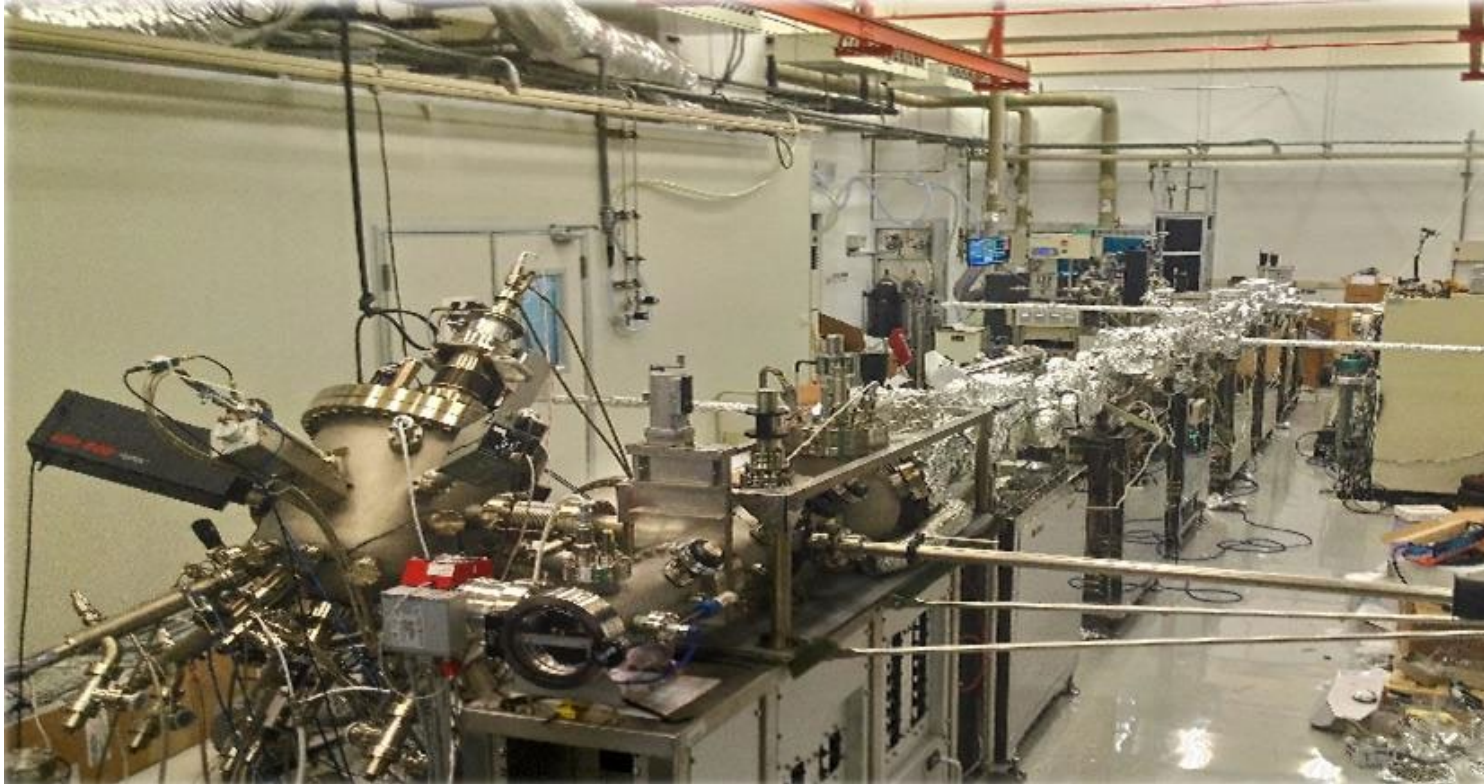
$$RRR \ll 10$$

- X-ray alone may not be sensitive to **random point defects** in SRO films, but low temperature **residual resistivity** does !
- In ruthenate, low temp. charge transport is largely influenced by the **Ru vacancies** that were common in PLD films.
- **Adsorption-controlled growth** using MBE was developed to overcome **Ru-vacancy** problem.

Capogna *et al.* *PRL* 2002.

Several transport issues at low temp. in SRO films can be revisited !

Oxide MBE at IoP installed in Nov. 2014



Sources:

10 effusion cells
4 pockets EB evap.

Ex-situ charac.:

- RBS
- X-ray (IoP AS)
- STEM-EELS (CCMS NTU)
- XPS (NSRRC, Hsinchu)
-

Characterization:

RHEED
RGA
Pyrometer
QCM

Active group members

PI: Dr. Wei-Li Lee

Post-doc:

Dr. Akhilesh Singh

RA :

Elisha Lu

Trent yang

Jyoti Verma

Ph.D. student:

Uddipta Kar

Master students (collab.):

T.W. Kuo C.Y. Chen

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Prof. Ivan Bozovic
Prof. Harold Hwang
Prof. Donglai Feng
Dr. D.W. Shen
Dr. Rob Moore
Dr. Wei-Sheng Lee
Dr. Ben Bensaoula
....

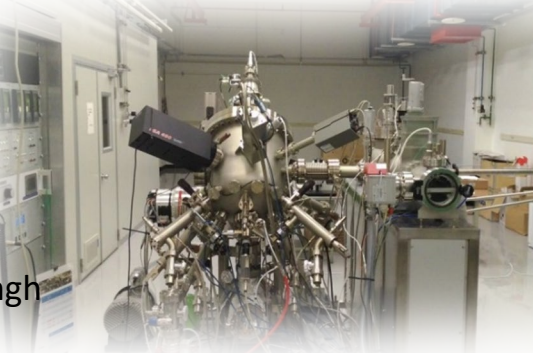
Oxide MBE facility at IoPAS with ozone distiller



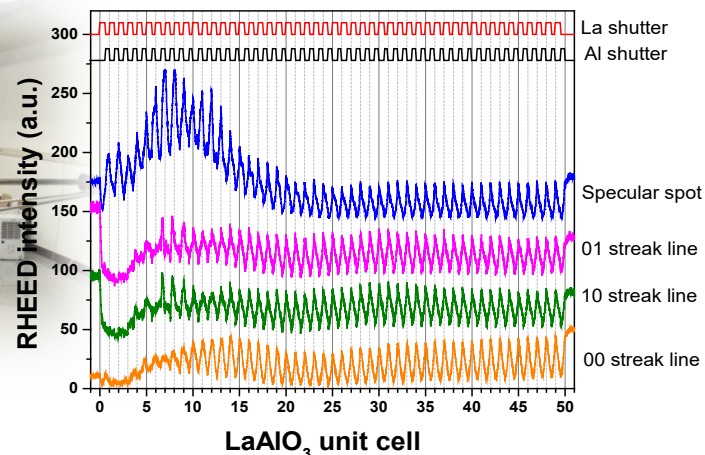
Dr. Wei-Li Lee



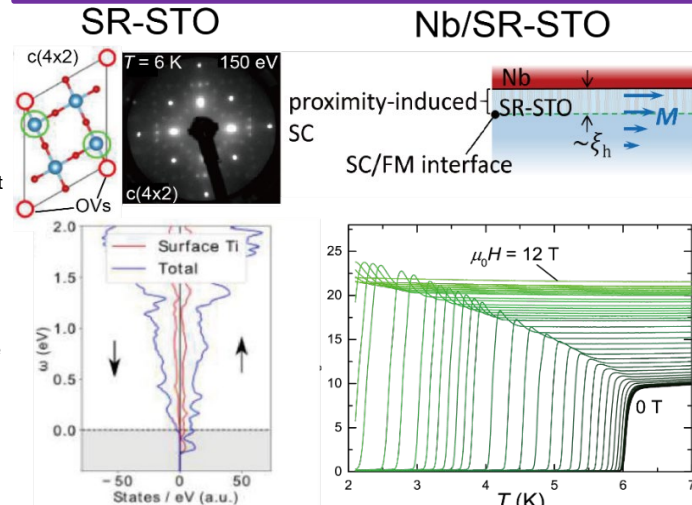
Dr. Akhilesh Singh



In-situ RHEED monitor

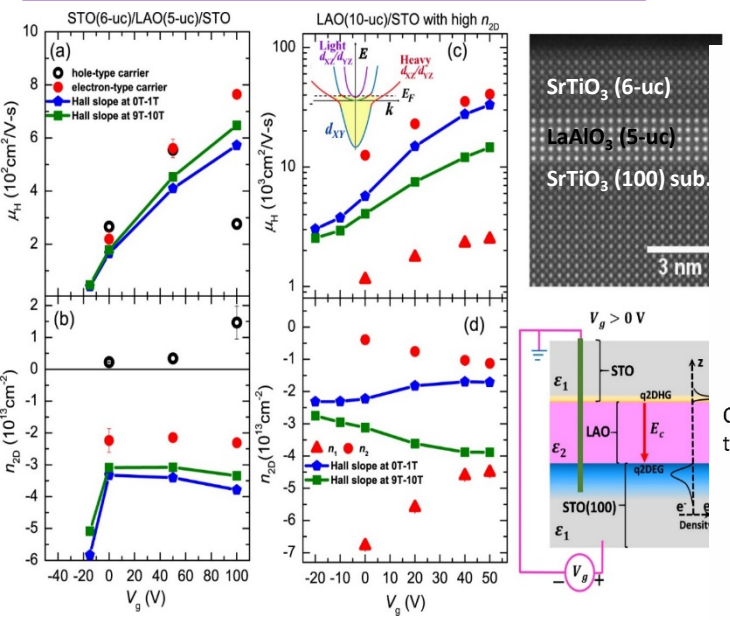


Spin-polarized in-gap states in surface-reconstructed SrTiO₃



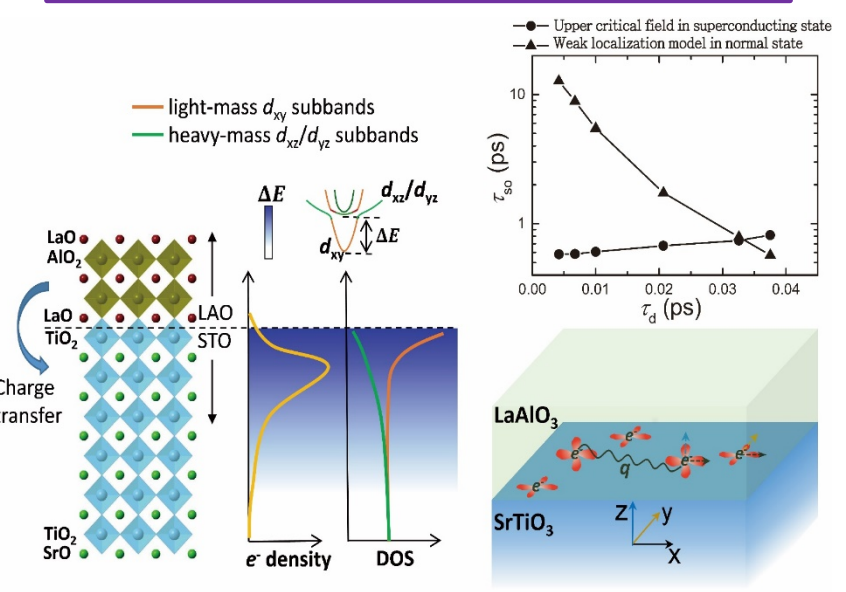
npj Quantum Mater. 5, 45 (2020)

Quasi-two-dimensional hole gas at complex oxide interface



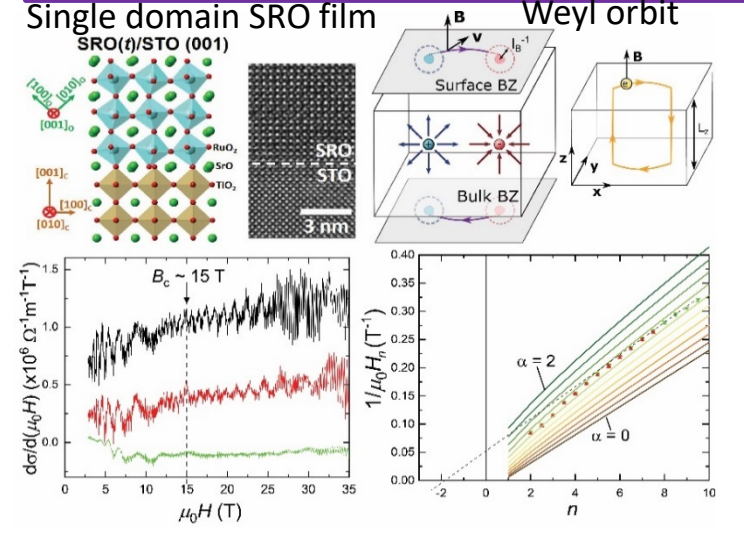
Phys. Rev. Materials 2, 114009 (2018)
Phys. Rev. Materials 3, 075003 (2019) (Dr. MW Chu)

Orbital selectivity for Cooper pairing at superconducting interface



Phys. Rev. Research 2, 013311 (2020)

Weyl-orbit quantum oscillation in topological Weyl semimetal SrRuO₃



Kar *et al.* *Sci. Rep.* 11, 16070 (2021)
 Kar *et al.* *npj Quantum Materials* 8, 8 (2023).

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Institute of Physics, Academia Sinica, Nankang, 11529, Taipei, Taiwan

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Kar et al. Sci. Rep. 11, 16070 (2021)

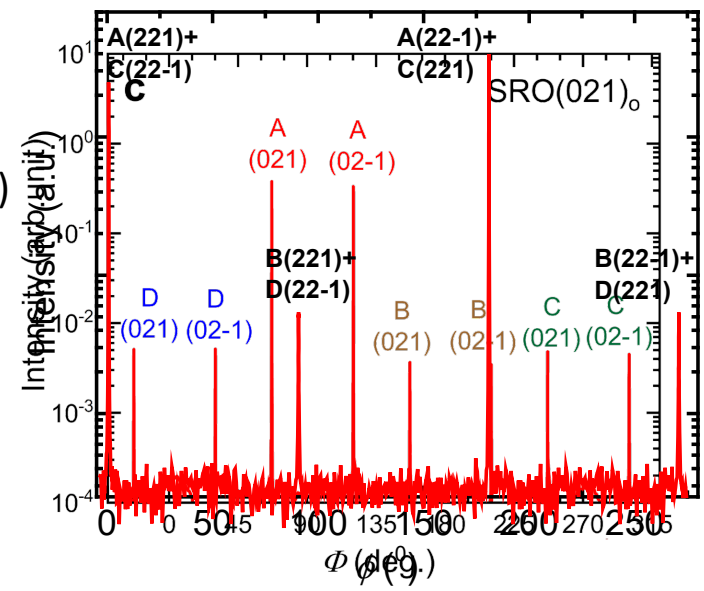
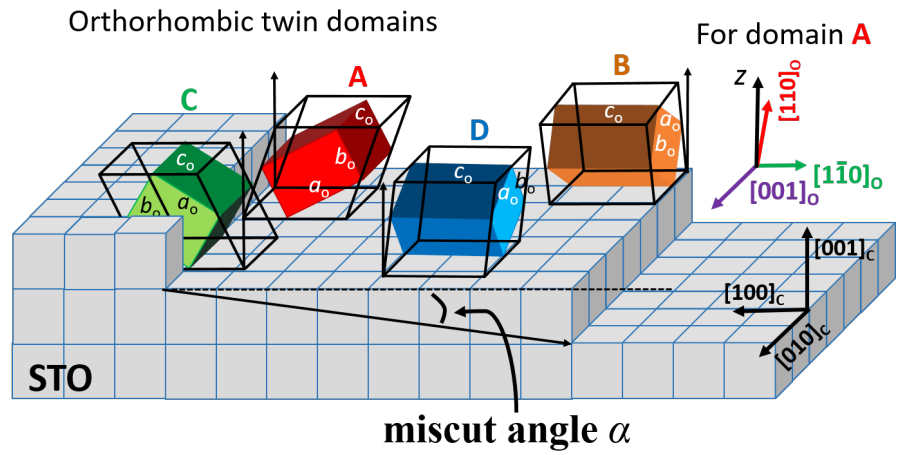
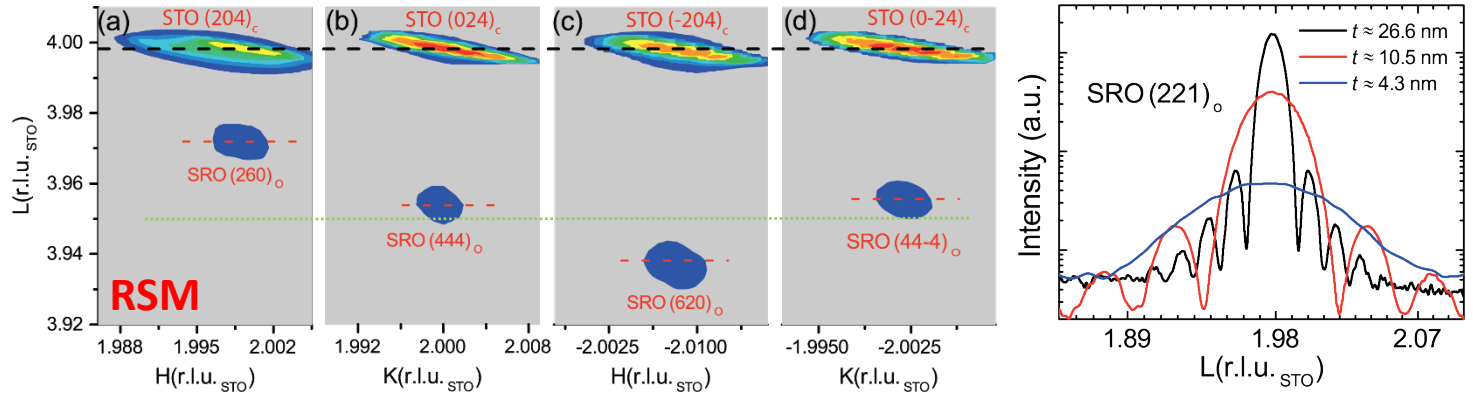
Kar et al. npj Quantum Materials 8, 8 (2023).

Kar et al. arXiv:2307.04482, submitted

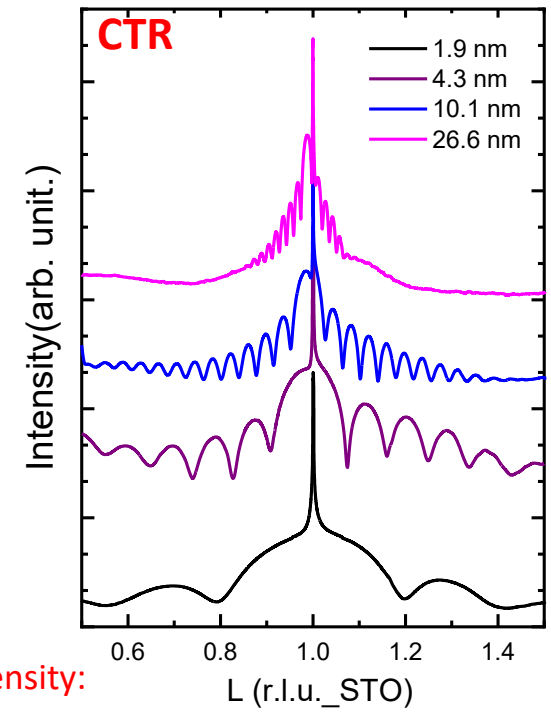
□ Conclude and future outlooks

Determination of domain populations in SRO films on miscut STO (001) sub.

- Slightly distorted Orthorhombic-phase:
 - ✓ Reciprocal space mapping (RSM)
 - ✓ Observable $(221)_o$ reflection
- Excellent thickness uniformity :
 - ✓ Crystal truncation rods (CTR)
 - ✓ AFM Surface roughness < 0.3 nm
- Distinguish domains via X-ray $(0\ 2\ \pm 1)$ reflections
 - ✓ Four possible orthorhombic twin domains
 - ✓ The volume fraction for each domain is highly sensitive to the substrate's miscut angles (α, β)
 - ✓ Dominant domain A with $[001]_o // \text{STO}[010]_c$



Domain volume fraction from integrated peak intensity:
 Domain A/C overlapped
 Domain A = 94.1%, Domain B = 1.7%,
 Domain C = 2.0%, and Domain D = 2.2%.

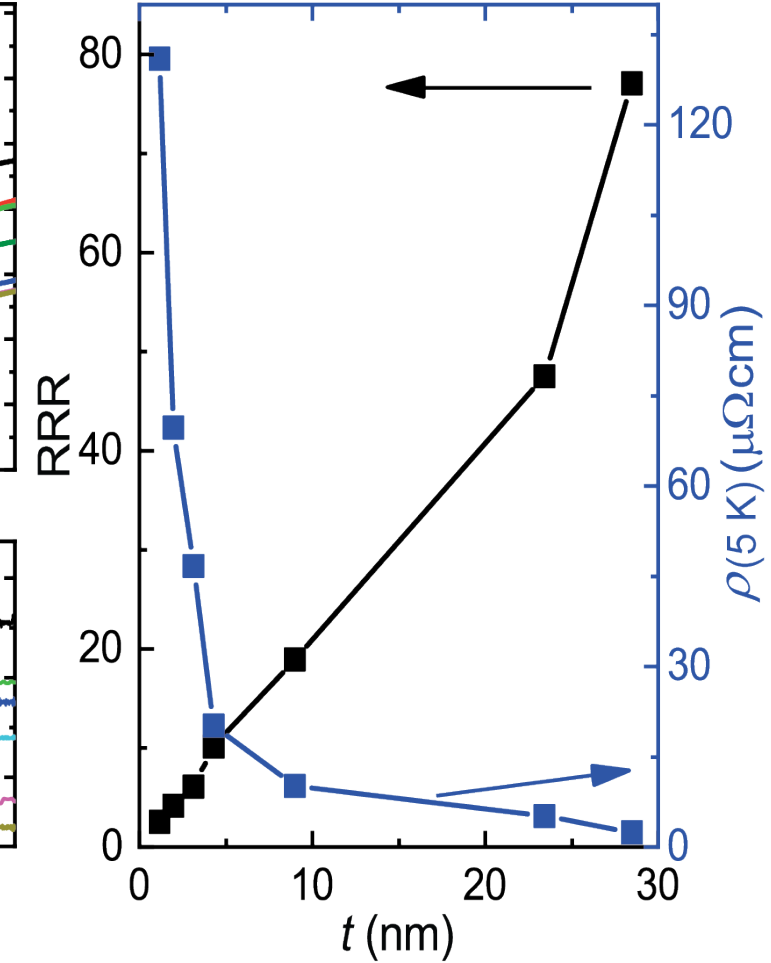
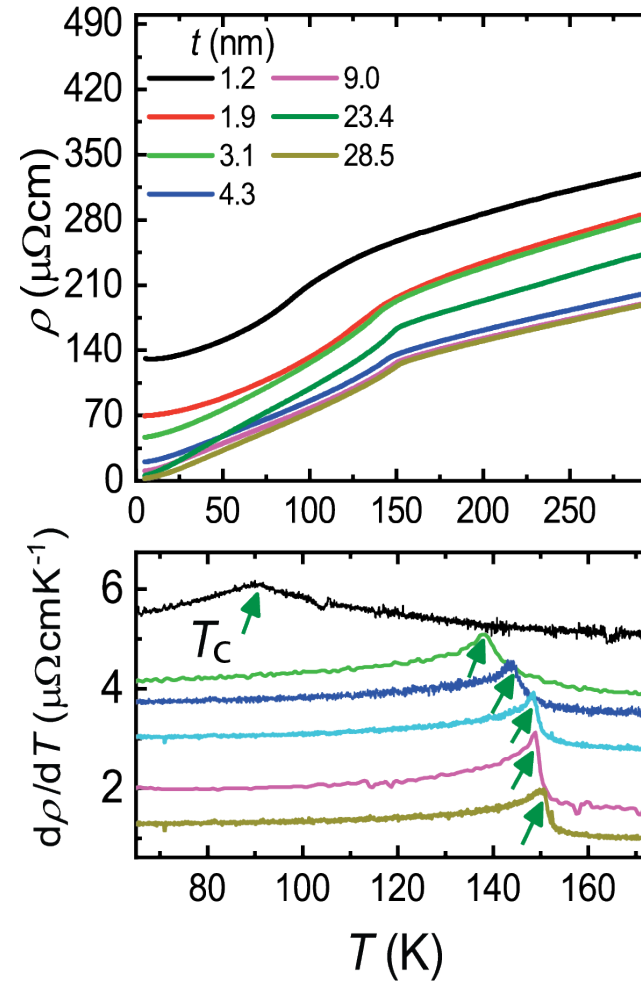


Kar et al. Sci. Rep. 11, 16070 (2021)

The growth of untwinned SRO films with low residual resistivity

Kar et al. Sci. Rep. 11, 16070 (2021)

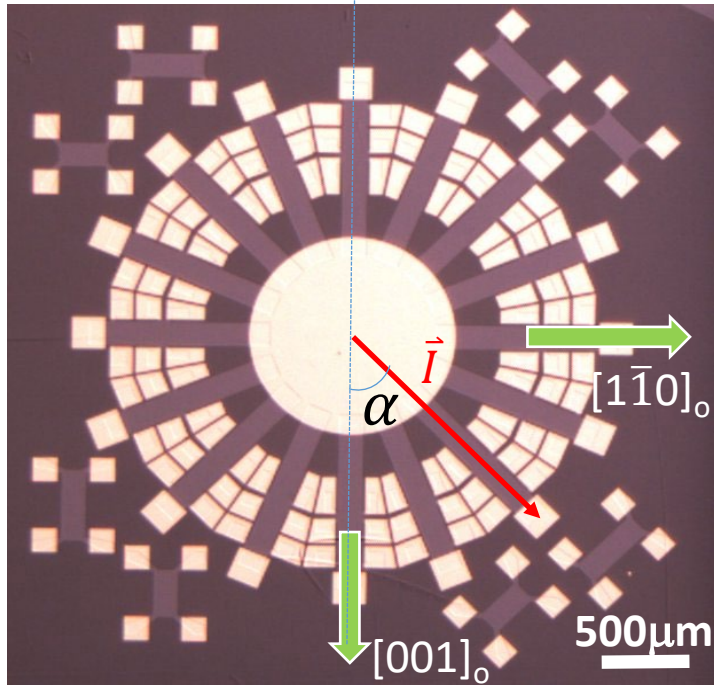
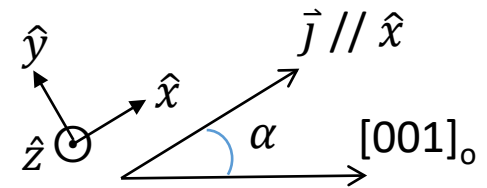
- **Untwinned** SRO films using **miscut** STO (001) sub. with a small miscut angles ($\alpha = 0.1^\circ, \beta = 0^\circ$) : dominant **A** domain with a volume fraction more than **90%** for $7.7 \text{ nm} < t < 40 \text{ nm}$.
- The metallic and ferromagnetic nature survives down to $t = 1.2 \text{ nm}$ of SRO.
- **RRR** reduces from **77.1** for $t \approx 28.5 \text{ nm}$ to 2.5 for $t \approx 1.2 \text{ nm}$, while $\rho(5\text{K})$ increases from **$2.5 \mu\Omega\text{cm}$** for $t \approx 28.5 \text{ nm}$ to **$131.0 \mu\Omega\text{cm}$** for $t \approx 1.2 \text{ nm}$.
- High RRR and low residual resistivity are close to that of single crystal SRO !



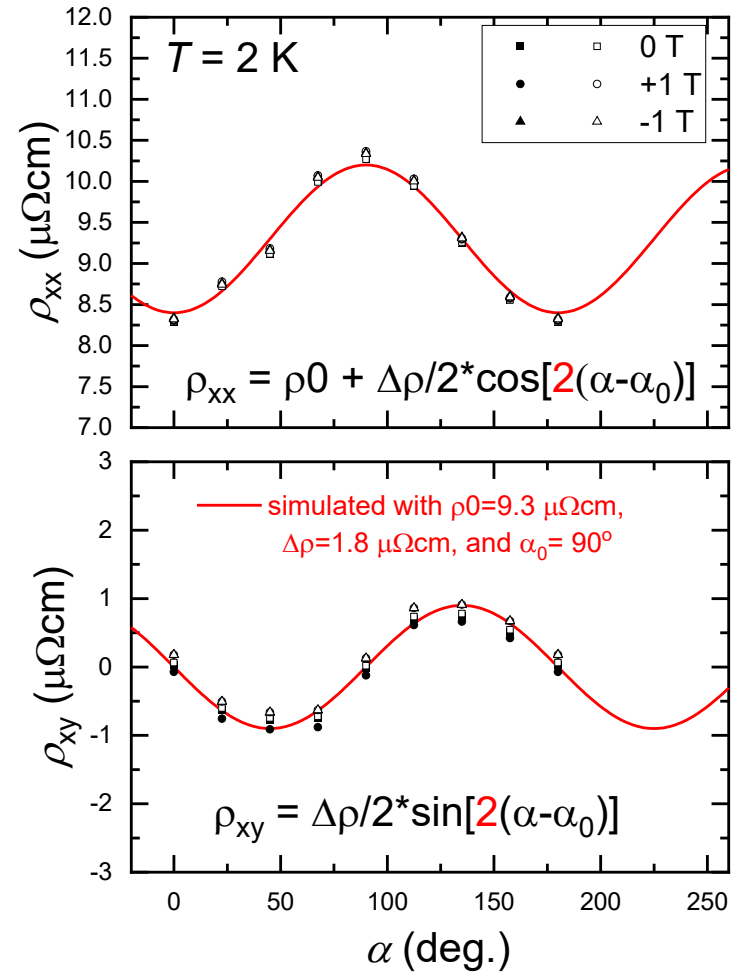
Resistivity anisotropy in untwinned SrRuO3

SRO $t = 13.7$ nm
sunbeam device

+B // - \hat{z}
 \otimes



α : angle between
bias current \vec{I} & $[001]_o$

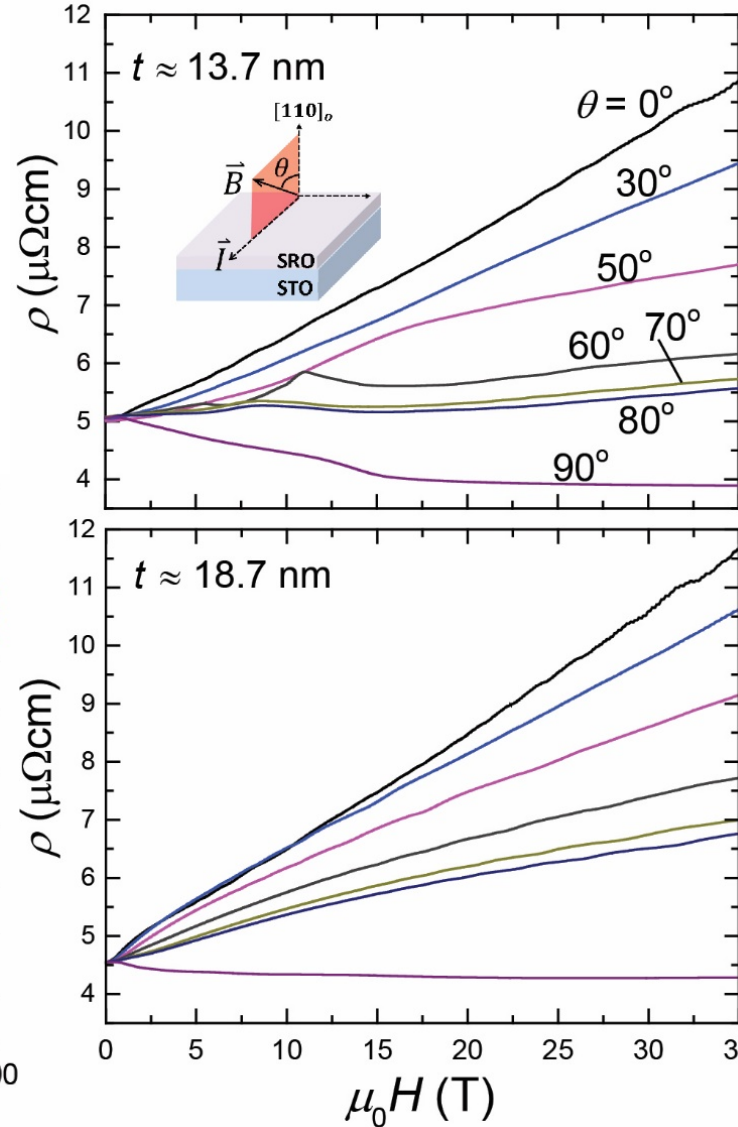
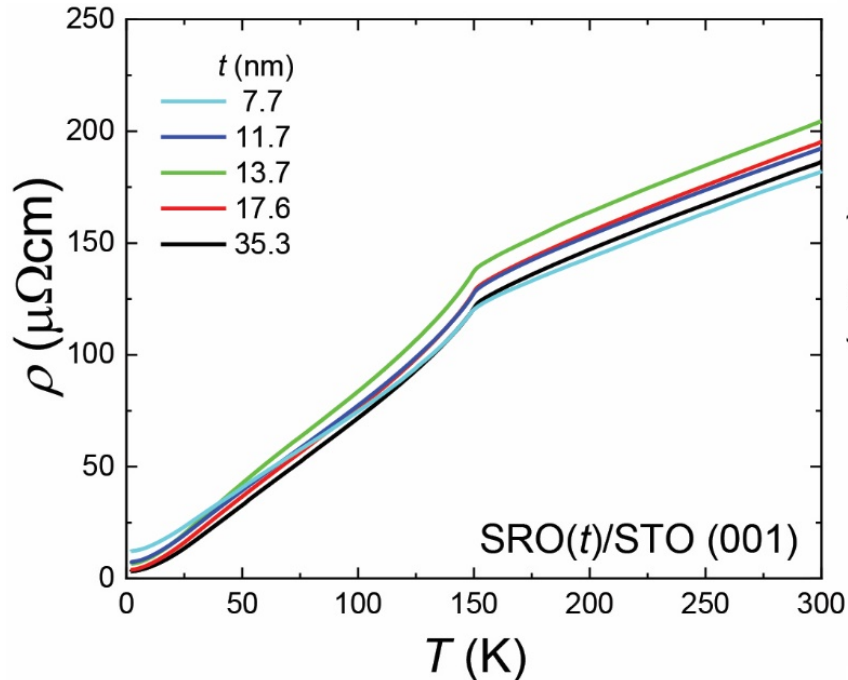
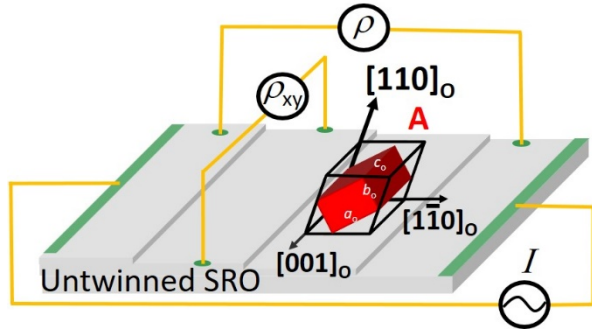


- SRO film was patterned to have exactly the **same Hall bar geometry** to minimize the leads misalignment artifact.
- Agree well with the simulated ρ anisotropy: justifying the **single-domain/untwinned** SRO films

$$\vec{E}_a = \Delta\rho (\hat{a} \cdot \vec{J}) \hat{a}, \text{ and } \hat{a} // [1\bar{1}0]_o.$$

- The magnetic coercive field (H_c) ~ 0.3 T, and thus the ρ variation is NOT “magnetization” effect ! (ex: AMR/PHE), $\vec{M} \perp \vec{I}$ is always satisfied.
- For the following quantum oscillation measurements for SRO films with different thicknesses (t), same measurement geometry of $\vec{I} // [1\bar{1}0]_o$ to avoid complication due to anisotropy effect.

Thickness dependent magnetotransport in untwinned SRO films on miscut SrTiO3 (001) sub.



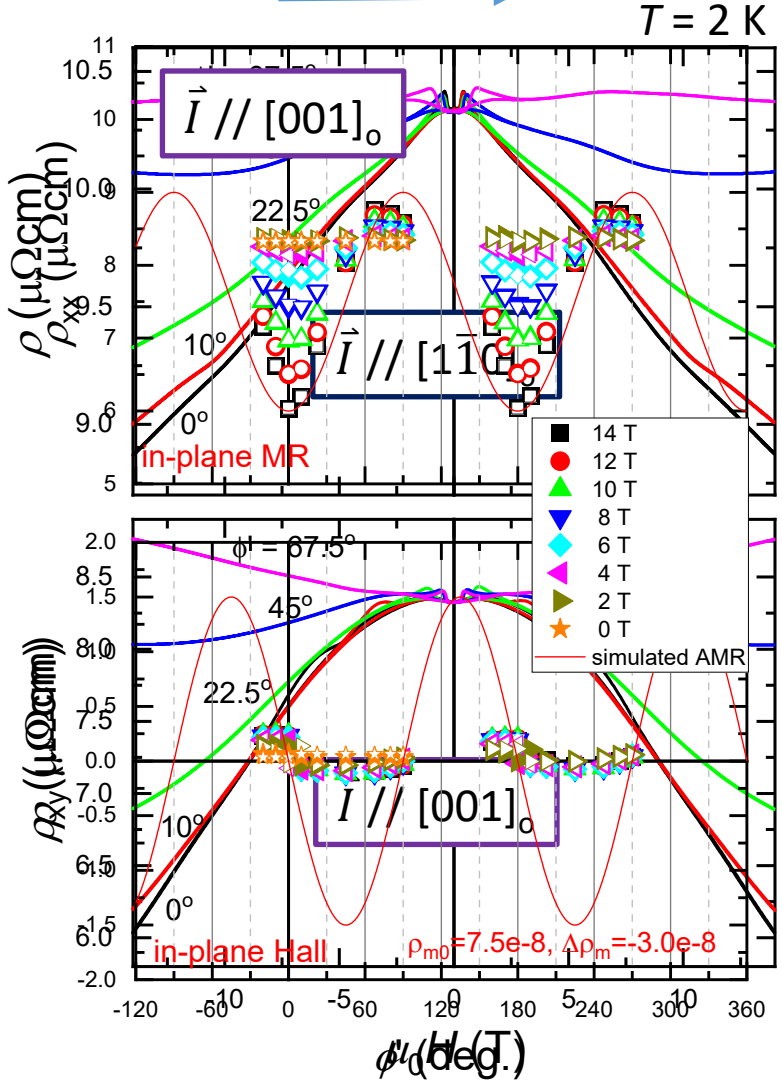
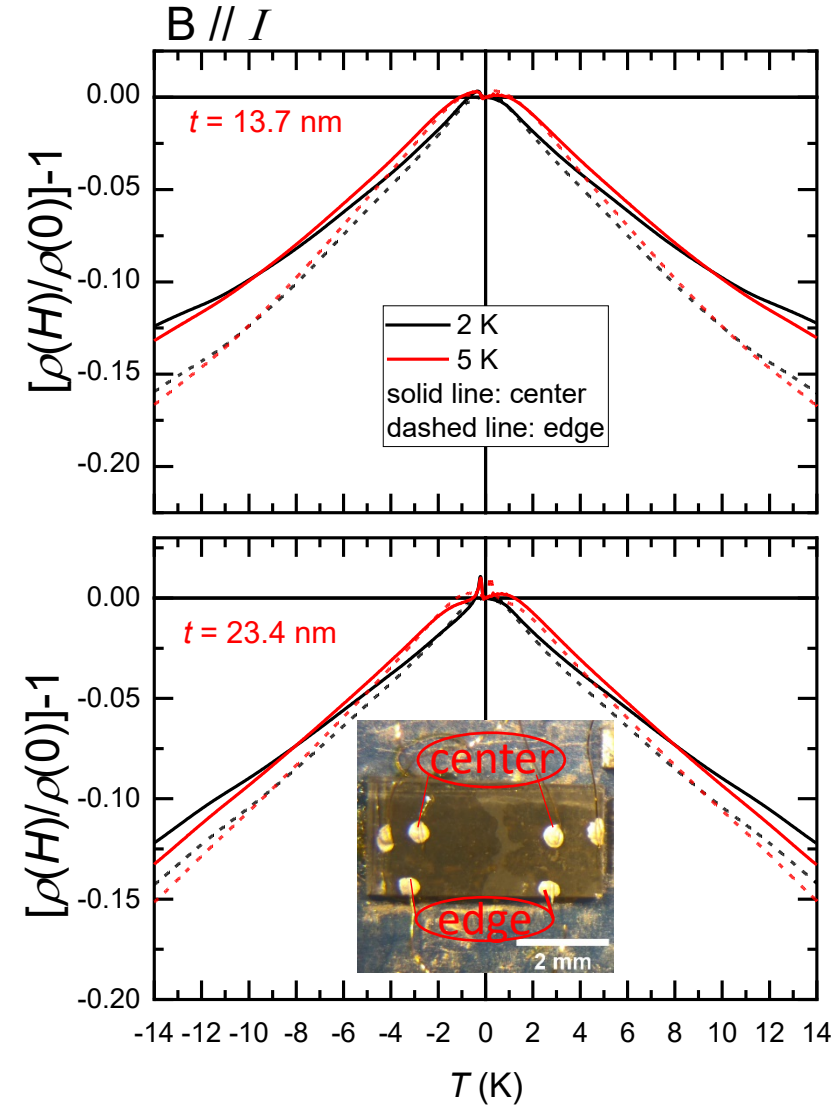
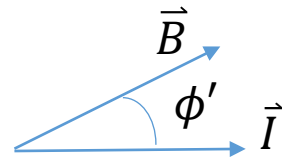
Adsorption-controlled growth by oxide MBE
 Dominant A domain with a volume fraction more than **90%** for $7.7 \text{ nm} < t < 35.3 \text{ nm}$

Kar et al. Sci. Rep. 11, 16070 (2021)

- Use same transport geometry for all untwinned SRO films with different t s
 $\vec{I} \parallel [1\bar{1}0]_o \perp [001]_o$
- For thickness t : 7.7 to 35.3 nm
 RRR ($\rho(300\text{K})/\rho(5\text{K})$): **14.4** to **51.6**
 RR (2.5K): **12.31** to **3.24** $\mu\Omega\text{cm}$
- Consistent MR behavior for a WSM
 - ✓ Large and nonsaturating **positive** MR ($\theta = 0^\circ$)
 - ✓ **Negative** longitudinal MR ($\theta = 90^\circ$):
Chiral anomaly.

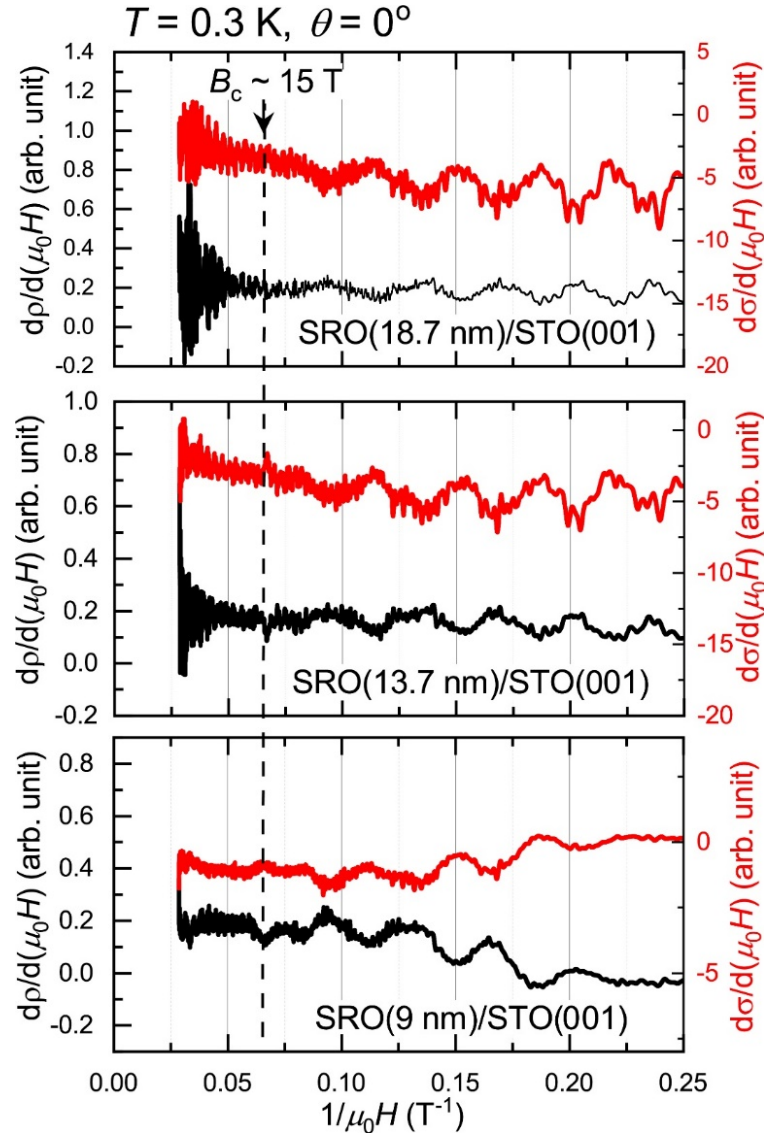
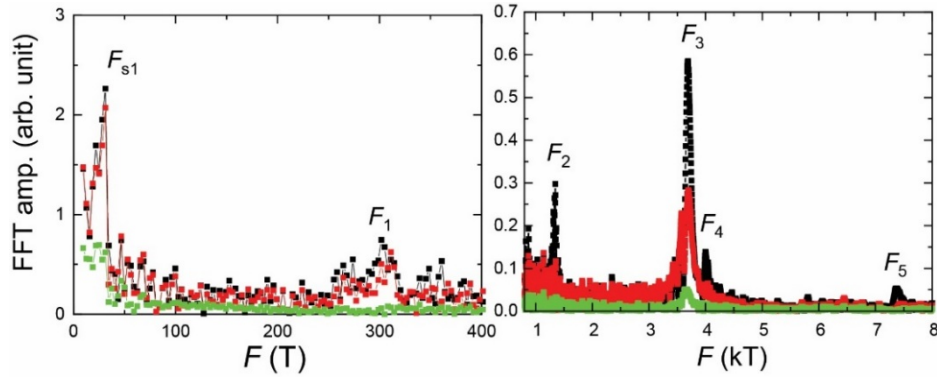
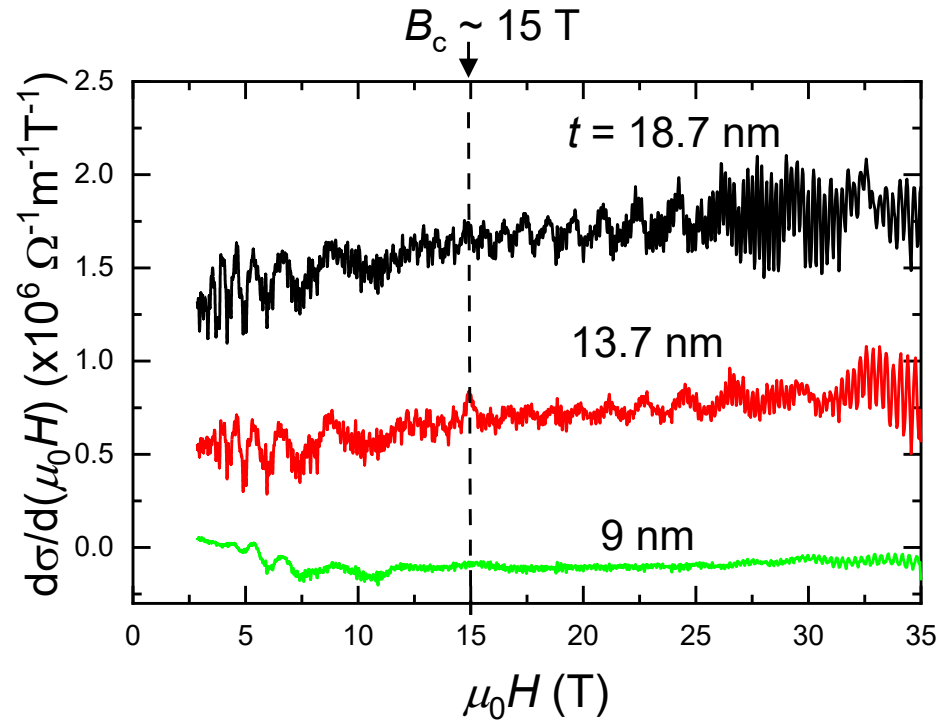
Current jetting or Chiral anomaly ?

Liang *et al.* PRX 8, 031002 (2018)



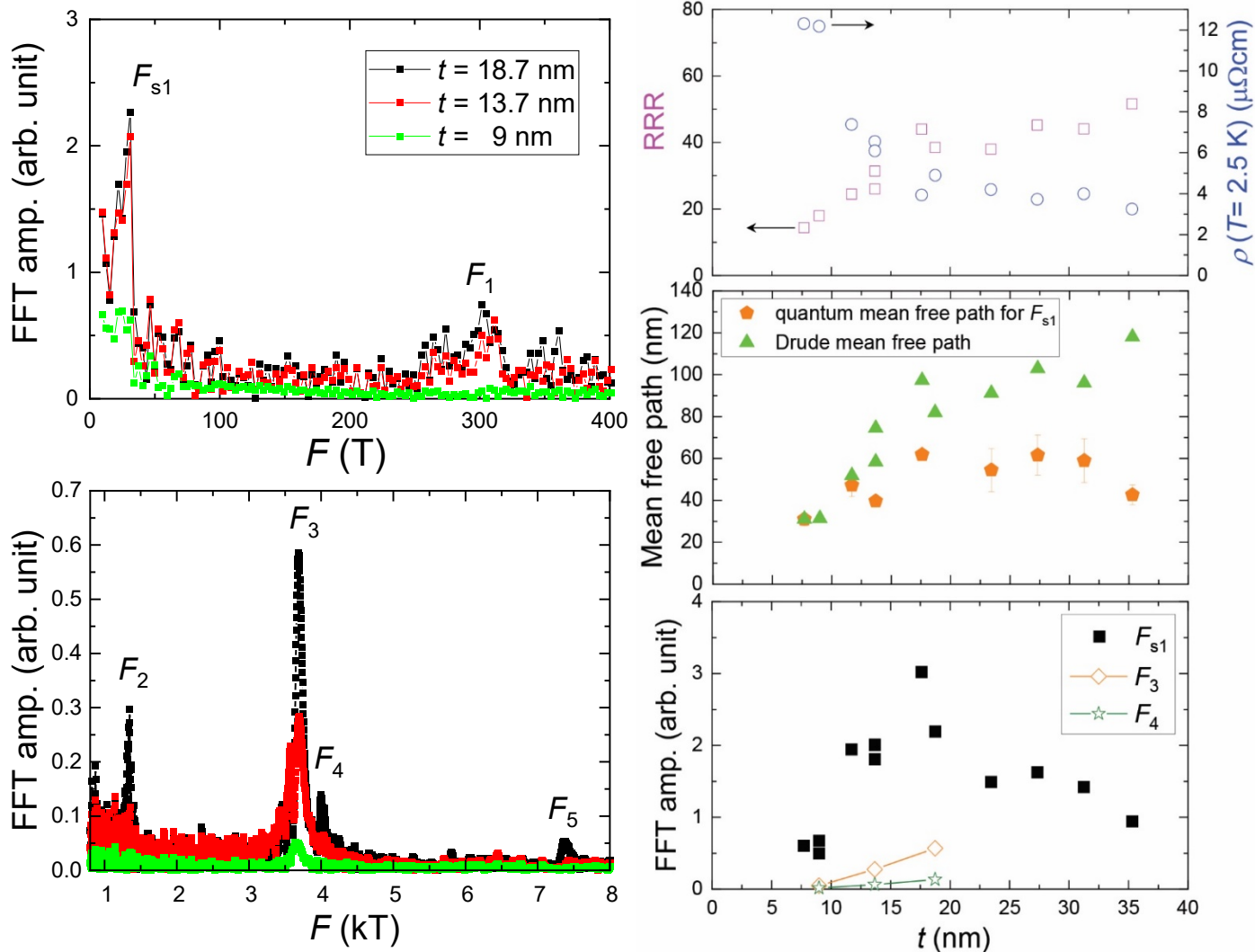
- Varying contact locations: consistent **negative MR** behavior.
- Same negative MR for $B // I$ for $I // [001]_o$.
- $B_{cyc} \sim 16$ T: using mobility $\mu_e \sim 3,000$ cm^2/Vs , and set $\mu_e B_{cyc} \sim 5$.
- Quantum limit field $B_Q \sim 15$ T for a single spin subband with a pocket size of $F = 30$ T.
- $B_{cyc} \sim B_Q$, current jetting may not be significant.
- More rigorous ϕ' -dep. MR, the large negative MR for $\phi' \approx 0$ can not be simply due to anisotropy MR (or planar Hall effect) in a magnet.

High field quantum oscillations in untwinned SRO films



- For $\mu_0 H > 3$ T, $F_{s1} \sim 30$ T appears.
- For $\mu_0 H > 12$ T, F_{1-5} from 300 T to 7,500 T appears with ampl. increase with t .
- $F_{s1} \sim 30$ T appears to vanish above $B_c \sim 15$ T for all three samples!

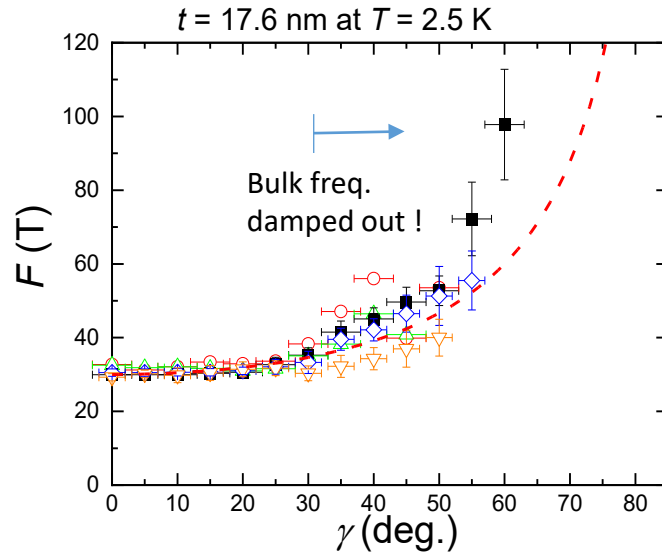
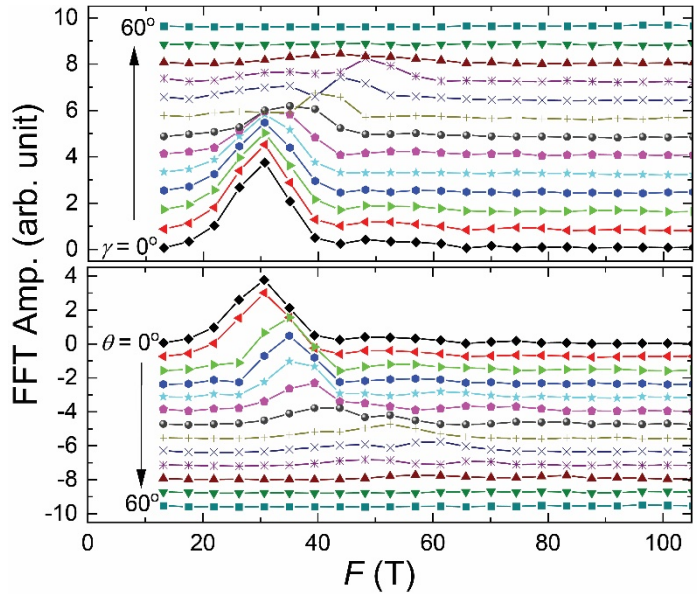
Thickness dep. quantum oscillation



- The extracted **quantum lifetime** for F_{s1} shows relatively weak t -dep. (Cf. progressive increases of Drude MFP with t)
- **Non-monotonic t -dep.** FFT amplitude for F_{s1} (Cf. F_3, F_4 show progressive increases of FFT amplitude with t as expected)
- F_{s1} does not appear to be largely affected by the bulk scattering: surface origin ?
- From temp.-dep. QO data:
 F_{1-5} from 300 T to 7,500 T
 $(3 m_e$ and $5 m_e$ for F_1 and $F_3)$
 $F_{s1} \sim 30$ T with $m^* \approx 0.3 m_e$
- For doped-SrTiO₃: $m^* \sim 0.7 - 1.5 m_e$ for light Ti d_{xy}

Kozuka *et al.* Nature 462, 487 (2009)
Wang *et al.* Nat. mater. 15, 835 (2016)

θ and γ angular dependent quantum oscillations for $F_{s1} \sim 30$ T

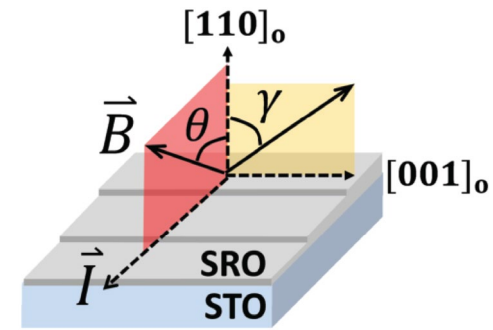
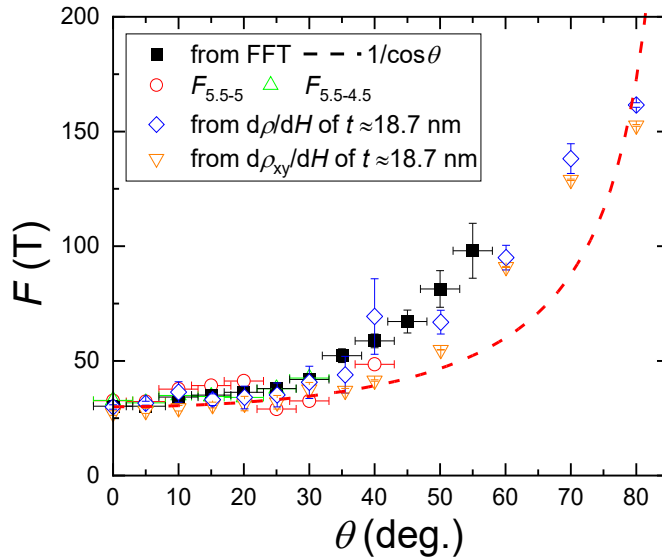


- Splitting of F_{s1} in FFT spectra at intermediate angles may infer competing QO contributions: **3D bulk Fermi pockets**, **3D Weyl nodes** and surface-origin effect (Weyl-orbit QO).

- As θ and γ increases above $\sim 30^\circ$, bulk freq. F_{1-5} damped out faster due to surface/interface scatterings.

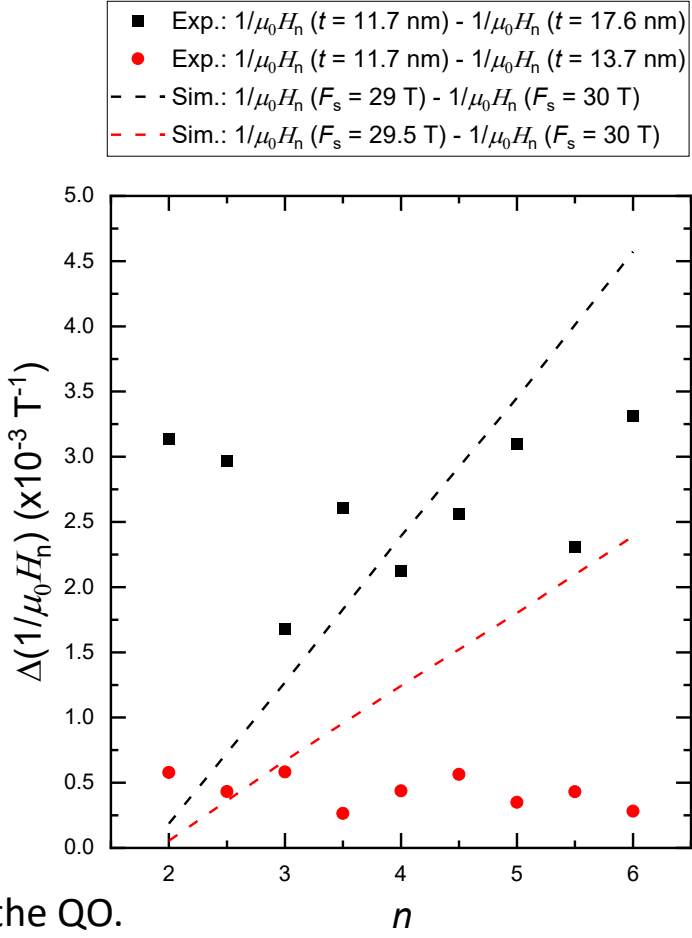
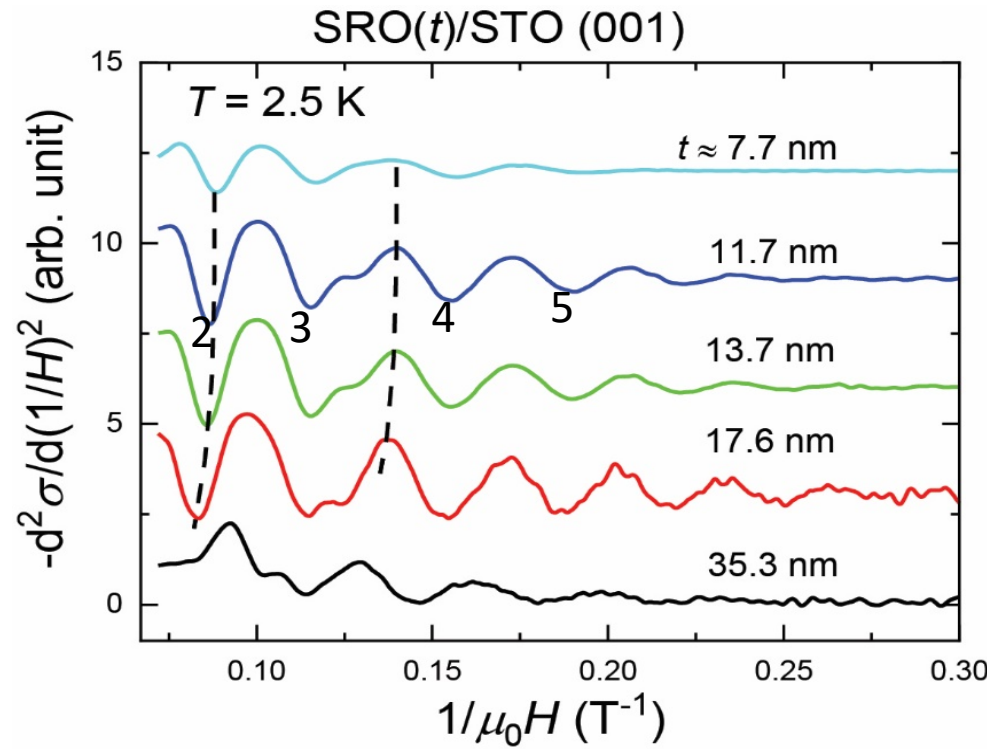
Drude ℓ_d (≈ 100 nm) $\gg t$ (≈ 13.7 nm) $\approx \ell_B$ (4.7 nm @ 30 T)

- For the QO of F_{s1} , **$1/\cos(\text{angles})$** dependences are observed for both θ and γ rotations, inferring a **2D-like Fermi pocket** for F_{s1} .



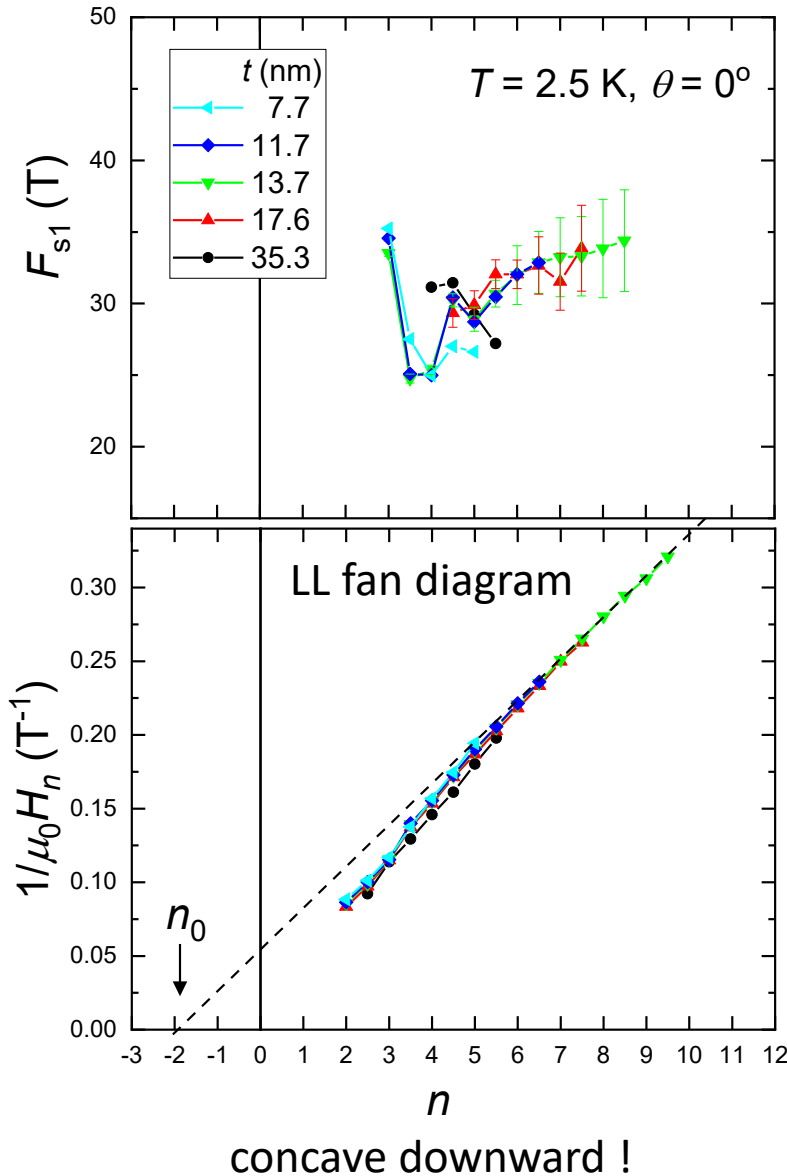
c.f. Kaneta-Takada et al. npj QM 7, 102 (2022)

Unique thickness dep. of the QO phase for $F_{s1} \sim 30$ T



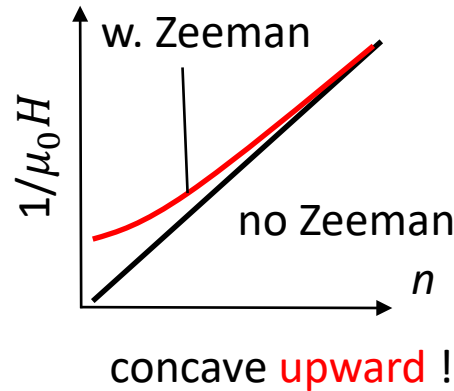
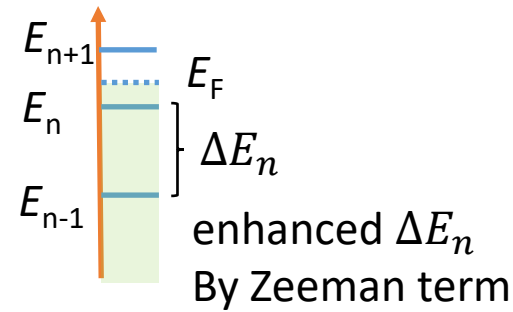
- Using derivatives ($d\sigma/dH$ or $-d^2\sigma/d(1/H)^2$) to avoid possible distortions to the QO.
- σ_{xx} minima or ρ_{xx} maxima: integer LL index n (Xiong et al. PRB 86, 045314 (2012))
For a 3D system with coexistence of bulk conductivity, and $\rho_{xx} = \sigma_{xx} / [\sigma_{xx}^2 + \sigma_{xy}^2] \sim 1/\sigma_{xx}$.
- Oscillation ampl. is largest for $10 \text{ nm} < t < 20 \text{ nm}$.
- Thickness dep. QO: progressive shifts of the peak/valley to lower $1/\mu_0 H_n$ value when t goes from 7.7 to 17.6 nm.
- Weyl-orbit QO: $\frac{1}{\mu_0 H_n} = \frac{e}{\hbar k'_0} \left[\frac{\pi \hbar v n}{\mu} - L_z \right]$.
- The amount of phase shift is nearly "n"-indep.: phase shift due to small density variation can be excluded.

Unique concave downward feature for $F_{s1} \sim 30$ T



LL spectrum of a conical band:

$$E_n = v_F \sqrt{(2ne\hbar B + \underbrace{(g\mu_B B / 2v_F)^2}_{\text{Zeeman term}})}$$



- LL fan diagram shows an unique and unusual **concave downward** curvature, and thus the extracted F_{s1} value gradually decreases with LL index n .

Cf. Zeeman coupling energy gives an opposite curvature (concave upward) !

- If treating $B_c \sim 15$ T as the field for the quantum limit, an unusual large intercept $n_0 \approx -2$ was observed.

Cf. For a typical 3D band,

$$n_0 = \begin{cases} \pm \frac{1}{8}, & \text{trivial band.} \\ \pm \frac{5}{8}, & \text{conical band } (\pi \text{ Berry phase).} \end{cases}$$

Xiong *et al.* PRB 86, 045314 (2012)

Wang *et al.* PRL 117, 077201 (2016)

- Demagnetization field, H_d :

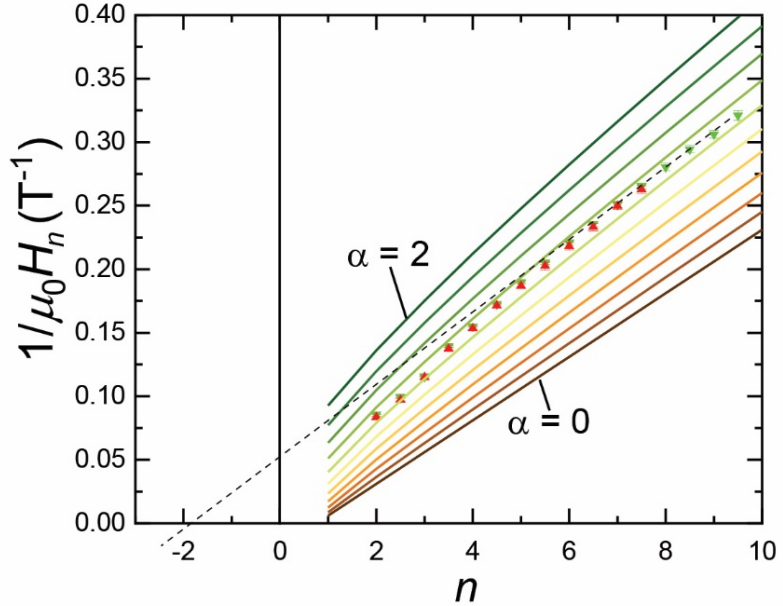
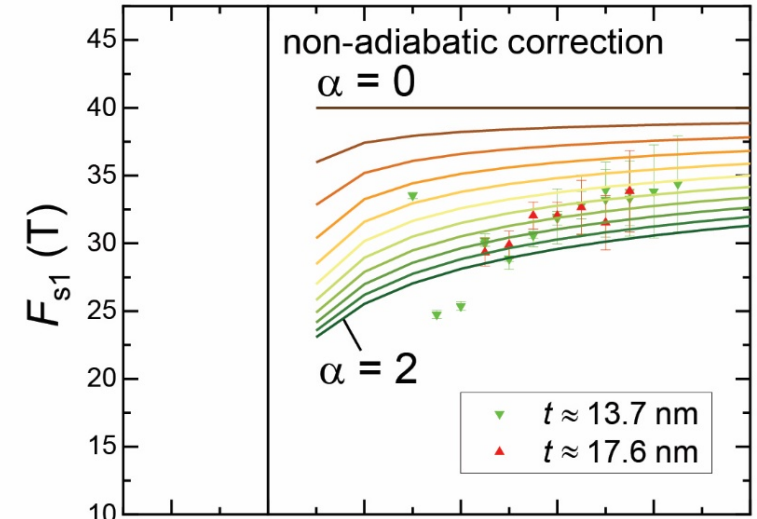
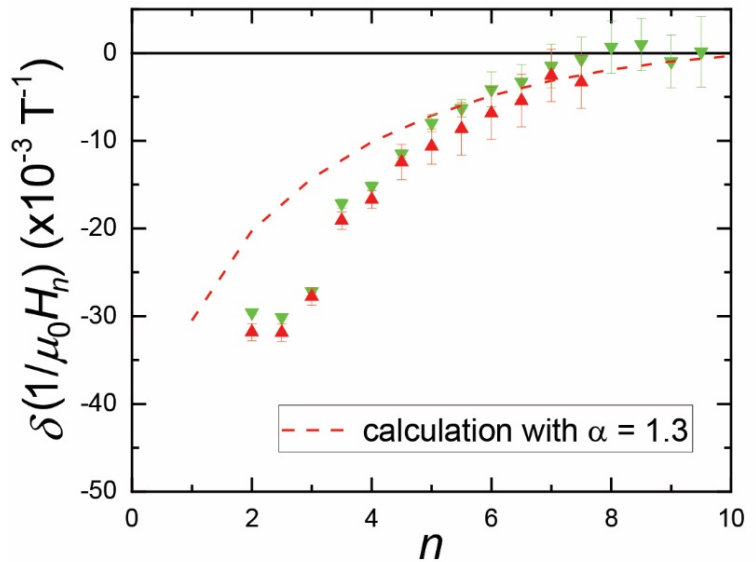
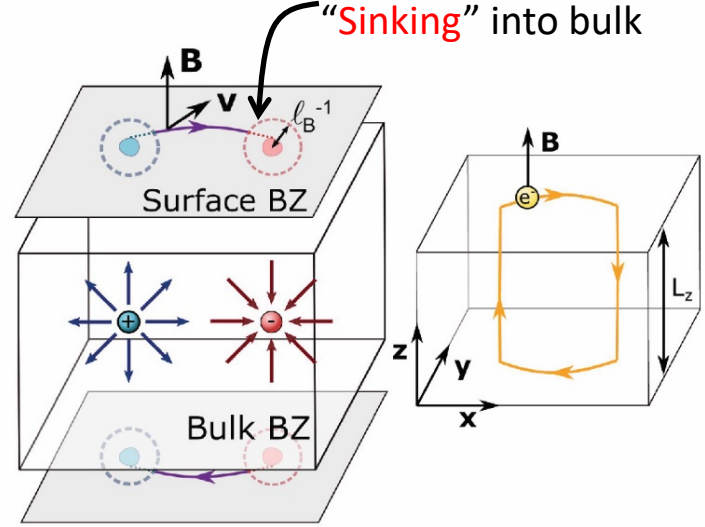
$$\mu_0 H_d = -D_t M_{sat} \approx 0.3 \text{ T}$$

(Coercive field $H_c \sim 0.3$ T)

The influence of non-adiabatic corrections to Weyl-orbit quantum oscillations

Non-adiabatic corrections:

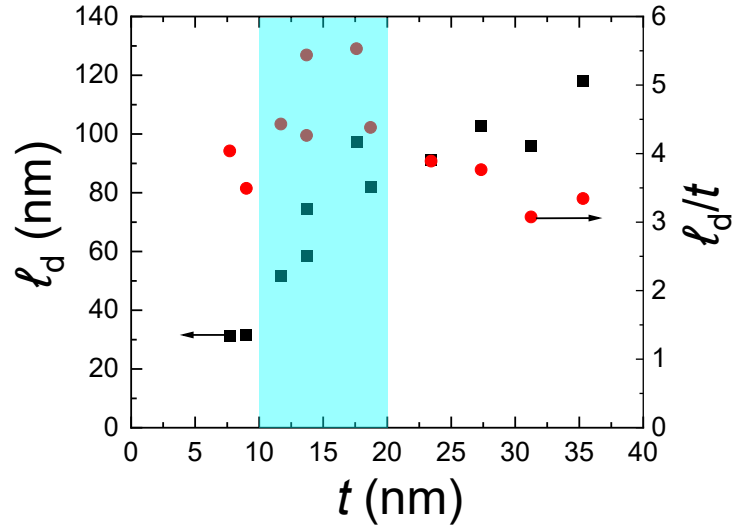
“Sinking” into bulk



- “Sinking” into the bulk states before reaching the projected nodes: reduced area enclosed by Weyl-orbit with a relevant length scale of $1/\ell_B$ in k-space. (magnetic length ℓ_B (5 T) \approx 11 nm)
Cf. Surface-bulk connectivity via nodes revealed in QPI STM (Inoue *et al.* *Science* 351, 1184 (2016), Batabyal *et al.* *Sci. adv.* 2, e1600709 (2016))
- Non-adiabatic correction factor α :

$$\frac{1}{\mu_0 H_n} = \frac{e}{\hbar k'_0} \left[\frac{\pi \hbar v n}{\mu} - L_z \right].$$
 $k'_0 \equiv k_0 (1 - 4\alpha/k_0 \ell_B)$, and α is non-adiabatic correction param.
- Simulated curves with $L_z = 13.7$ nm (NO any other adjusting param. !!):
 - ✓ Concave downward curvature increases with increasing α .
 - ✓ Upward shifting: a large intercept n_0 .
- Extracted Weyl-orbit QO parameters:
 $k_0 = 1.09 \text{ nm}^{-1}$, $\alpha = 1.3$,
 $\mu = 15.43 \text{ meV}$, $v = 1.34 \times 10^5 \text{ m/sec}$
- Sizable effect for α term even in low field:
 $1/\ell_B$ (5 T) $\approx 0.1 \text{ nm}^{-1}$, $k'_0 \approx 0.6 k_0$! $B_{sat} \sim 30 \text{ T} > B_c$.

Optimum thickness of $10 \leq t \leq 20$ nm for the Weyl-orbit QO effect

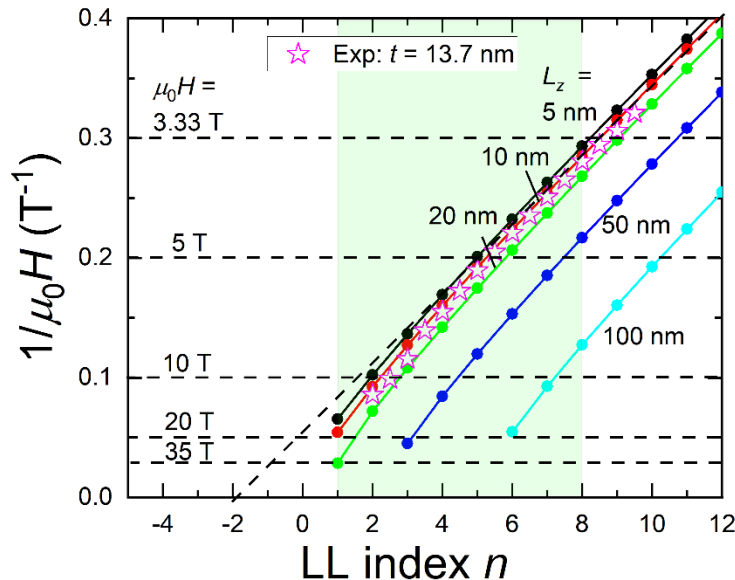


Simulated WOE Landau fan diag.

Thickness dep. WOE

$$\frac{1}{\mu_0 H_n} = \frac{e}{\hbar k'_0} \left[\frac{\pi \hbar v n}{\mu} - L_z \right]$$

$k_0 = 1.09 \text{ nm}^{-1}$
 $\alpha = 1.3$
 $\mu = 15.43 \text{ meV}$
 $v = 1.34 \times 10^5 \text{ m/sec}$



- The ratio of ℓ_d/t governs the bulk tunneling amplitude in the Weyl-orbit QO: (Drude MFP ℓ_d with a bulk density $n_{3D} = 6.1 \times 10^{21} \text{ cm}^{-3}$)
 - ✓ The Weyl-orbit QO is favorable for $\ell_d/t > 1$.
 - ✓ Largest ℓ_d/t for $10 \leq t \leq 20 \text{ nm}$: Weyl-orbit QO may be maximized to dominate over 3D bulk QO for $\mu_0 H < 15 \text{ T}$. (note: F_{1-5} from 300 T to 7,500 T appears for $\mu_0 H > 12 \text{ T}$.)
- $t \leq 20 \text{ nm}$ can reveal Weyl-orbit QO within a **relatively lower field range**, where its ampl. can dominate over that from other 3D bulk pockets, and both **large n_0** and **downward concave** feature can be clearly identified !
- Competition between **Bulk 3D pockets**, **tunnel ampl.** and **disorder-induced** suppression of Fermi-arcs/WSM phase
 - For $t \gg 20 \text{ nm}$:
 - Further decline of the **bulk tunneling ampl.** ($\exp(-t/\ell_d)$) !
 - $1/H_n - n$ curve shift downward: need higher field for the WO QO !
 - Increased QO contribution from the bulk 3D pockets.
 - For $t \ll 10 \text{ nm}$:
 - Rapid drop of the ℓ_d due to increased surface scattering plus increased **disorder** in ultra-thin SRO films.
 - Suppression of both Weyl-orbit and bulk 3D Weyl nodes QO.

Wilson *et al.* PRB 97, 235108 (2018)

Revealing surface charge transport in thin films of topological Weyl metal SrRuO₃

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Outline

□ Review of the topological Weyl semimetal and ferromagnetic Weyl metal SrRuO₃ (SRO) system:

- Brief review of magnetic Weyl semimetal and **Bulk-surface correspondences** in topological Weyl metal SRO.
- Adsorption control growth of SRO thin films using oxide MBE facility at IoPAS.

□ Weyl-orbit quantum oscillation effect (WQE):

- Structural charac. of **low defect level** and **untwinned** SRO thin films.
- **“Thickness”** dependent quantum oscillations and comp. to simulated Weyl-orbit QO.



□ Nonreciprocal and nonlinear charge transports (NRTE) in SRO thin film:

- Fabrication of **sunbeam** devices from an untwinned SRO thin film for anisotropy measurements.
- Observation of **NRTE** and **nonlinear Hall effect** in SRO thin film at low temperatures.

□ Conclude and future outlooks

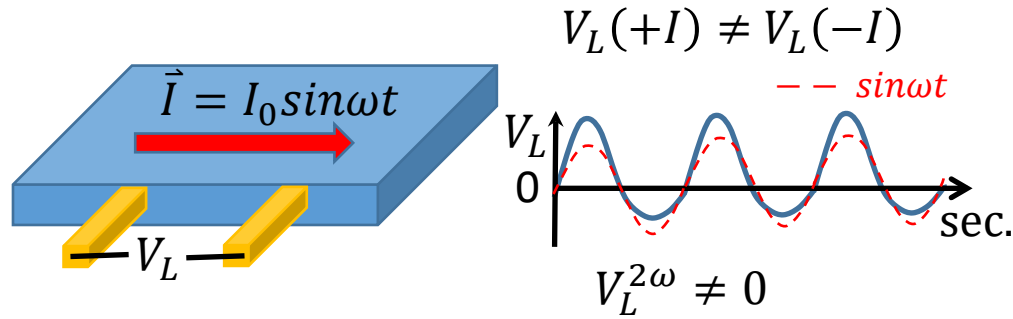
Kar et al. Sci. Rep. 11, 16070 (2021).

Kar et al. npj Quantum Materials 8, 8 (2023).

Kar et al. arXiv:2307.04482, submitted.

Nonreciprocal and nonlinear charge transport effects in single-phase materials (selected)

NRTE (current rectification)



Selected examples for NRTE (incomplete)

- Magneto-chiral effect: $V_L = V_{L0}(1 + \gamma I \cdot (\vec{P} \times \vec{B}))$.
Breaking both **inversion sym:** \hat{I} and **Time-reversal sym:** \hat{T}
- Velocity asymmetry with broken \hat{I} .
Ex: TI surface state, gapped BLG with trigonal warping ...
- Asymmetry scattering effect with \hat{I} breaking surface states.
Ex: between chiral edge modes of QAHE and surface states

Rikken & Wyder, PRL 94, 016601 (2005)

Tokura and Nagaosa, Nat. Commun. 9, 3740 (2018)

He et al., Nat. Phys. 14, 495 (2018)

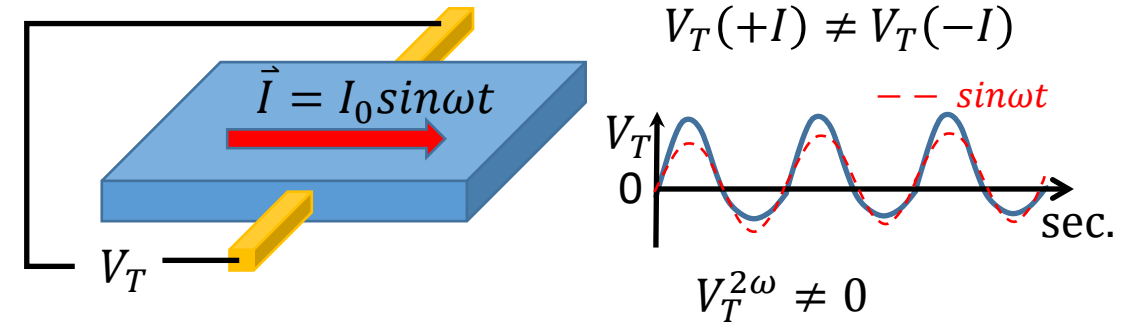
Lu et al., Phys. Rev. Research 3, 033160 (2021)

Kou et al. PRL 113, 137201 (2014)

Yasuda et al., Nat. nanotech. 15, 831 (2020)

NRTE and NLH Can be a probe for detecting broken \hat{I} ! (c.f. optical SHG)

Nonlinear Hall effect (NLH, Hall current rectification)



Possible mechanisms for NLH (incomplete)

- Intrinsic Berry curvature effect and **quantum metric dipole** (D_M): PT symmetric AFM BP/MnBi2Te4/BP
- Extrinsic **Berry curvature dipole** (D): $J_a^{2\omega} \propto \tau D_{ba} E_b^2$
 $D_{bd} \equiv \int \frac{dk^3}{(2\pi)^3} f_0 \frac{\partial \Omega_b}{\partial k_d}$, (ex: bilayer WTe2...)
- Extrinsic **skew scattering** and **side jump** effects.
- Broken \hat{I} is needed for nonzero NLH.

Gao, Yang, Niu, PRL 112, 166601 (2014)

Gao et al., Science 381, 6654 (2023).

Sodermann and Fu PRL 115, 216806 (2015).

Ma et al., Nature 565, 337 (2019).

Du et al. Nat. Commun. 10, 3047 (2019).

Scale-Invariant Quantum Anomalous Hall Effect in Magnetic Topological Insulators beyond the Two-Dimensional Limit

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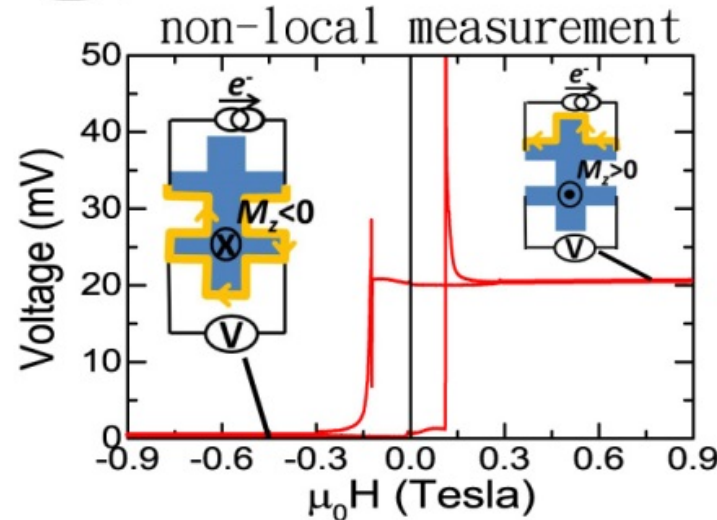
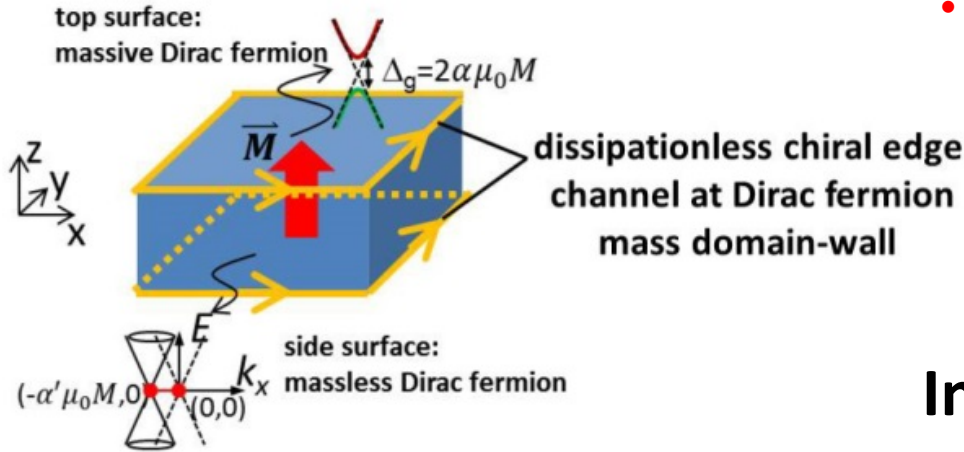
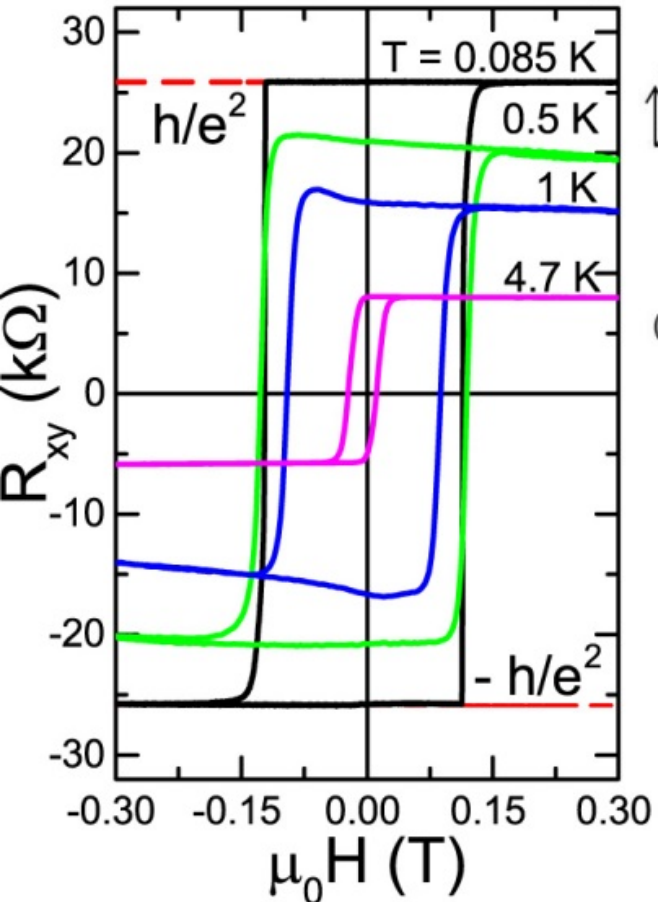
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(Received 26 May 2014; revised manuscript received 28 July 2014; published 26 September 2014)

3D ferromagnetic topological insulator

Cr doped $(\text{BiSb})_2\text{Te}_3$



- “One-way” electron flow of QAHE chiral edge channel can be switched on and off by controlling M_z .
- Co-existence of dissipationless 1D chiral edge mode and a dissipative channel!
- Somewhat robust topological edge/surface states against other trivial states.

Inferring NRTE due to the coexistence of dissipationless chiral edge mode and dissipative channel for a thick magnetic TI!

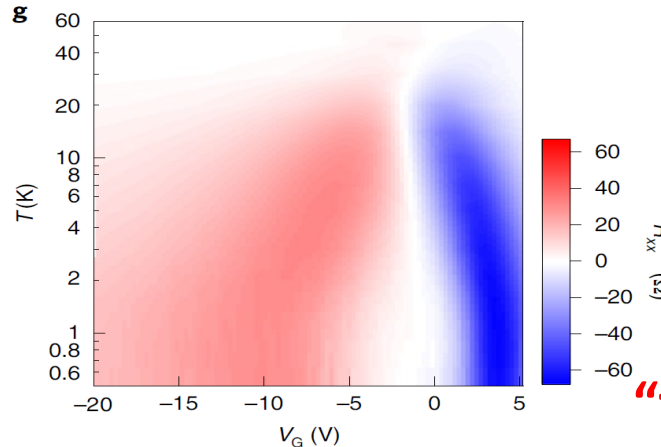
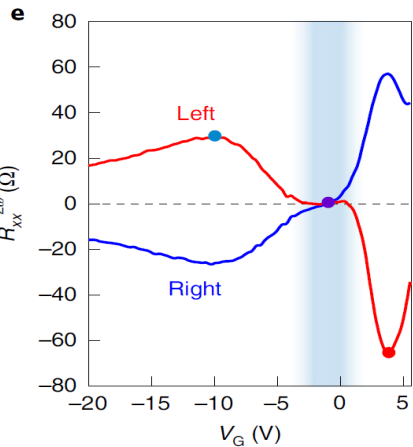
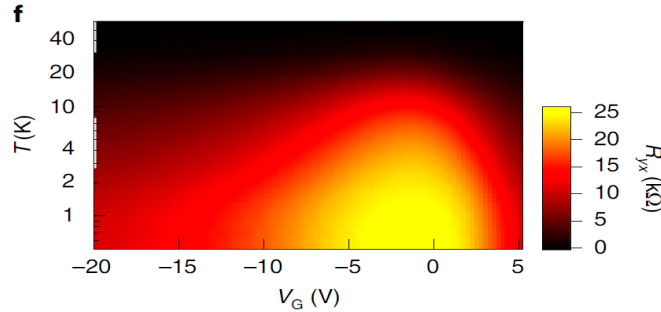
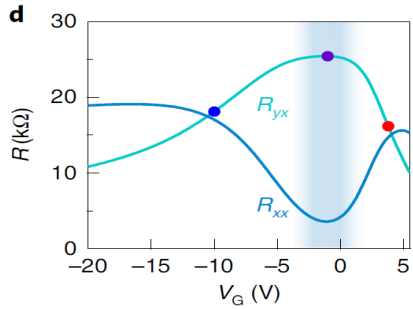
Kou *et al.* PRL 113, 137201 (2014)

In the format provided by the authors and unedited.

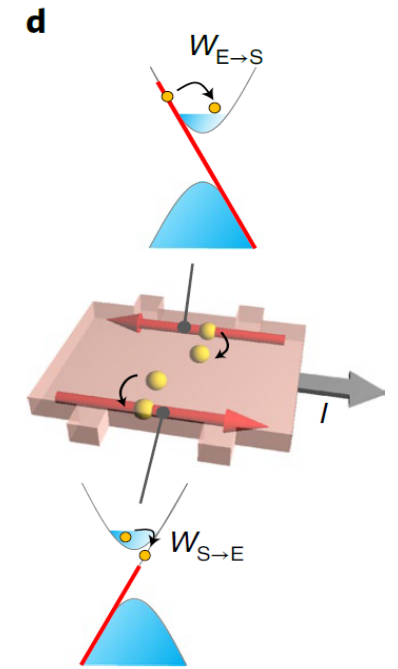
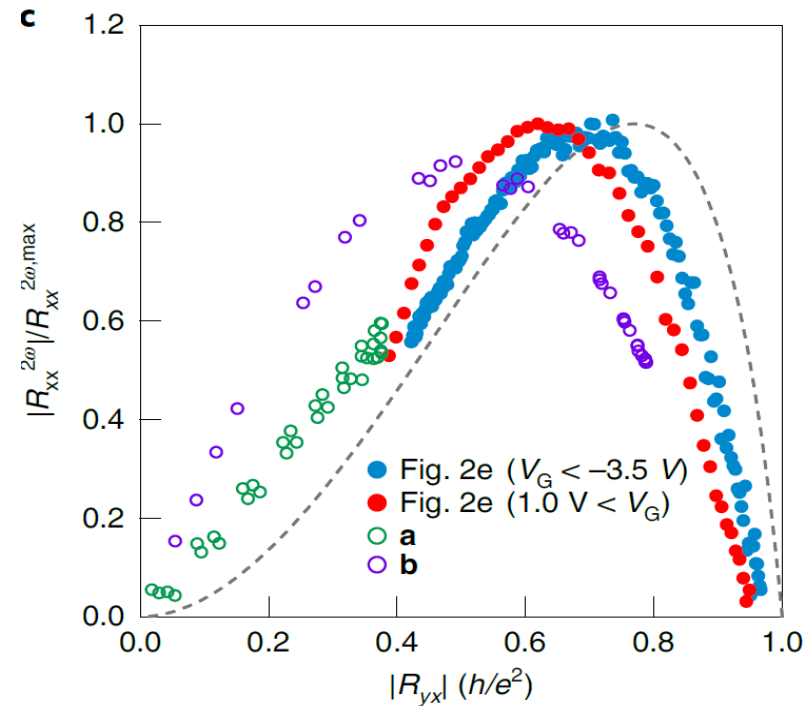
Large non-reciprocal charge transport mediated by quantum anomalous Hall edge states

Kenji Yasuda^{1,6}, Takahiro Morimoto^{1,2}, Ryutaro Yoshimi³, Masataka Mogi¹, Atsushi Tsukazaki⁴, Minoru Kawamura³, Kei S. Takahashi^{2,3}, Masashi Kawasaki^{1,3}, Naoto Nagaosa^{1,3} and Yoshinori Tokura^{1,3,5}

Nat. nanotech. 15, 831 (2020)



Cr-doped Magnetic topological insulator



- Asymmetric scattering between **dissipationless 1D chiral edge modes** with **dissipative surface states**:

$$W_{edge-to-surface}(+I) \neq W_{surface-to-edge}(-I)$$

- NRTE of $R_{xx}^{2\omega}$ is vanishing when 1D chiral edge mode dominates the charge transport.
- The observed NRTE of $R_{xx}^{2\omega}$ persist up to 40 K ($\approx T_c$)!! (C.f. QAHE with $R_{xy} = h/e^2$ only survives up to ~ 1 K !)

“the non-reciprocal resistance measurement may work as a valuable probe to detect the existence of the edge and surface states.”

Quantum Nonlinear Hall Effect Induced by Berry Curvature Dipole in Time-Reversal Invariant Materials

Inti Sodemann and Liang Fu

Department of Physics, Massachusetts Institute of Technology, Cambridge, Massachusetts 02139, USA

(Received 11 August 2015; published 20 November 2015)

PRL 115, 216806 (2015)

Second harmonic transverse current density:

$$j_a^{2\omega} = \chi_{abb} E_b^2$$

$$\chi_{abb} = \frac{e^3 \tau}{2\hbar^2 (1+i\omega\tau)} D_{bc}$$

Berry curvature dipole (BCD) $D_{bd} \equiv \int_k f_0 \frac{\partial \Omega_d}{\partial k_b}$

NLH will appear only when there is current component along \vec{D}

Taking into account the anisotropy effect:

ρ_a and ρ_b are the resistivity along two principal axes

and setting a BCD along \hat{b}

$$\chi_{abb} = -\chi_{bba} \equiv \chi_b \propto D_{bc}$$

$$\text{Nonlinear Hall resistance } R_y^{2\omega} = \frac{\chi_b \rho_a \rho_b^2}{W t^2} I \sin \alpha,$$

α : angle between bias current and \hat{a}

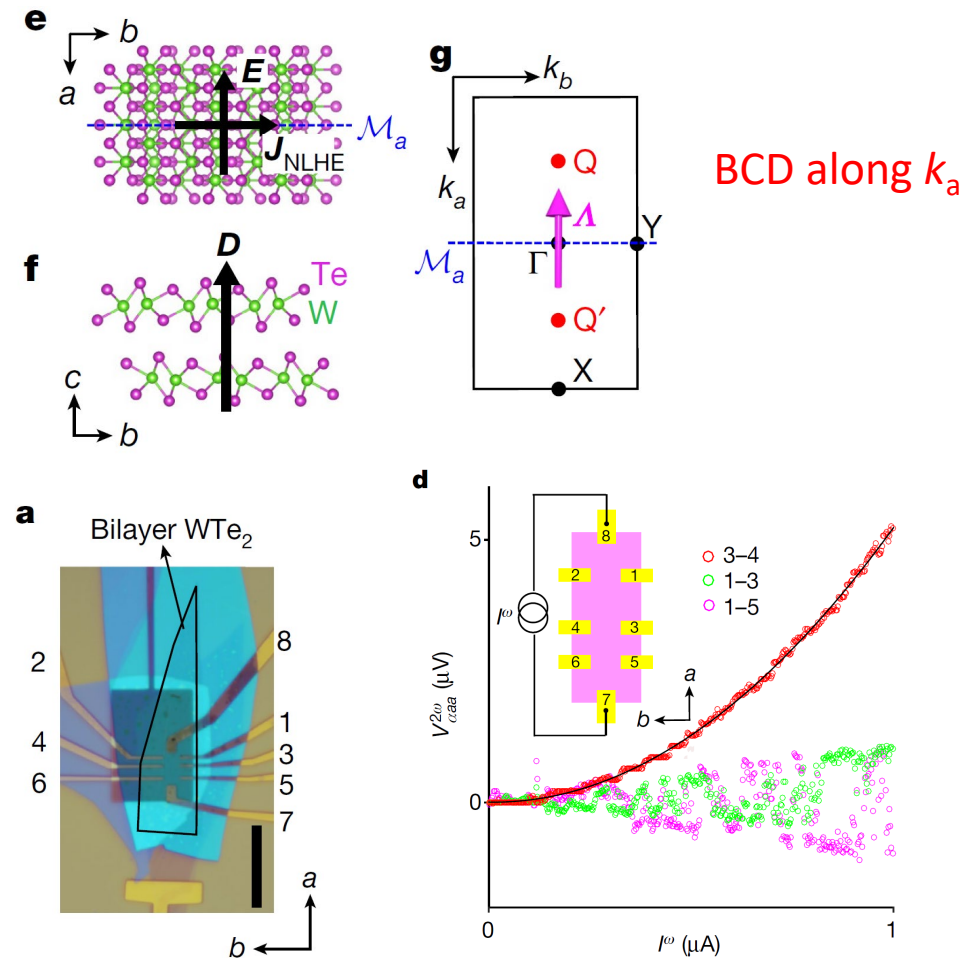
Kar et al. arXiv:2307.04482, submitted.

Observation of the nonlinear Hall effect under time-reversal-symmetric conditions

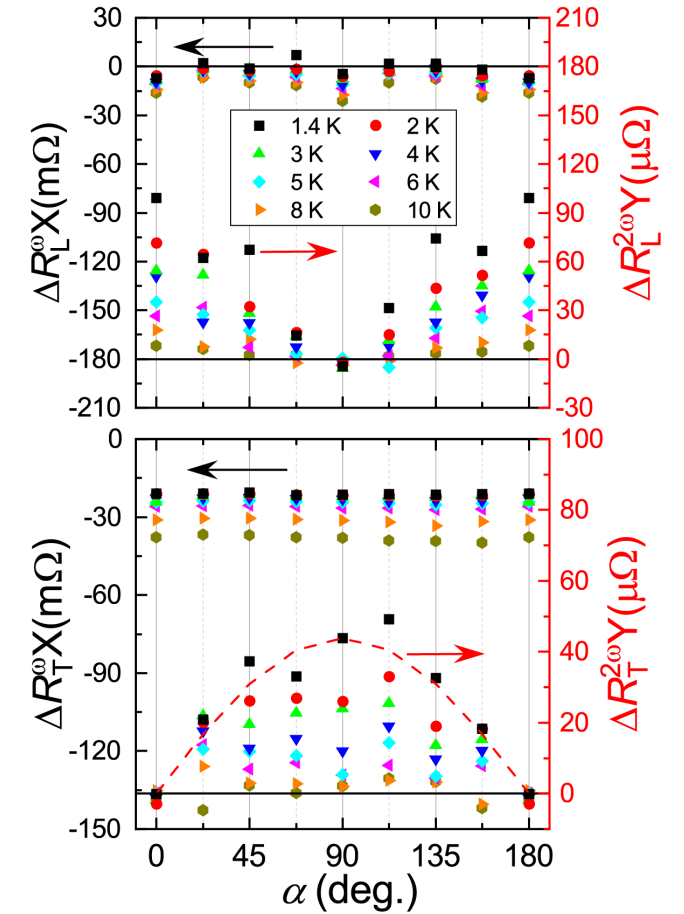
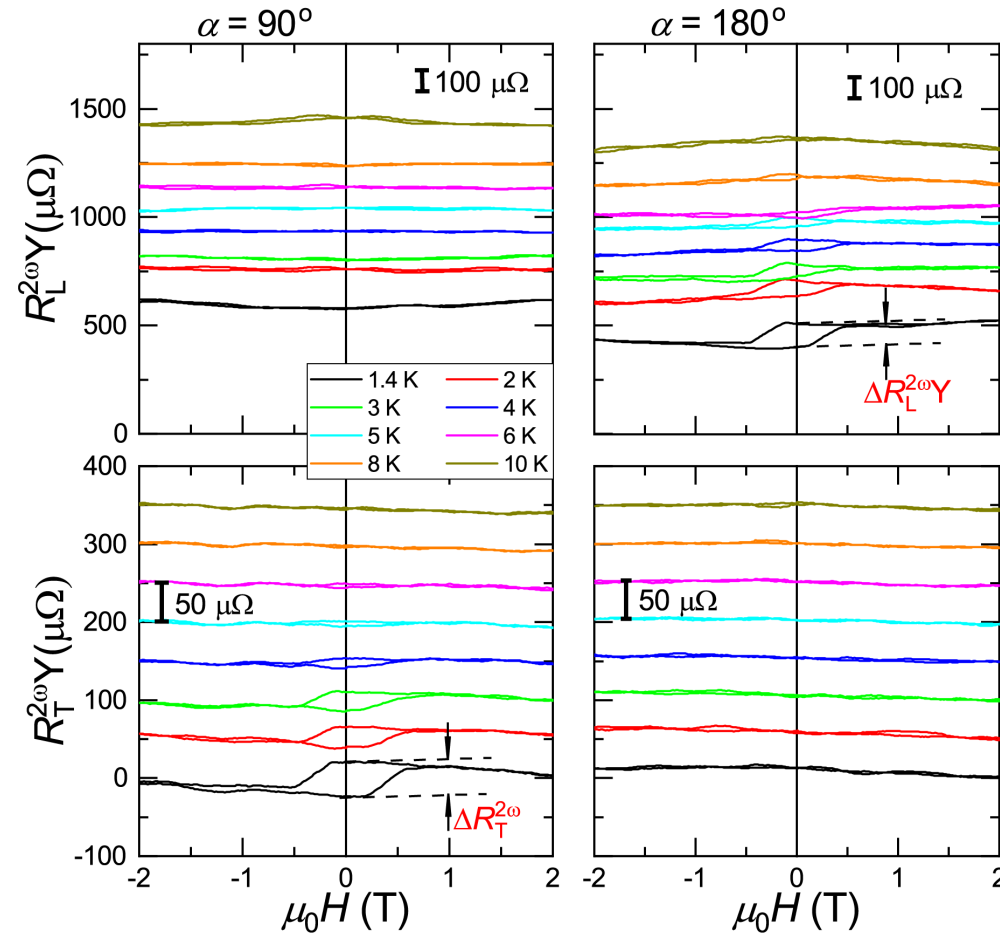
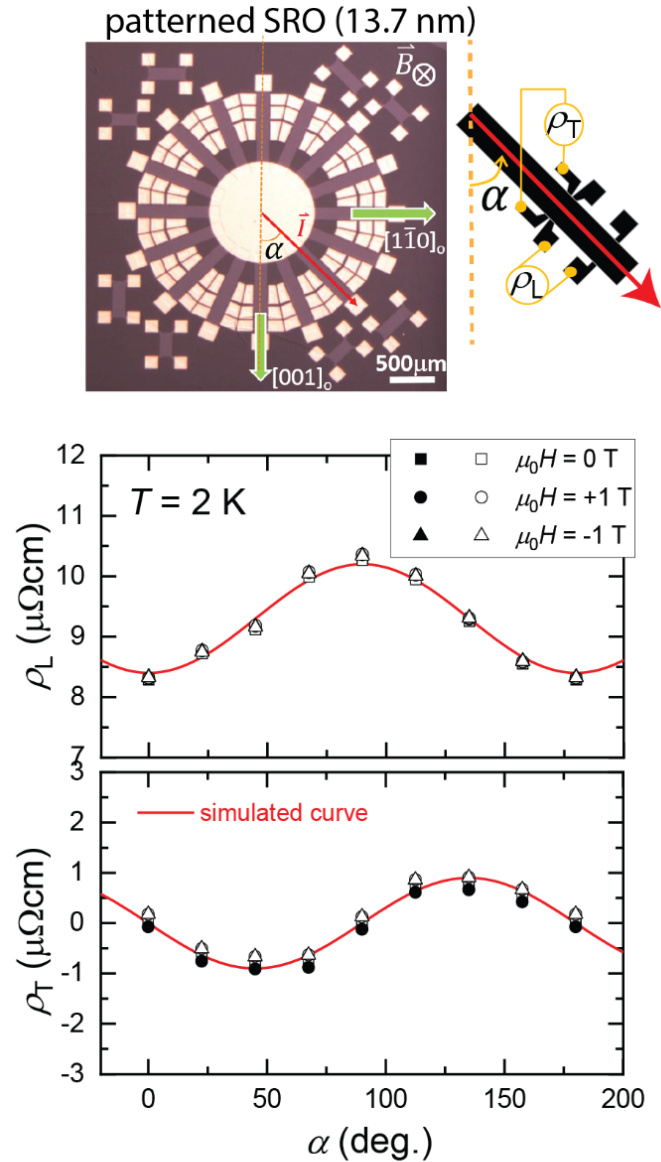
Qiong Ma^{1,13}, Su-Yang Xu^{1,13}, Huitao Shen^{1,13}, David MacNeill¹, Valla Fatemi¹, Tay-Rong Chang², Andrés M. Mier Valdivia¹, Sanfeng Wu¹, Zongzheng Du^{3,4,5}, Chuang-Han Hsu^{6,7}, Shiang Fang⁸, Quinn D. Gibson⁹, Kenji Watanabe¹⁰, Takashi Taniguchi¹⁰, Robert J. Cava⁹, Efthimios Kaxiras^{8,11}, Hai-Zhou Lu^{3,4}, Hsin Lin¹², Liang Fu¹, Nuh Gedik^{1*} & Pablo Jarillo-Herrero^{1*}

Ma et al., Nature 565, 337 (2019).

Broken \hat{I} in bilayer WTe₂ with a mirror plane M_a

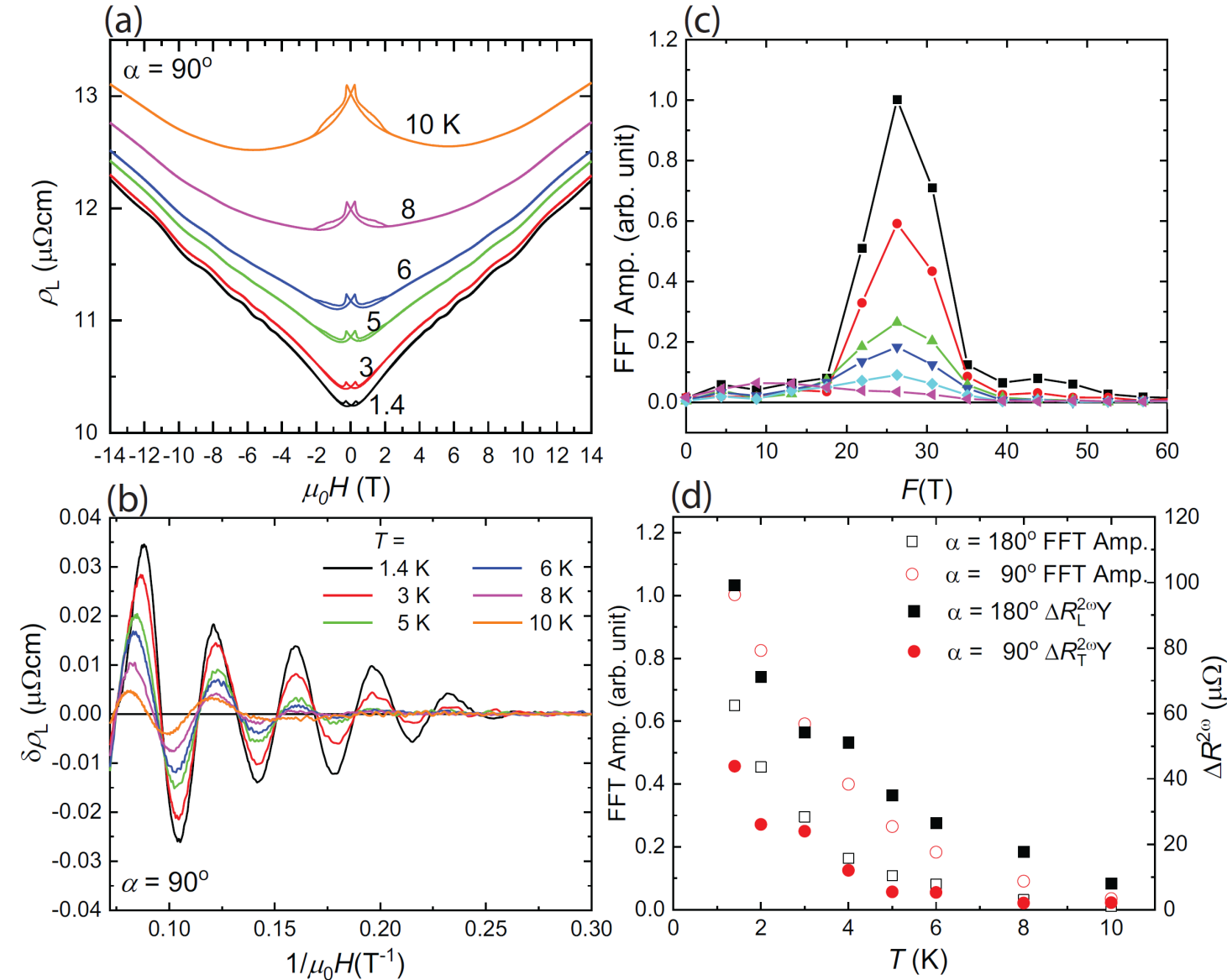


Observation of NRTE and NLH in SRO thin film for $T < 10$ K



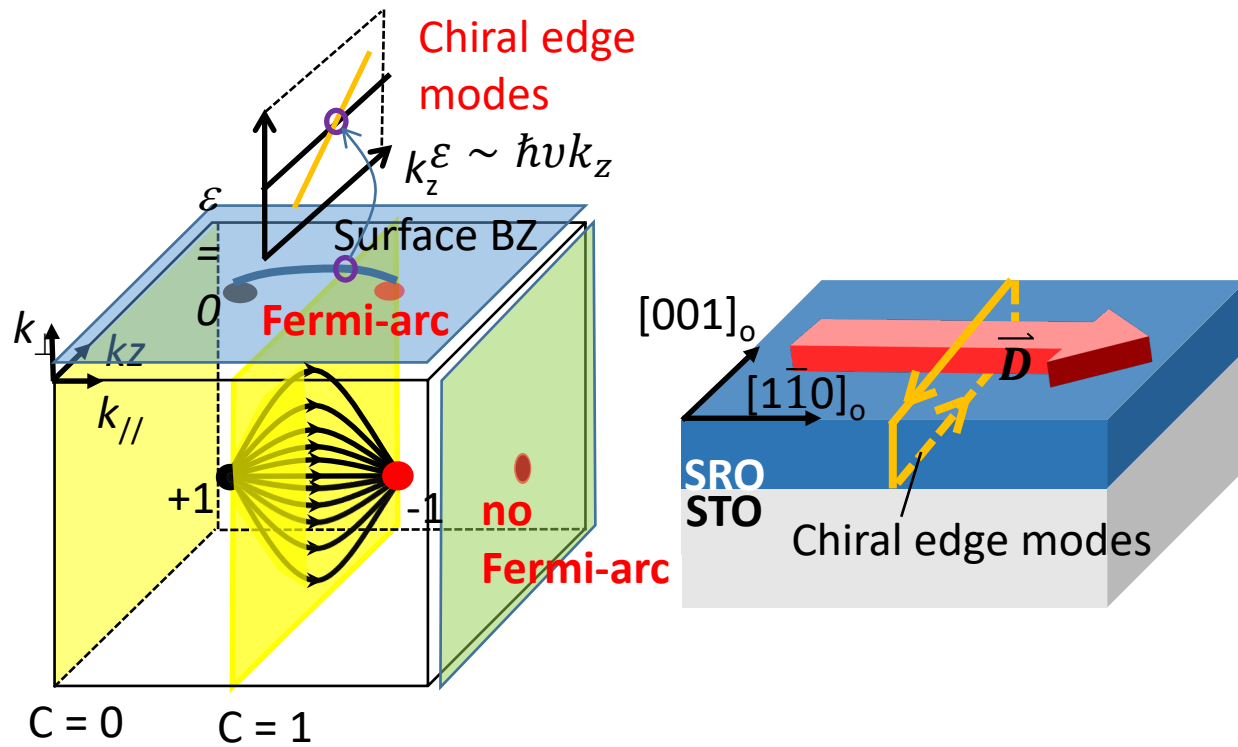
- Non-linear and non-reciprocal charge transport in both ρ_L and ρ_T in zero magnetic field.
- $\Delta R_T^{2\omega} \propto \sin \alpha$, while $\Delta R_L^{2\omega} \propto |\cos \alpha|$: orthogonality in the magnitude for $\Delta R_T^{2\omega}$ and $\Delta R_L^{2\omega}$.
- **Observed $\Delta R_T^{2\omega}$ and $\Delta R_L^{2\omega}$ are surprising since bulk SRO preserves inversion sym. ! space group ($Pbnm$ (300K), and $P12_1/n1$ (10K))**

What's happening for $T < 10$ K ?



- Crossover behavior in weak field MR and nonlinear field dependent of Hall resistivity: multi-channel charge conductions
- Rapid increase of the amplitude for 2D-like quantum oscillation with a freq. ~ 30 T below 10 K (Weyl-orbit Q.O.)
- The **Observed $\Delta R_T^{2\omega}$ and $\Delta R_L^{2\omega}$** for $T < 10$ K is in harmonic with the emergence of the 30 T quantum oscillation and also the crossover behavior in MR and Hall resistivity.
- The **Observed $\Delta R_T^{2\omega}$ and $\Delta R_L^{2\omega}$** are thus most likely also deriving from the **edges states and surfaces states** in SRO, where **broken \hat{I}** is well justified !

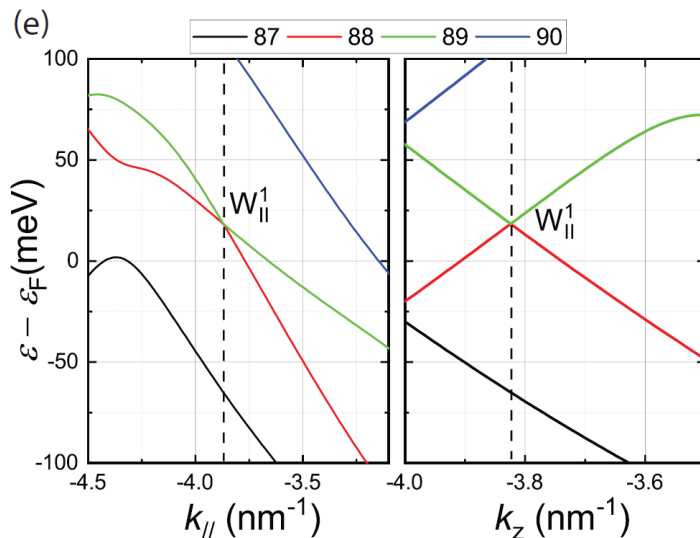
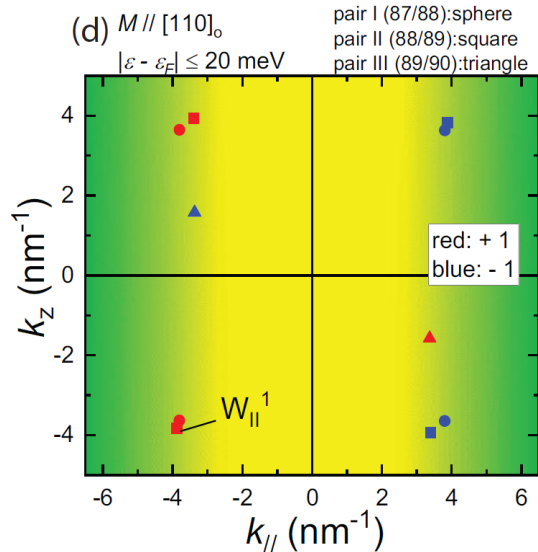
Surface Berry curvature dipole with 1D chiral edge mode in SRO thin film



- **Observed $\Delta R_T^{2\omega}$ and $\Delta R_L^{2\omega}$** and their orthogonal α dependence: surface/edge states with broken \hat{I} !
surface BCD $\vec{D} // [1\bar{1}0]_o$ + chiral edge modes $// [001]_o$

- Band calculations:
 - ✓ **Nonzero total Berry flux** for 2D slices along k_z : presence of chiral edge modes along $[001]_o$.
 - ✓ type II and **tilted** Weyl nodes: possible nonzero surface BCD along $k_{//}$ and thus $[1\bar{1}0]_o$.
 - ✓ Hot lines, separating surface and bulk states, with diverging BCD ?

Wawrzik et al. PRL 127, 056601 (2021).

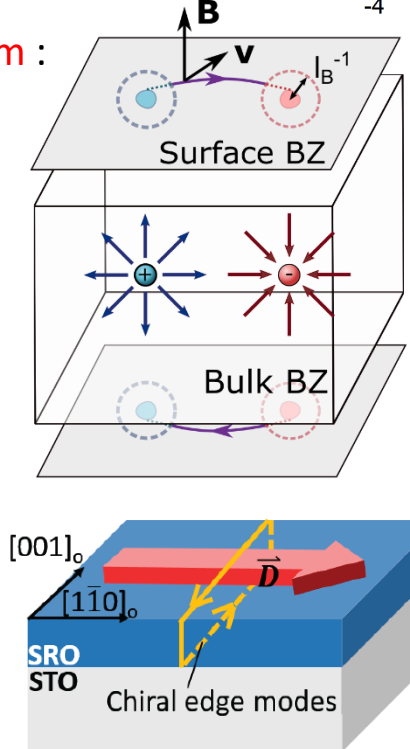
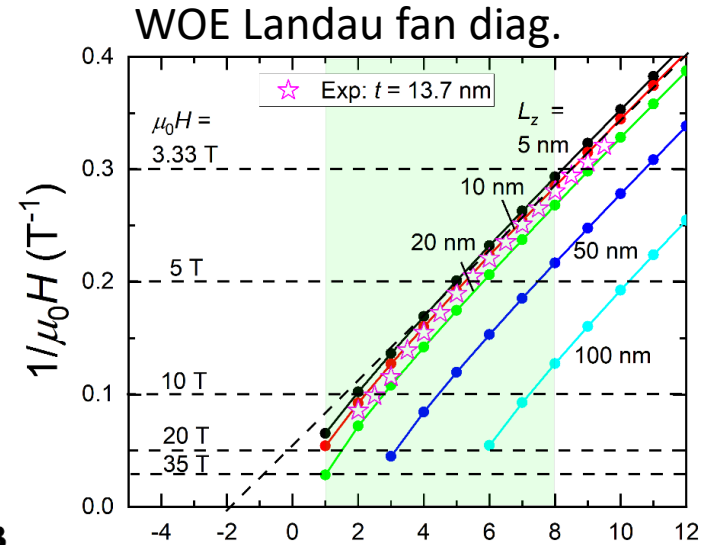


- The NRTE of $\Delta R_L^{2\omega}$ can be due to asymmetric scattering between the chiral **edge** modes on top surface with the Fermi-arc surface states. (cf. NRTE in QAHE)

Conclusion

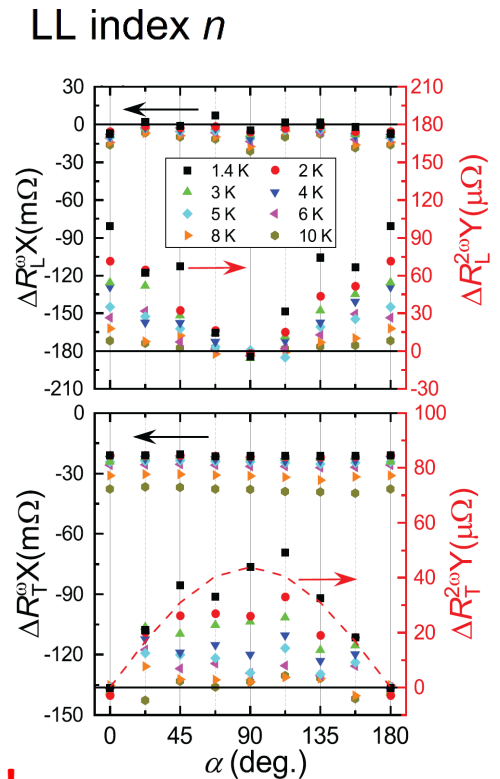
WOE: Kar *et al.* Sci. Rep. 11, 16070 (2021) and npj Quantum Materials 8, 8 (2023)

- Adsorption-controlled growth of SRO thin films on **miscut** STO (001) using oxide MBE:
 - $7.7 < t < 35$ nm, high RRR (~14 to 52) and low RR (~12 to 3 $\mu\Omega\text{cm}$)
 - Single-domain and **untwinned** epitaxial films with excellent thickness uniformity
- $F_{s1} \sim 30$ T with a light mass of $0.3 m_e$:
 - **Non-monotonic “thickness” (t)-dep.** of FFT amplitude with largest amplitude for t ranging from **10-20 nm** and relatively **weak t -dep.** of extracted quantum lifetime
 - F_{s1} follows $1/\cos(\text{angles})$ dep. (**2D-like** Fermi pocket)
- Simulated Weyl-orbit QO for thickness with optimum **thickness of $10 \leq t \leq 20$ nm** :
 - Unique **concave downward** curvature in LL fan diag.
 - Direct consequence of the **non-adiabatic corrections** (α term).



NRTE and NLH in SOR: arXiv:2307.04482

- **Observed $\Delta R_T^{2\omega}$ and $\Delta R_L^{2\omega}$** and their orthogonal α dependence: **surface** BCD $\vec{D} // [1\bar{1}0]_o$ + chiral **edge** modes $// [001]_o$
- Band calculations:
 - ✓ Nonzero total Berry flux for 2D slices along k_z support for the presence of chiral edge modes along $[001]_o$.
 - ✓ type II and tilted Weyl nodes: possible nonzero surface BCD along $k_{//}$ and thus $[1\bar{1}0]_o$.

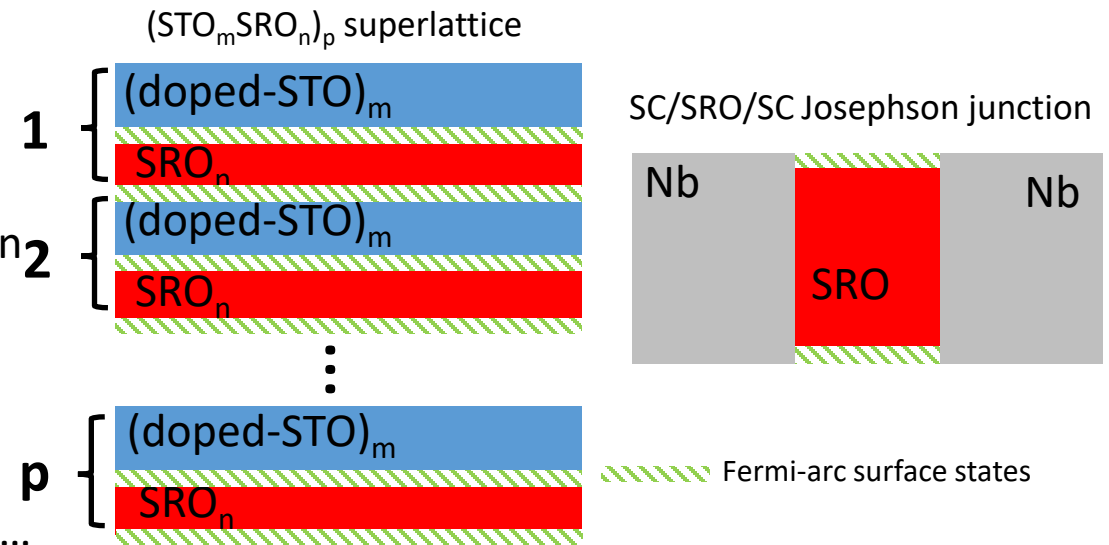
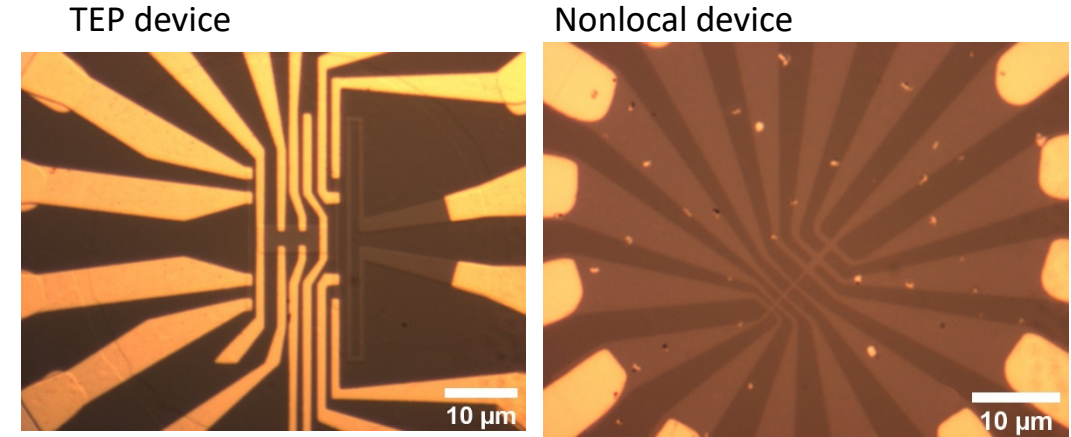


Only possible with sample in thin film form with low defect level grown by oxide MBE facility !

Outlook of future direction

- Unsettle issues for SRO:
 - ✓ The role of electron correlation at low temp ? Electronic nematicity ? ($\rho \sim T^2$ for $T \lesssim 15$ K)
 - ✓ The sustention of the Fermi-arc surface states and 1D chiral edge modes in Weyl *metals* (SRO trivial bulk states: $m^* > 3 m_e$)
 - ✓ The NRTE and NLH in system with **broken *PT***.
- Thin film of Weyl metal SRO is an ideal platform for the design and fabrication of topological electronics:
 - ✓ Further probing **Fermi-arc surface** states (**chiral-zero** modes) related physical effects: thermoelectric property, anisotropy property, SRO-based **Josephson** junction, superconducting proximity coupling to **Fermi-arc surface states** (Majorana physics ? FFLO states ?) ... etc
- Strain engineering on SRO films: tuning Fermi-arc surface states.
 - ✓ Apply adsorption controlled technique to the growth of SRO on different substrates:
Ex: (LSAT(001)_c, -1.6 %) , (DyScO3(110)_o, +0.4%)
- Extension of adsorption controlled technique to other oxides:
 - ✓ Development of metal-organic sources for Ti, Ru ... etc
 - ✓ Unconventional S.C. Sr₂RuO₄, Mott insulators LaTiO₃, Ca₂RuO₄ ...
 - ✓ “Altermagnet” RuO₂
 - ✓

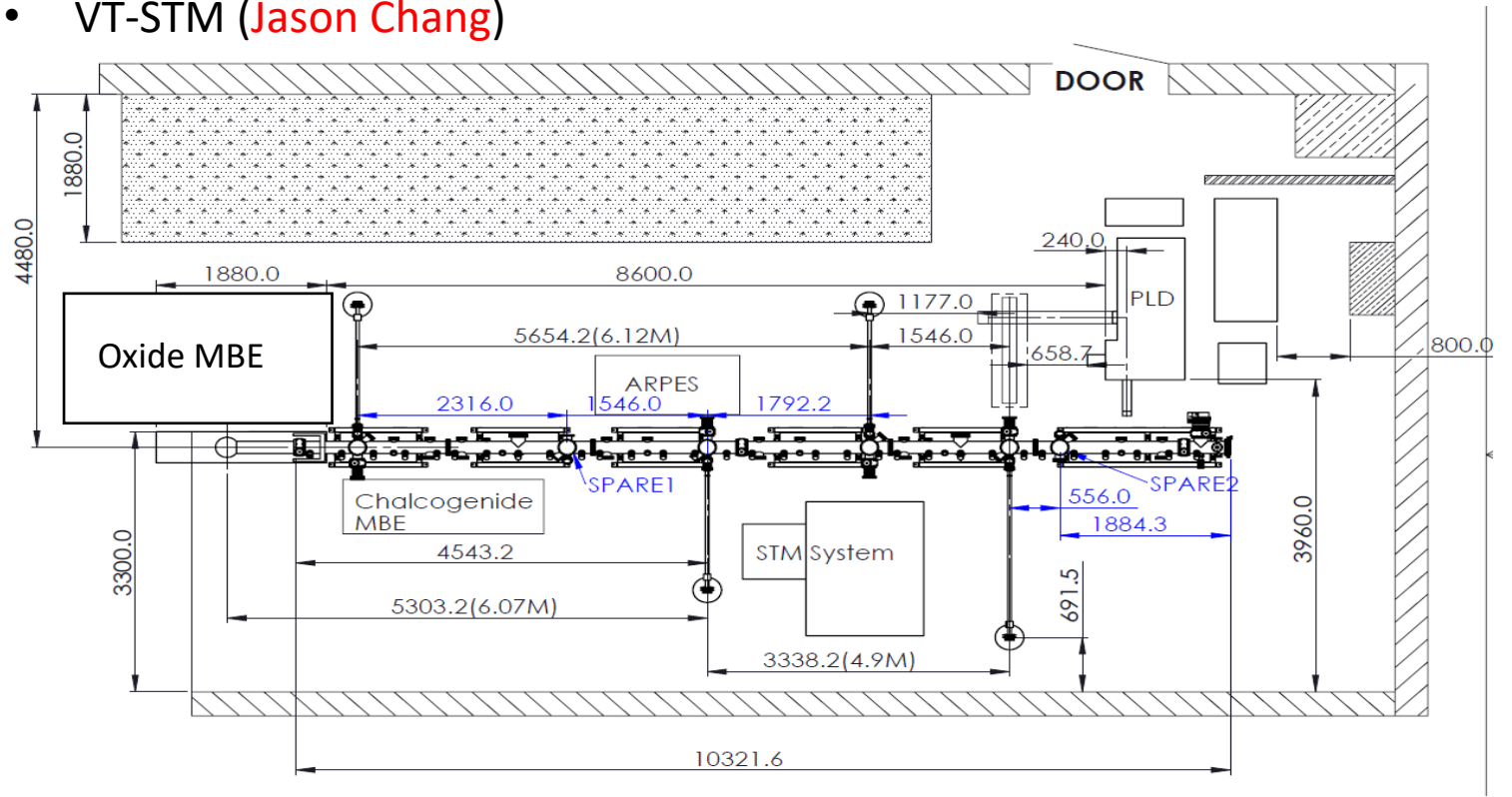
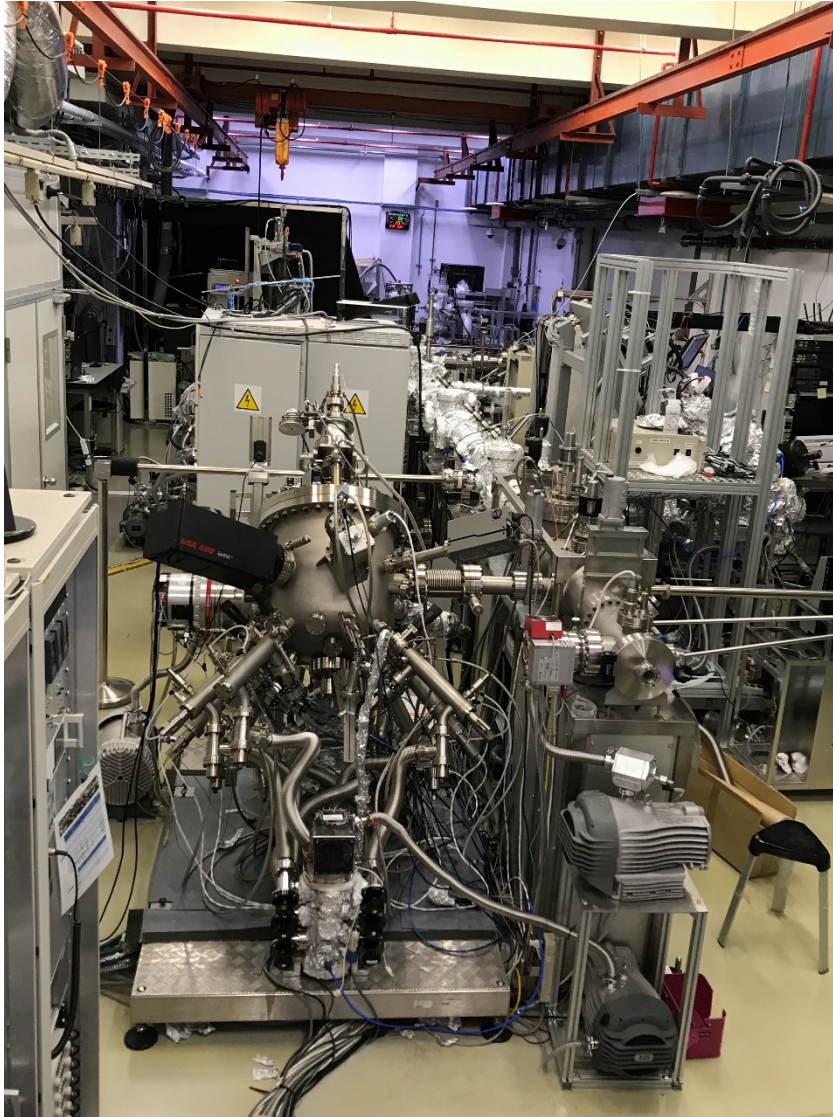
Patterned SRO-device



Multi-chamber UHV epitaxial thin film growth and characterization system

Lab (B113-115)

- Oxide MBE with O₃ distiller 2014 (Wei-Li Lee)
- PLD 2014 (YH Chu)
- UHV sample transfer chamber 2016 (Wei-Li Lee, Jason Chang)
- ARPES: DA 30, He-lamp, and monochromator 2017 (SJ Tang)
- Chalcogenide MBE 2017 (Yung Liou, Sankar Raman?)
- VT-STM (Jason Chang)



> 4M USD investments since 2014.

Oxide MBE + Chal. MBE + ARPES + PLD + VTSTM

**This is NOT a plan/proposal ! Those facilities are what we already had at IoP !
Need to recruit active young PIs (ARPES, MBE) to get involved !**

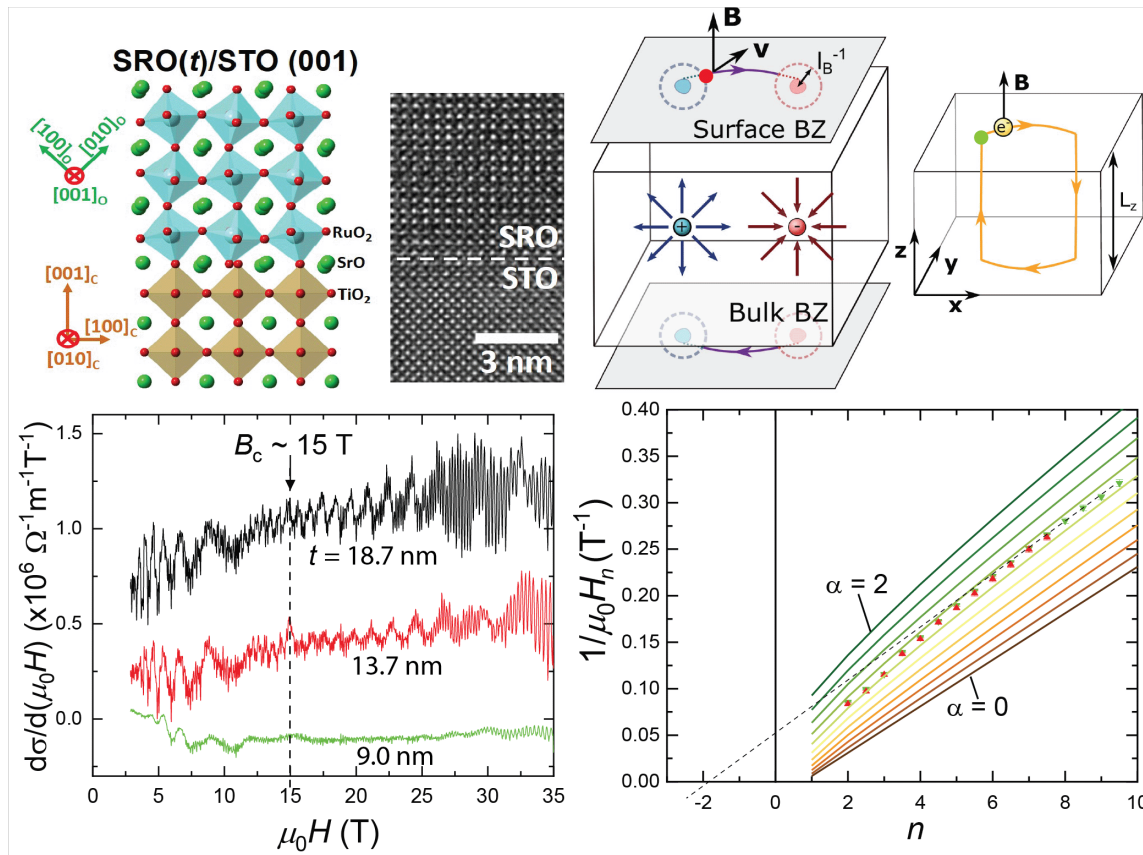
-----THE END-----

Thank you for your attention

Weyl-orbit QO.

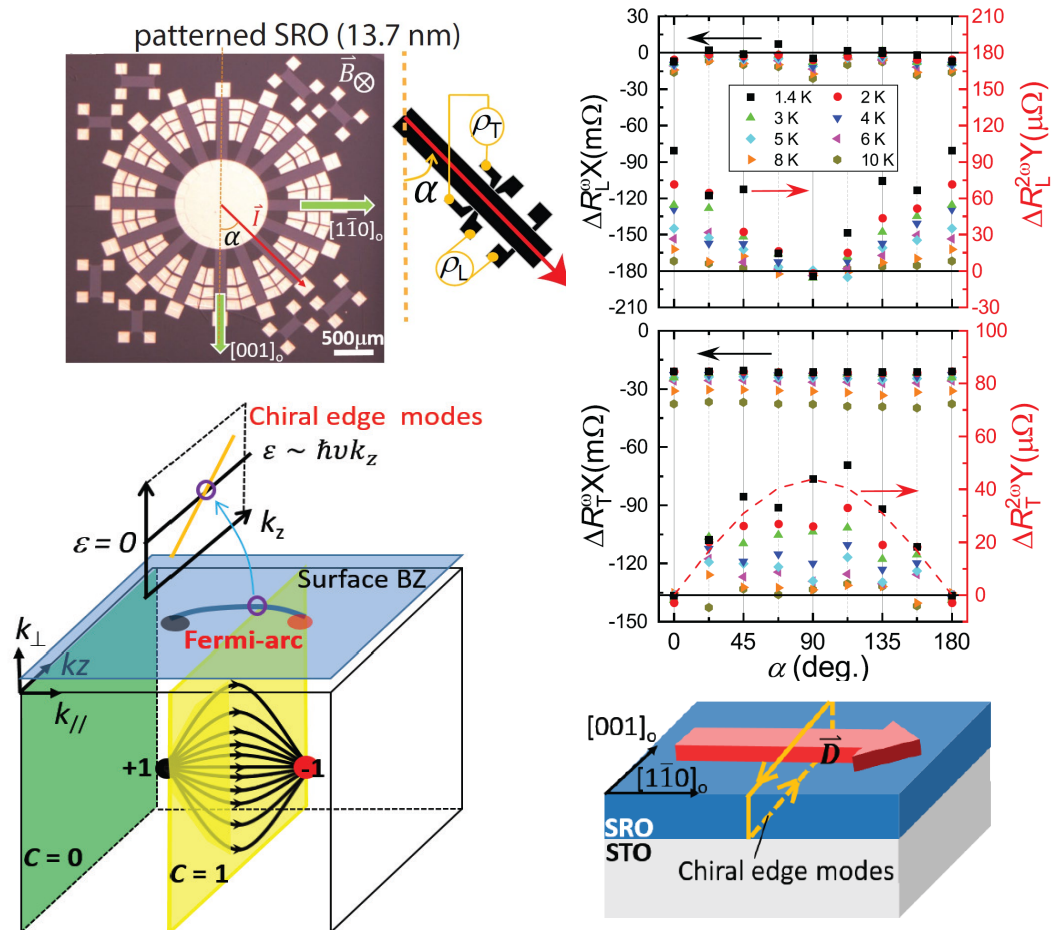
Kar *et al.* *Sci. Rep.* 11, 16070 (2021)

Kar *et al.* *npj Quantum Materials* 8, 8 (2023).



NRTE and nonlinear Hall

Kar *et al.* arXiv:2307.04482, submitted.

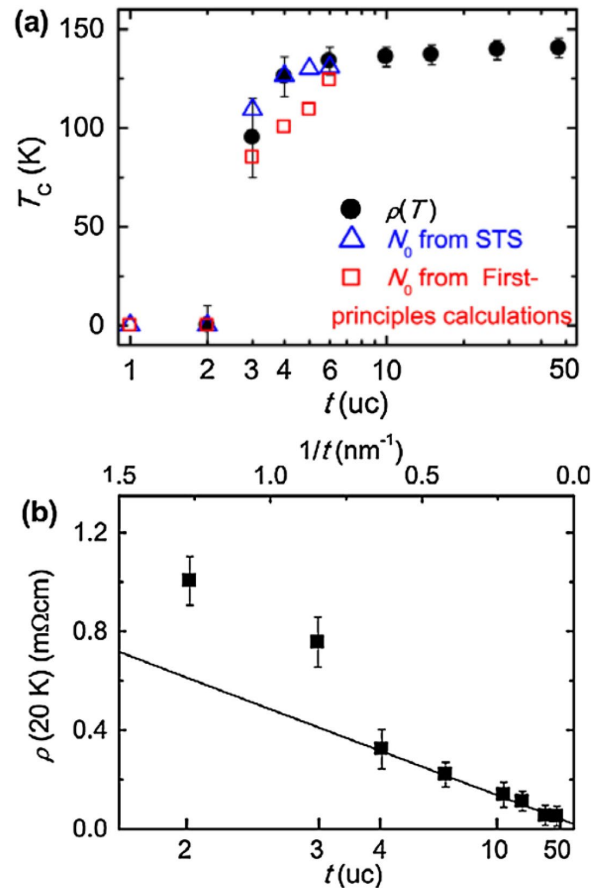


Supporting information below

Revisit of physical properties in SRO ultra thin films

SRO films grown by pulsed laser deposition (PLD)

- Critical thickness of about 3 uc for itinerant Ferromagnetic property in SRO films



Chang *et al.* PRL 2009

Several transport issues at low temp. in SRO films can be revisited !

SRO films grown by MBE using adsorption controlled technique

Ferromagnetism and Conductivity in Atomically Thin SrRuO₃

H. Boschker,¹ T. Harada,¹ T. Asaba,² R. Ashoori,³ A. V. Boris,¹ H. Hilgenkamp,⁴ C. R. Hughes,^{1,5} M. E. Holtz,⁶ L. Li,^{2,3} D. A. Muller,^{6,7} H. Nair,⁸ P. Reith,⁴ X. Renshaw Wang,^{4,*} D. G. Schlom,^{7,8} A. Soukiassian,⁸ and J. Mannhart¹

PHYSICAL REVIEW X **9**, 011027 (2019)

- A 2D metallic and ferromagnetic oxide

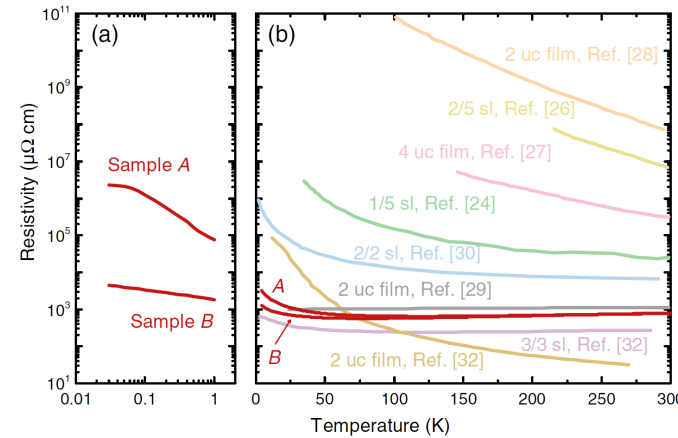
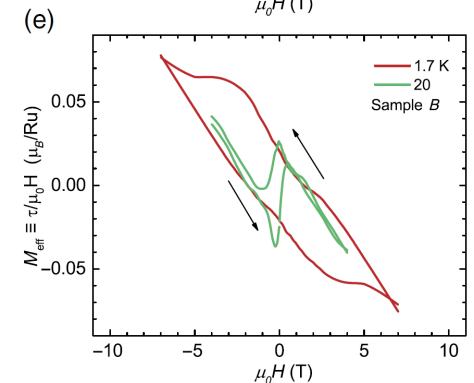
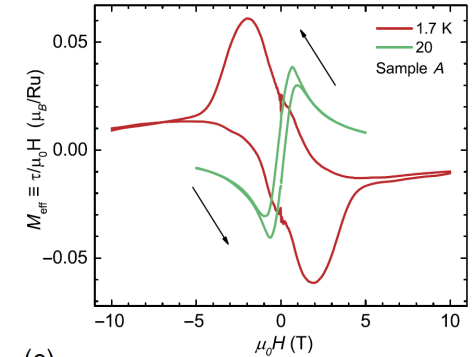


FIG. 7. Temperature dependence of the resistivities of samples A and B. (a) Temperature range below 1 K on a logarithmic scale. (b) Temperature range $2 < T < 300$ K on a linear scale. For comparison, thin-film and superlattice (sl) samples found in the literature with a comparable thickness of the SrRuO₃ layers are also shown. The superlattices are $\{(\text{SrRuO}_3)_1 - (\text{SrTiO}_3)_5\}_{20}$ [24], $\{(\text{SrRuO}_3)_2 - (\text{BaTiO}_3)_5\}_{36}$ [26], $\{(\text{SrRuO}_3)_2 - (\text{LaAlO}_3)_2\}_{60}$ [30], and $\{(\text{SrRuO}_3)_3 - (\text{SrTiO}_3)_3\}_{15}$ [32]. All samples are grown on SrTiO₃ substrates.

Monolayer sample A: upper bound of 0.4% two-layer SRO.(STEM)

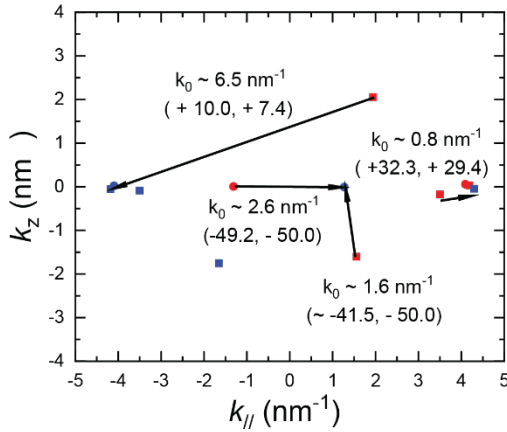
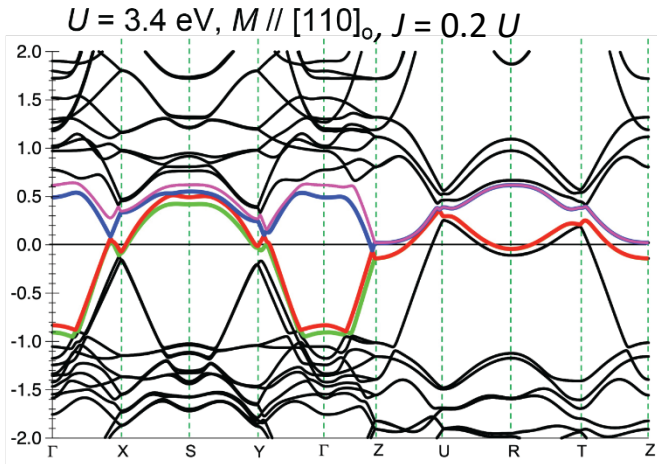
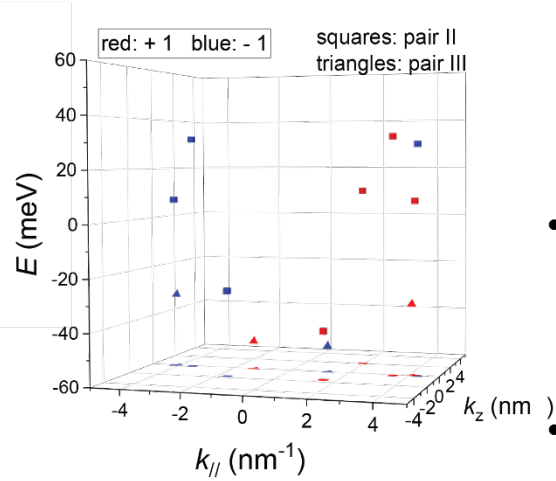
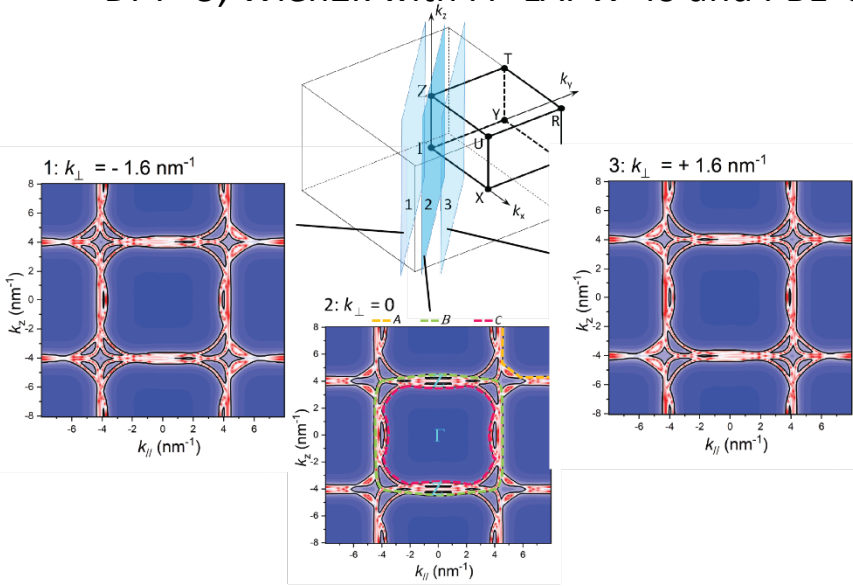
Monolayer sample B: upper bound of 0.3% two-layer SRO.

Torque magnetometry



Comparison to band calculations

DFT+U, Wien2k with FP-LAPW+lo and PBE-GGA,



- Bulk pockets A, B, and C:

	A	B	C
Band cal. (T)	5077	7531	5517
Exp. QO (T)	3680 (F_3)	7400 (F_5)	4000 (F_4)

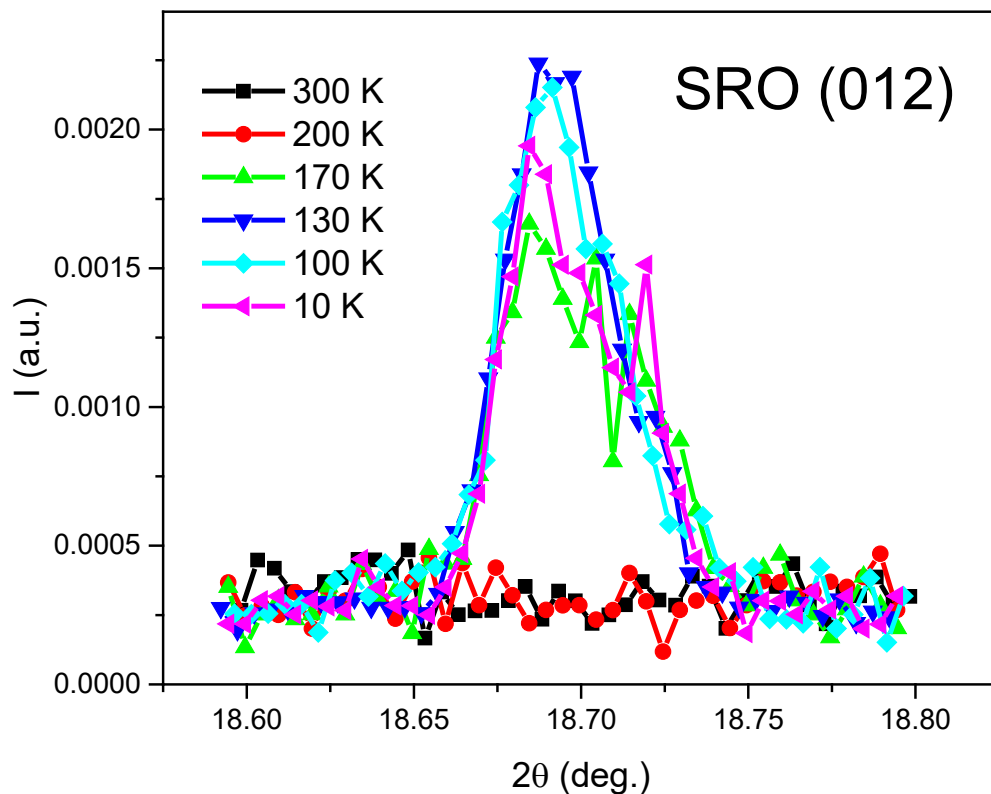
- Searching for Weyl-nodes from four pairs of bands near Fermi energy (with an energy window of $|E - E_F| \leq 50$ meV)

- The nodes are **NOT** at high sym. Locations, and sensitive to the band parameters (U, M)

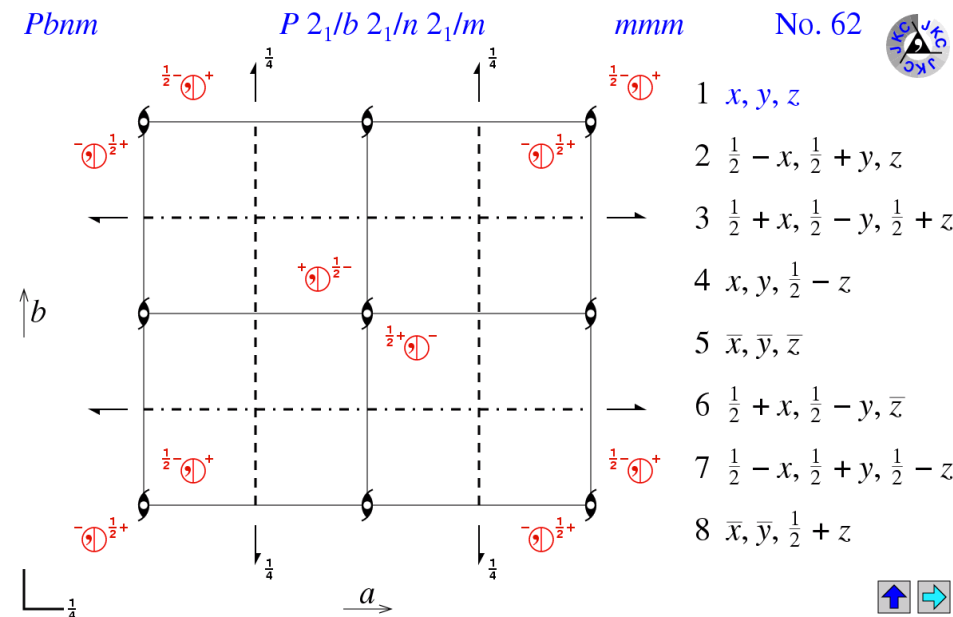
- Non-overlapped Weyl-node pairs on $(110)_o$ plane can be identified with Fermi-arc length k_0 ranging from **0.8 to 6.5 nm⁻¹**, supporting for the occurrence of Weyl-orbit QO in our untwinned SRO films.

Cf. $k_0 = 1.09 \text{ nm}^{-1}$ from experiment.

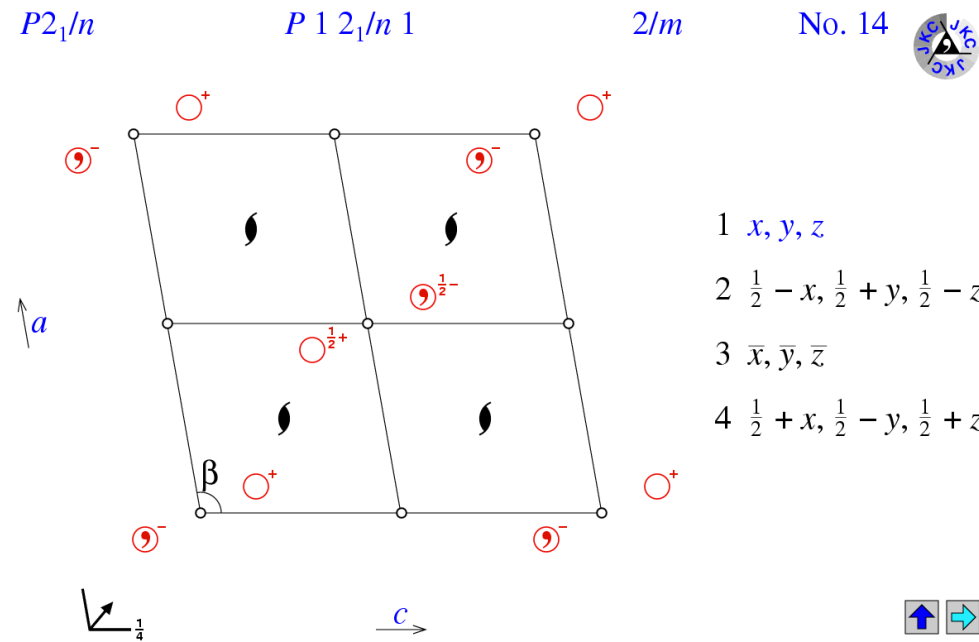
Temperature dependent XRD of the SRO 35 uc



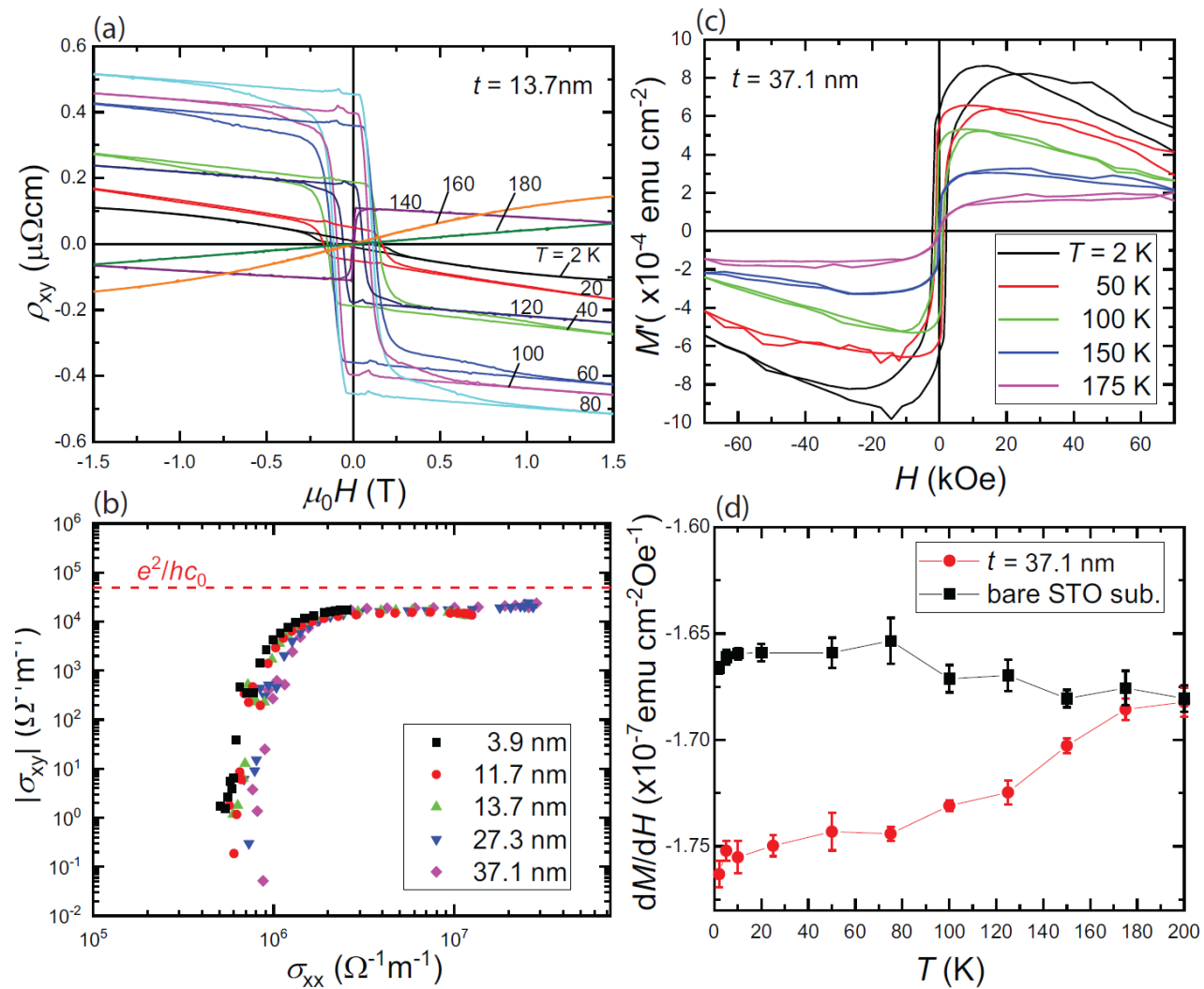
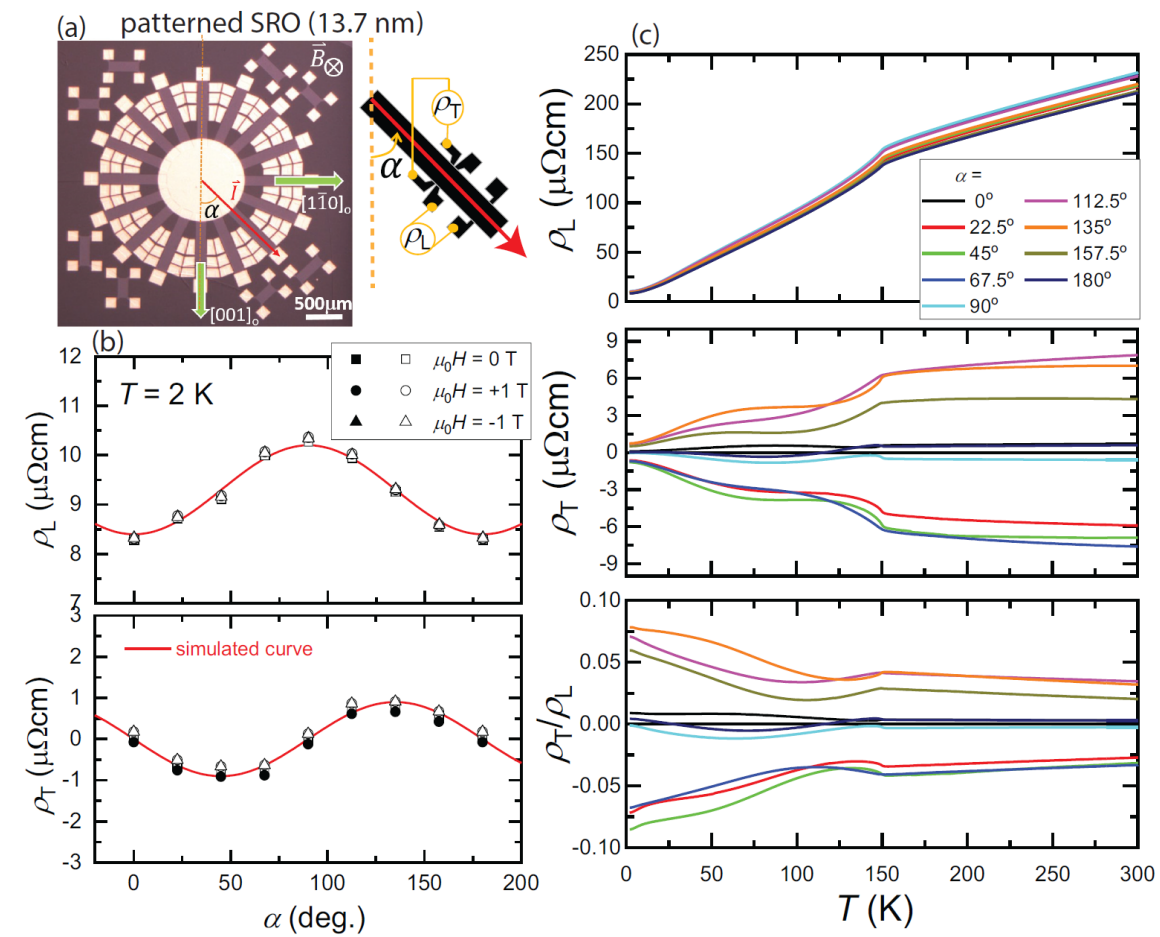
SRO space group (Pbnm) at RT

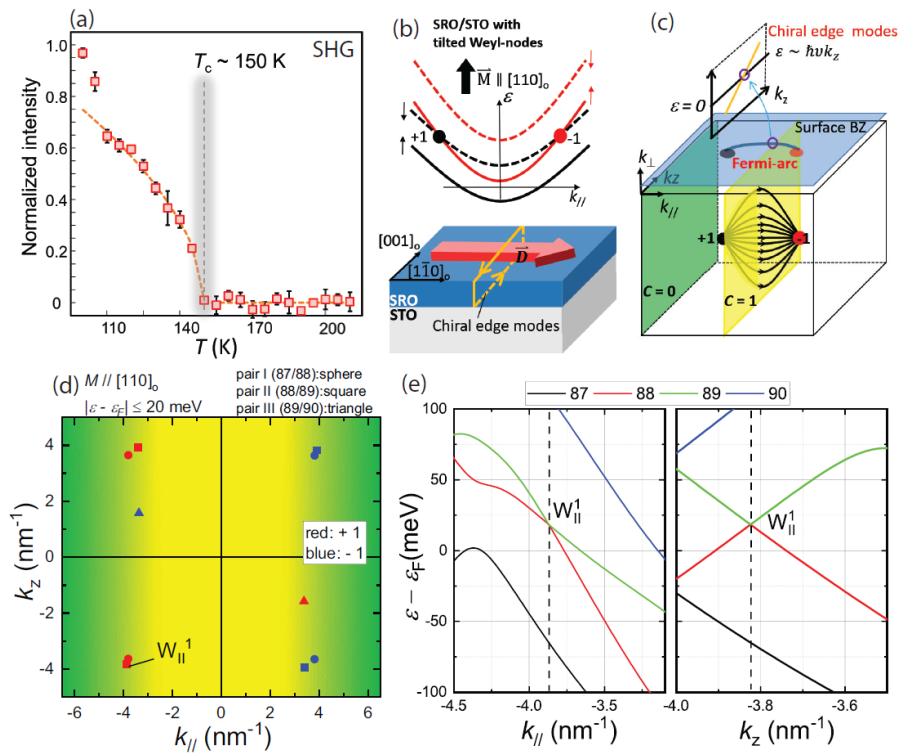
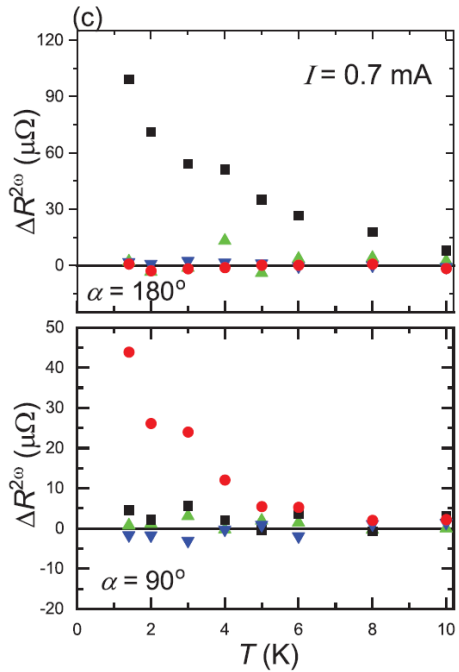
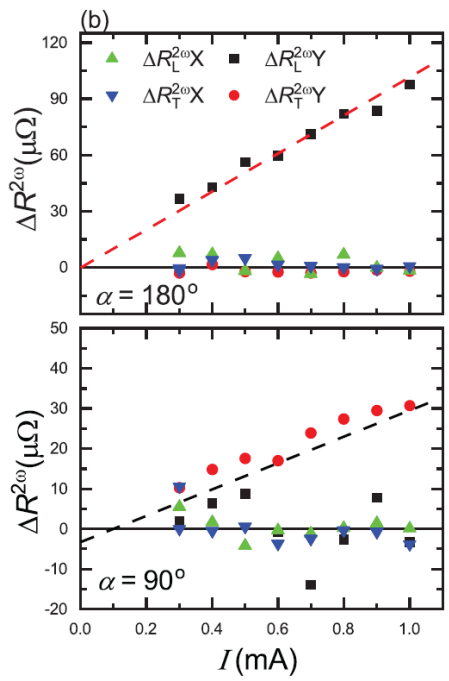
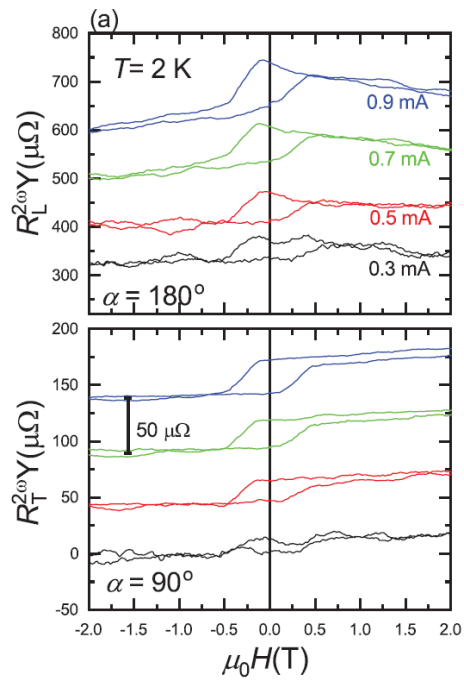


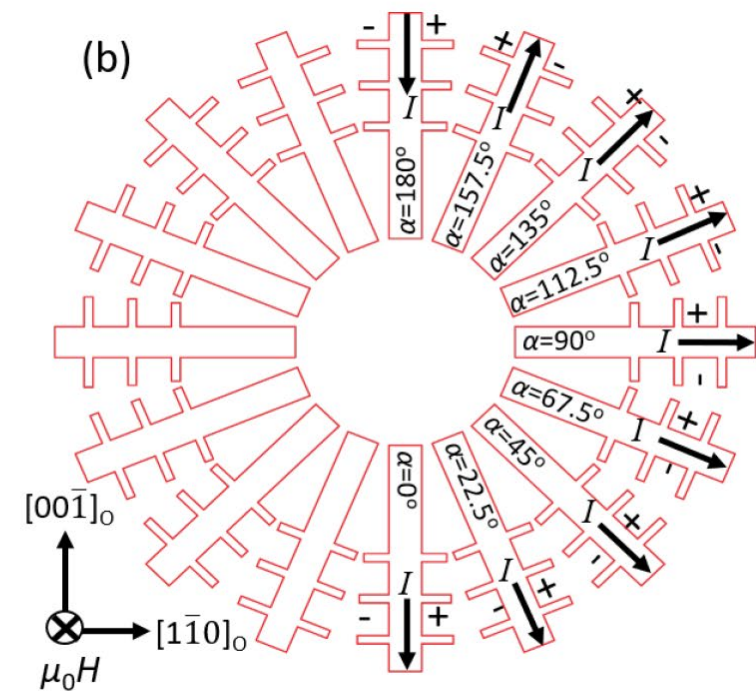
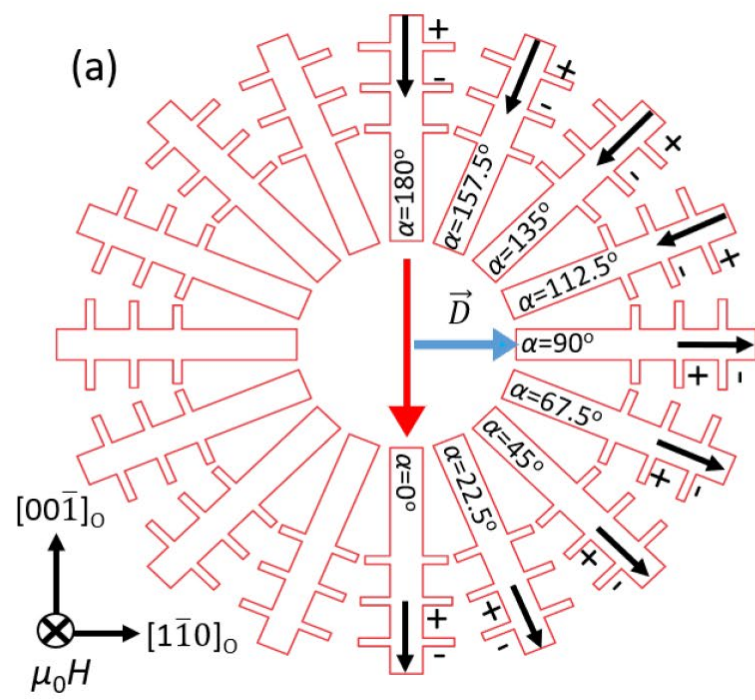
SRO space group (P12₁/n1) at below ~170 K



- ❑ The Pbnm SRO likely changes to the P12₁/n 1 SRO after breaking the mirror symmetry.
- ❑ SRO (012) reflection is allowed in the P12₁/n 1 space group.
- ❑ SRO(012) reflection is forbidden in Pbnm space group.
- ❑ SRO (012) peak were not appeared at 200 K and 300 K, revealing for the Pbnm space group.
- ❑ SRO (012) peak appeared from 170 K to 10 K suggesting for a structural transition from pbnm to likely P12₁/n 1 space group.







Supporting information end